

Advanced CMOS Image Sensors

GPIXEL PRODUCTS BROCHURE



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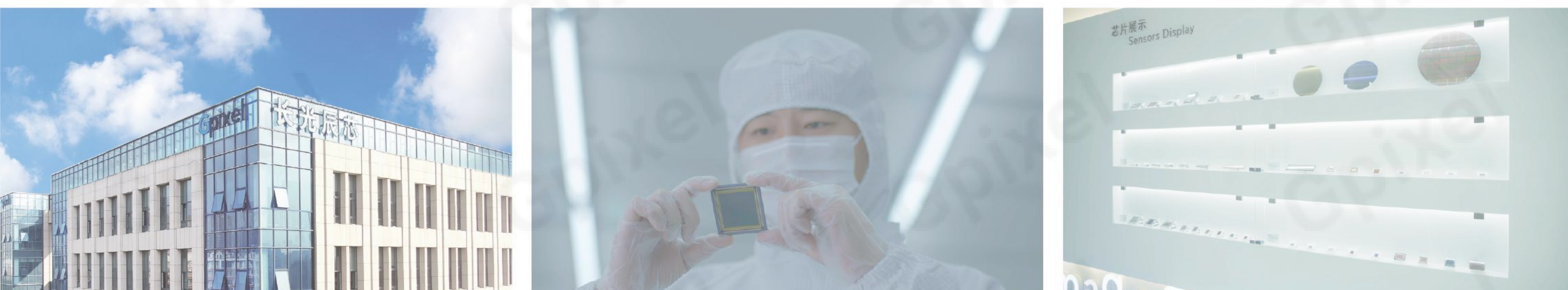
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GP-PR250124 V1.0

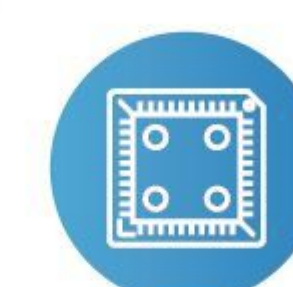
+ COMPANY



Founded in 2012, Gpixel focuses on the design and development of high-performance CMOS image sensors. Company headquarters are located in Changchun, China and additional design centers are located in Hangzhou, Dalian, Antwerp, and Tokyo. Gpixel provides advanced CMOS image sensors and exceptional customer service to camera makers around the world.



2012
Founding



Products
Advanced CMOS image sensors



Vision
Focus on technology
Insist on innovation

The Gpixel team includes first-class semiconductor physicists and globally recognized image sensor experts. Gpixel has a strong foundation of intellectual property related to charge-domain global shutter pixels, low noise circuit design, layout optimization for performance and yield of high resolution and large format image sensors, implementation of on-chip high dynamic range modes, backside illumination with high peak quantum efficiency, and true charge transfer based time delay and integration (TDI).

Gpixel has created a broad portfolio of products covering automation & inspection, scientific imaging, medical imaging, video & photography, and traffic & transportation.





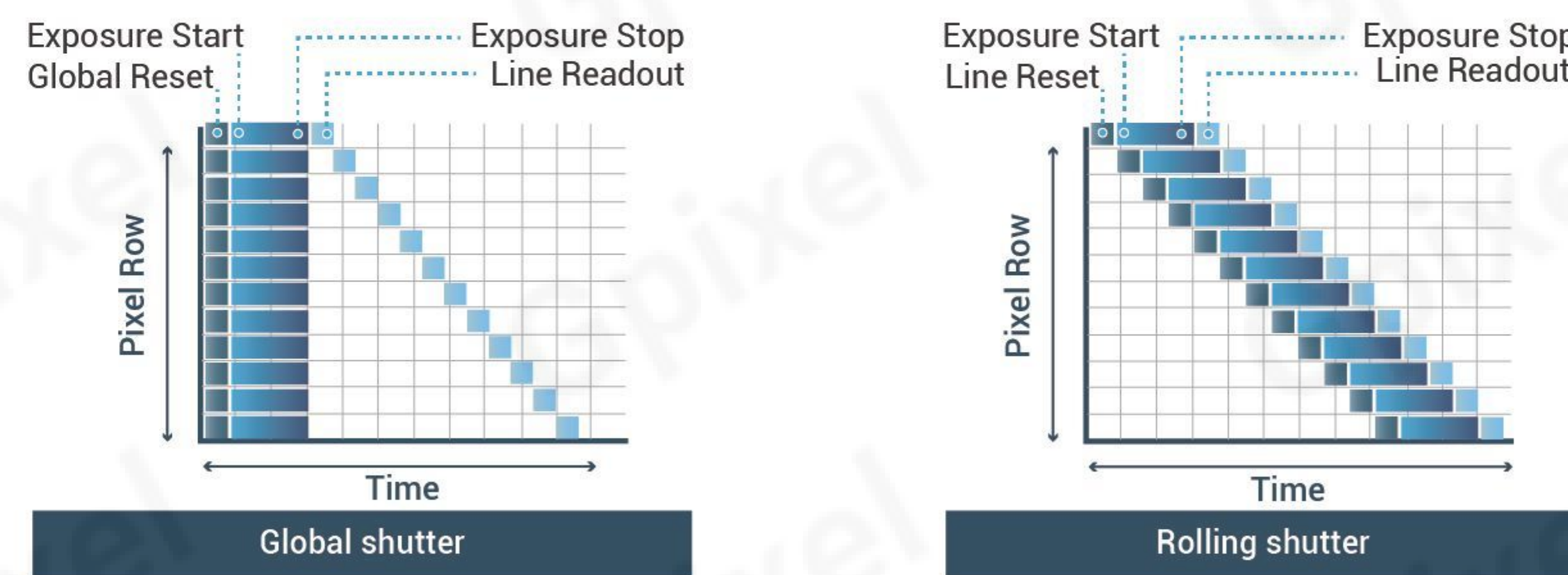
Global Footprint

Gpixel employees from **12** countries around the world



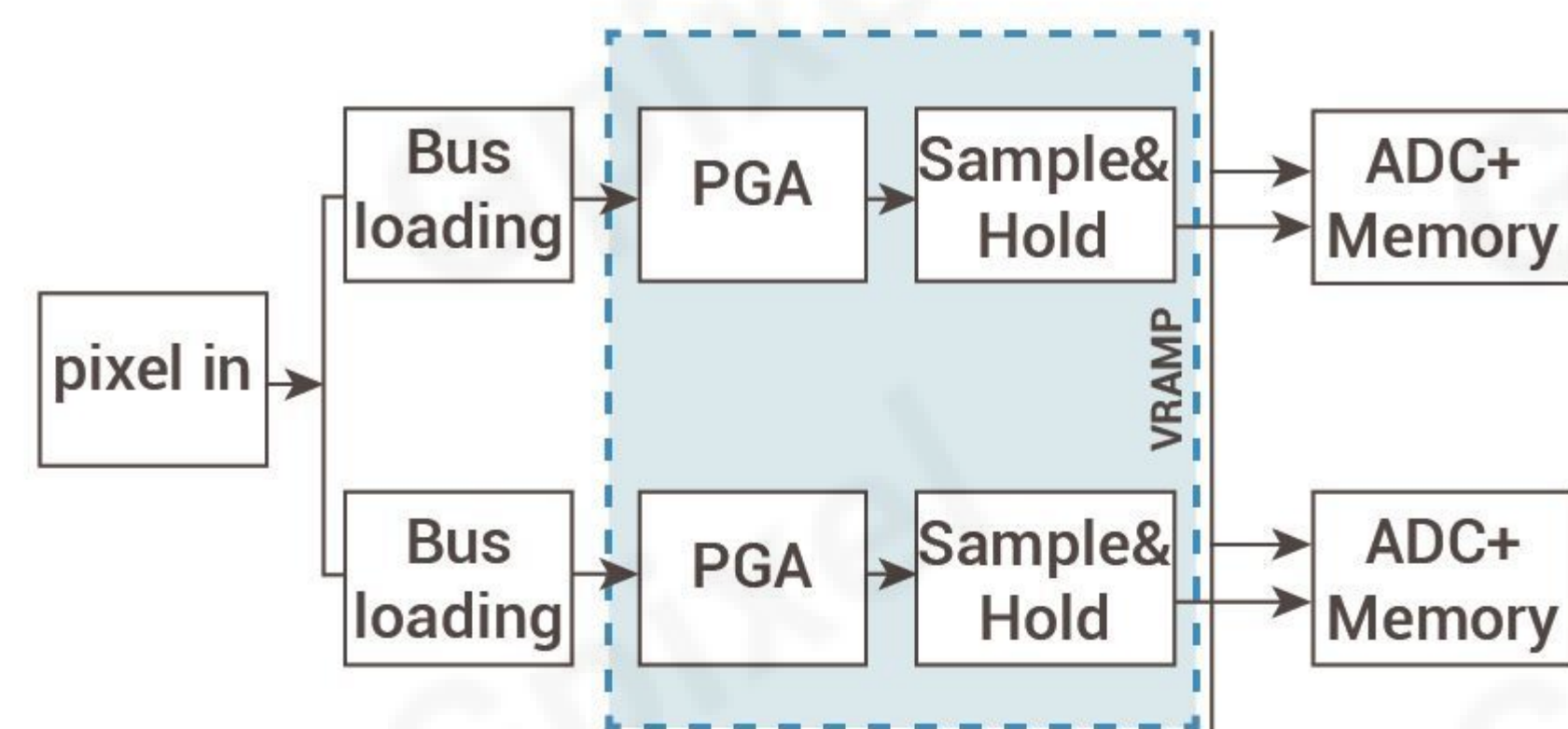
G Global Shutter Pixels

- The entire pixel array can start and end exposure at the same time.
- Advanced charge-domain global shutter pixels can realize single-electron level readout noise.
- Dual microlens array design effectively optimizes shutter efficiency.



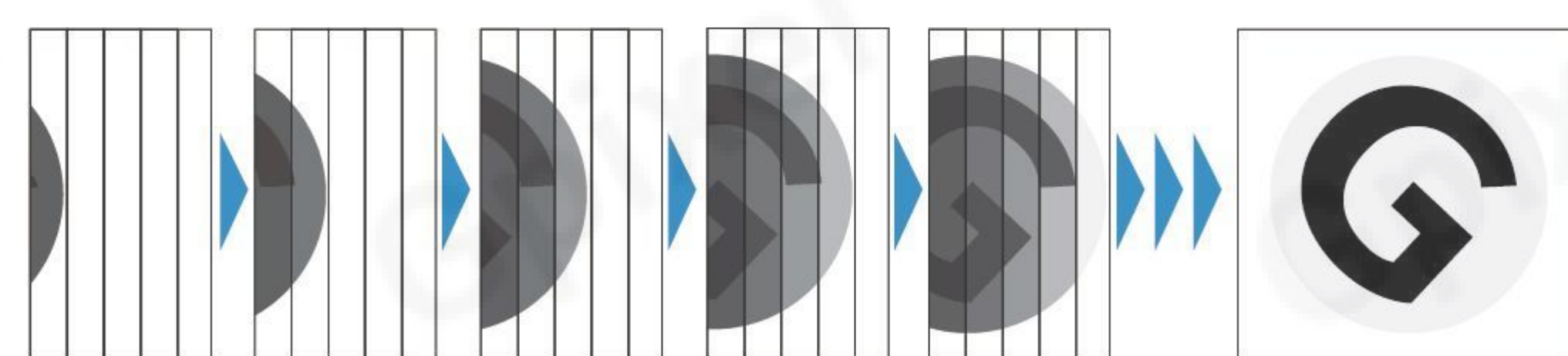
G Low Noise, High Speed, High Dynamic Range

- Correlated multiple sampling technology can achieve read noise less than a single electron.
- Using interleaved time-sharing high-speed circuit design, data rates up to 1Tbps are possible.
- Dual-gain circuit designs achieve >100 dB dynamic range in a single exposure.



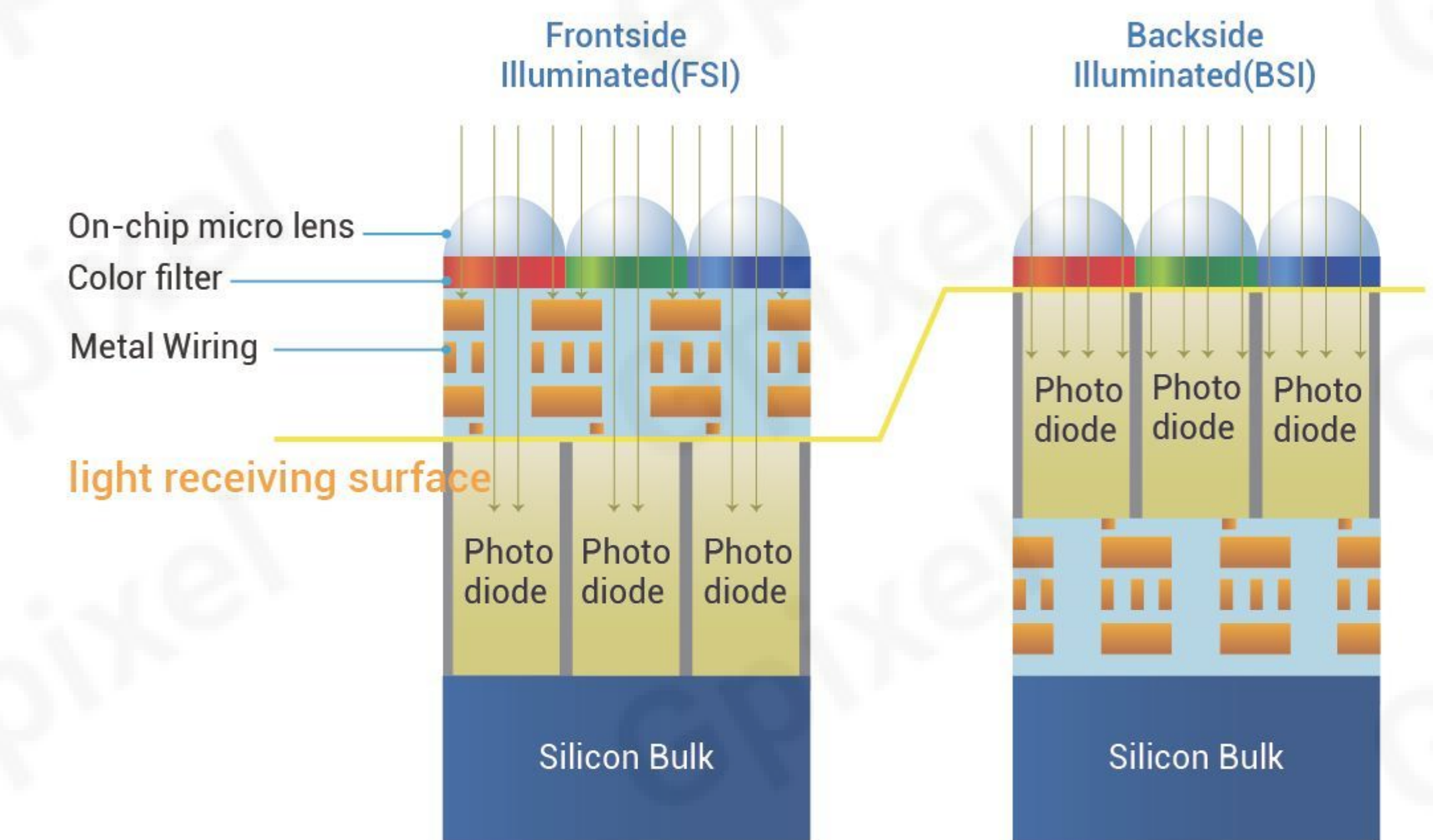
G Time Delay and Integration

- In low-light environments, TDI can provide both fast scanning and high image quality while optimizing detection efficiency.
- For the same scanning speed, compared with ordinary line array sensors, less illumination is required and the system's energy consumption is lower.
- TDI is ideal for the inspection of wafers, PCBs, and displays, as well as for high throughput gene sequencing.



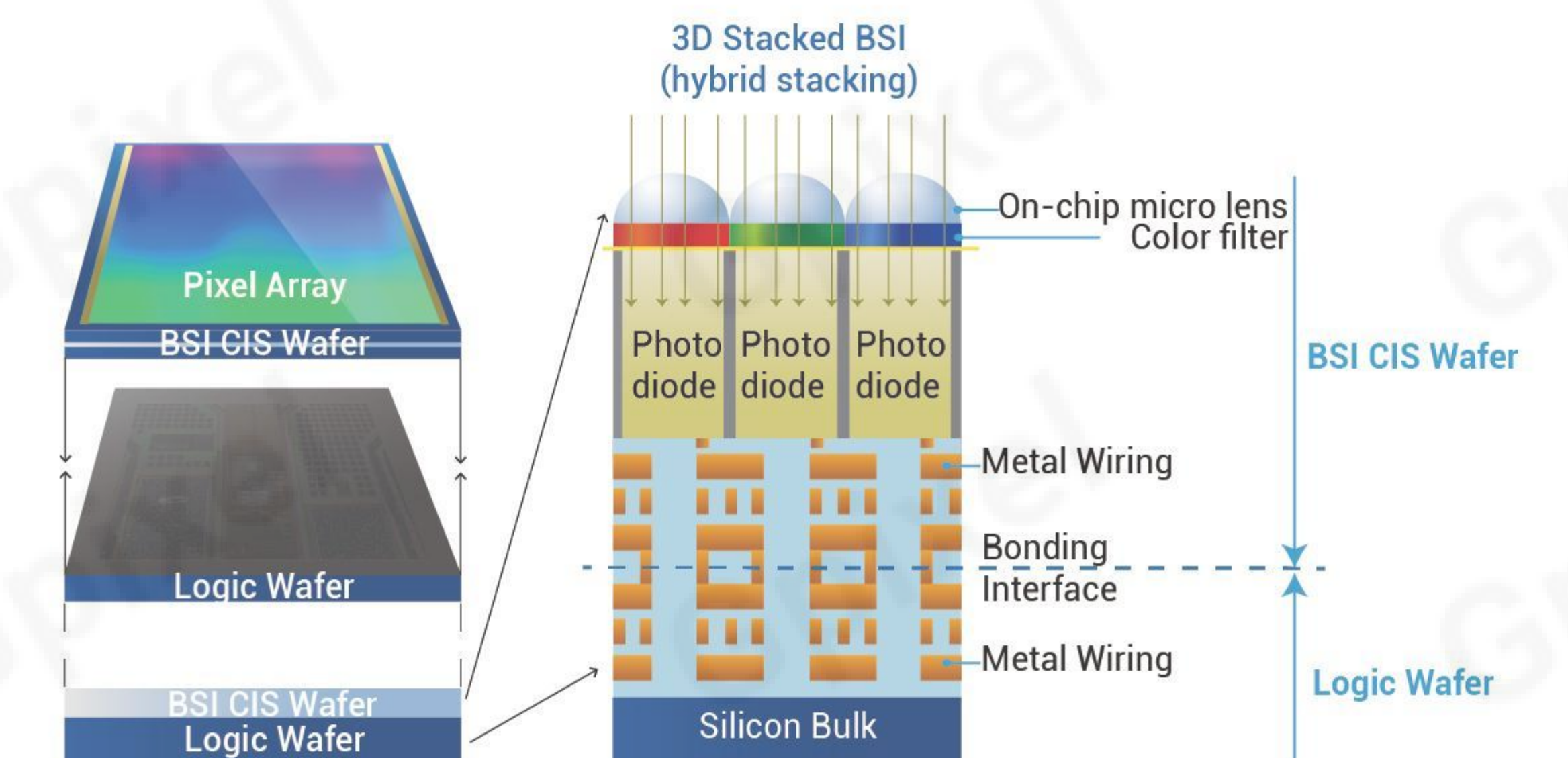
G Backside-illumination

- Gpixel's self-developed backside-illumination technology achieves peak quantum efficiency over 95%.
- The spectral range can be extended from the ultraviolet to the near infrared.
- The addition of Gpixel's Pulsar technology extends the range into the soft xray region.



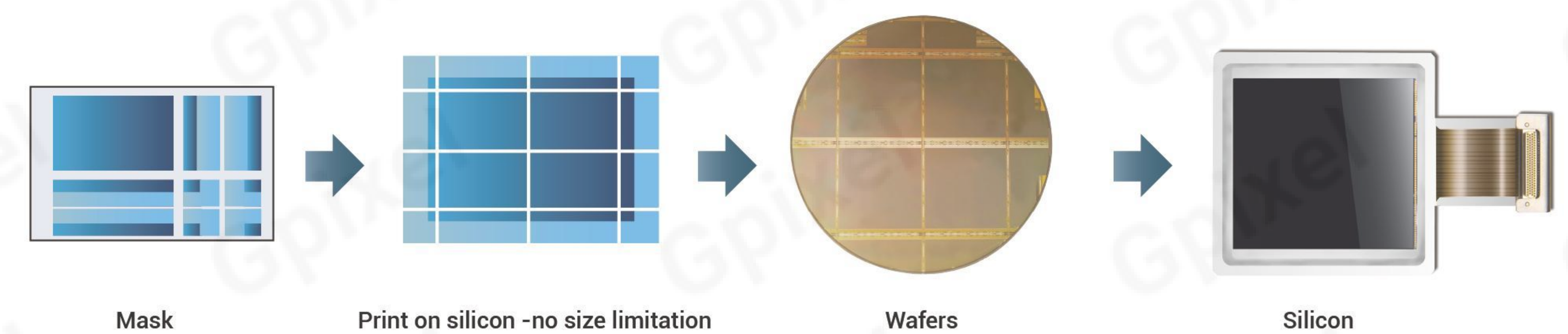
G Advanced Wafer Stacking

- Pixels and supporting circuits are independently designed and the separate wafers are bonded together through copper interconnections.
- Stacked chip architectures provide small size, fast read-out rate and high integration.



G Large-Area and High-Resolution Chip Design

- Breaks through the lithography limit of 24 mm x 32 mm in a single pass.
- Related design expertise allows for stitching of even dense pixel designs with minimization of boundary artifacts.



Market Segments

Industrial

- Factory Automation
- Machine Vision
- Line Scan
- Inspection (PCB/FPD/wafer)
- Logistics, AGV

Scientific

- Life science
- Astronomy
- DNA Sequencing
- Spectroscopy
- Electron Microscopy

Professional Imaging

- Photography
- Video
- Cinematography

Others

- High Speed
- Traffic (ITS)
- Medical Imaging
- Custom Products
- ...

Using our many years of industry experience and expert technical capabilities, we provide advanced CMOS image sensors and quality service to our customers.



Gpixel

Advanced CMOS Image Sensors



Product Contents

7 families of standard products, meeting the needs of multiple industries

GMAX	GSPRINT	GSENSE	GLUX	GTOF	GCINE	GL	Custom
GMAX4002----- 13	GSPRINT6502BSI---29	GSENSE2020----- 37	GLUX9701BSI ----- 51	GTOF0503----- 55	GCINE3243----- 59	GLR1205BSI-S -- 63	Custom Design: ----- 75
GMAX3405----- 14	GSPRINT4502----- 30	GSENSE2020BSI - 38	GLUX1605BSI ----- 52		GCINE4349----- 60	GLR1402BSI-M - 64	Semi-Custom: -----76
GMAX2505----- 15	GSPRINT4510----- 31	GSENSE4040----- 39				GL1402 ----- 65	
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GMAX | GSPRINT | GSENSE | GLUX | GTOF | GCINE | GL

Area Scan CMOS Image Sensor

GMAX is a series of global shutter image sensors developed by Gpixel for machine vision and industrial inspection. This family of products delivers the ideal combination of high resolution and high frame rate for industrial imaging. The pixel size ranges from 2.5 μm to 4.6 μm , and the resolution from 2.4MP to 152MP. The four products developed using the 2.5 μm pixel platform are pin-compatible for easy camera integration.

GMAX4002	GMAX3405	GMAX2505	GMAX2509	GMAX3809
GMAX3412	GMAX3413	GMAX4416	GMAX2518	GMAX0505
GMAX4651	GMAX3265	GMAX32103	GMAX32152	

Product Family Features

- Global Shutter
- Standard Optical Formats
- 2.4MP-152MP resolution
- High Frame Rates

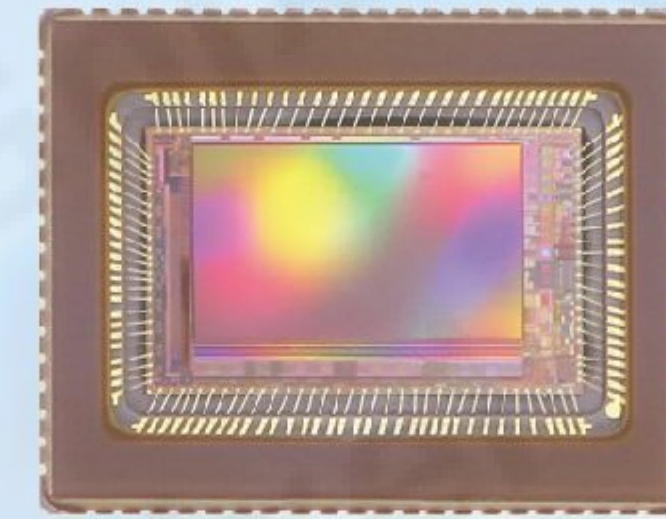
Applications

- Automation & Inspection
- Video Broadcasting
- Traffic & Transportation
- Medical Imaging



GMAX4002

2.4MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX4002 is a 1/1.7" optical format image sensor with 2048 x 1200 effective pixels. Featuring an advanced charge domain global shutter pixel, GMAX4002 operates with true CDS for low noise and high dynamic range. Gpixel's Red Fox technology is employed to deliver enhanced QE for NIR applications. GMAX4002 is configurable through I2C. It integrates both sub-LVDS and MIPI interfaces, for frame rates of 344 fps and 166 fps respectively. GMAX4002 supports 2x2 on-chip binning to achieve higher sensitivity and faster frame rate. It includes an on-chip sequencer and OTP functions. Assembled with a 74-pin CLCC package, GMAX4002 enables a cost-effective camera solution, easy integration and high-reliability mass production.

Key features and Benefits

- NIR enhanced
- Low noise global shutter
- On-chip sequencer
- MIPI and Sub-LVDS Data Interfaces
- One Time Programmable (OTP) Memory

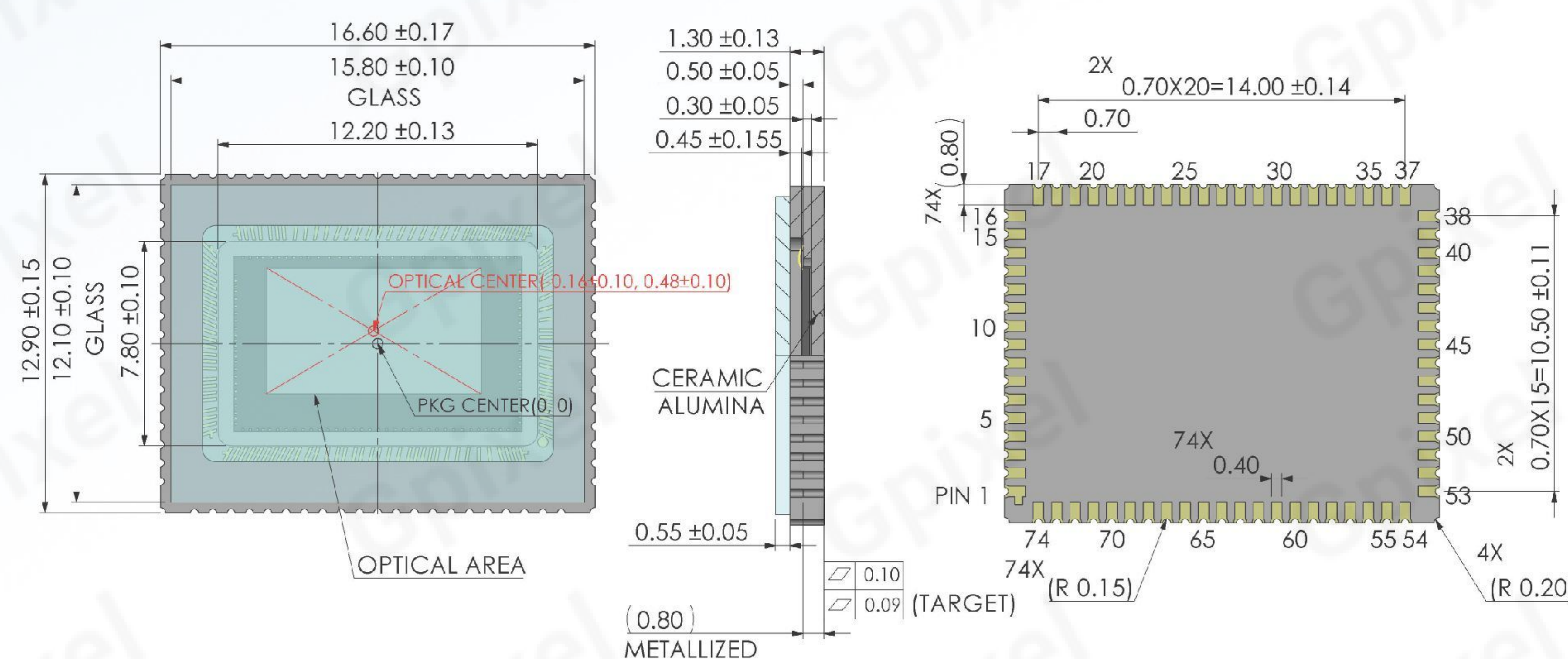
Application

- Automation & Inspection
- Logistic & Positioning
- Metrology
- Motion Capture

Specifications

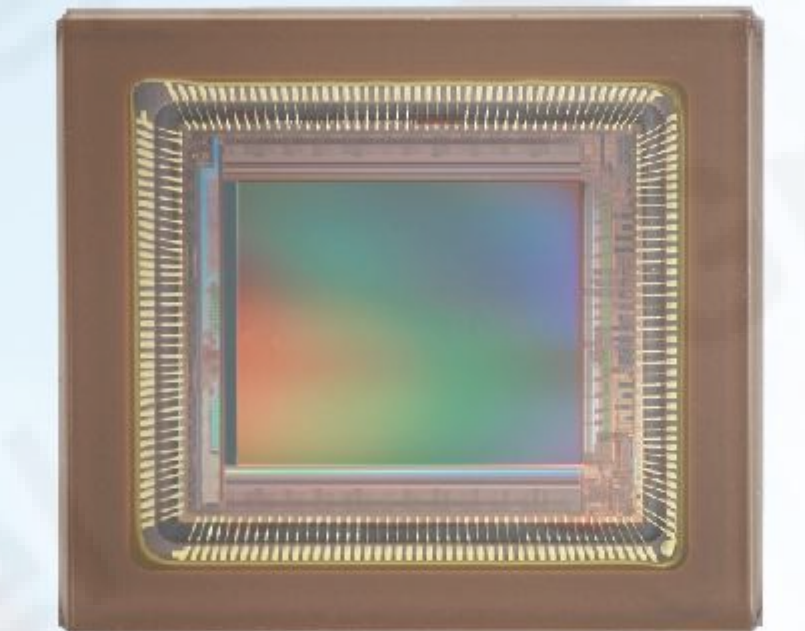
Nr of Active Pixels	2048 (H) x 1200 (V)	Pixel size	4.0 μ m x 4.0 μ m
Optical format	1/1.7"	Shutter type	Global shutter
Photosensitive area	8.2 mm x 4.8 mm (9.5 mm diameter)	Full well capacity	11.6 ke ⁻
Peak QE	73.7% @ 550 nm	Temporal noise	2.6 e ⁻
Parasitic Light Sensitivity	-92.0 dB	Dark Current	8.3 e ⁻ /pixel/s @ 37°C
Angular response	> 17 degree (80% response)	Dynamic Range	68.0 dB @ 12 bit, 64.4 dB @ 10 bit
Max. SNR	40.7 dB	ADC	10/12 bit
Max Frame rate	344 fps @ 10 bit	Channel multiplexing	8/4/2/1 @ sub-LVDS, 4/2/1 @ MIPI
Output format	8 ch sub-LVDS , 4 ch MIPI	Chroma	Mono, Mono (NIR enhanced), RGB Color
Max. Data rate	9.6 Gbps	Supply voltage	3.3 V (analog), 1.8 V – 3.3 V (IO), 1.2 V (digital)
Power consumption	<0.5 W	Package	CLCC 74-pins (16.6 mm x 12.9 mm)

Package Drawing



GMAX3405

5MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX3405 is a 2/3" optical format CMOS image sensor with 2448 x 2048 effective pixels and frame rates up to 164/100 fps in 10/12-bit mode with sub-LVDS interface and 73 fps over the 4 alternative MIPI DPHY channels. Based on a high-performance 3.4 μ m charge-domain global shutter pixel, GMAX3405 achieves a maximum full well capacity of 10 ke⁻ and minimum dark noise of 1.5 e⁻, delivering 68.8 dB linear dynamic range. Red Fox technology delivers QE of 75% @ 540 nm, and a NIR QE of 33% @ 850 nm. GMAX3405 is housed in a 176 pin ceramic LGA package with outer dimensions 17.6 mm x 15.8 mm, and is pin-compatible with GMAX3412.

Key features and Benefits

- NIR enhanced
- Low noise global shutter
- Ultra-short exposure time
- High dynamic range

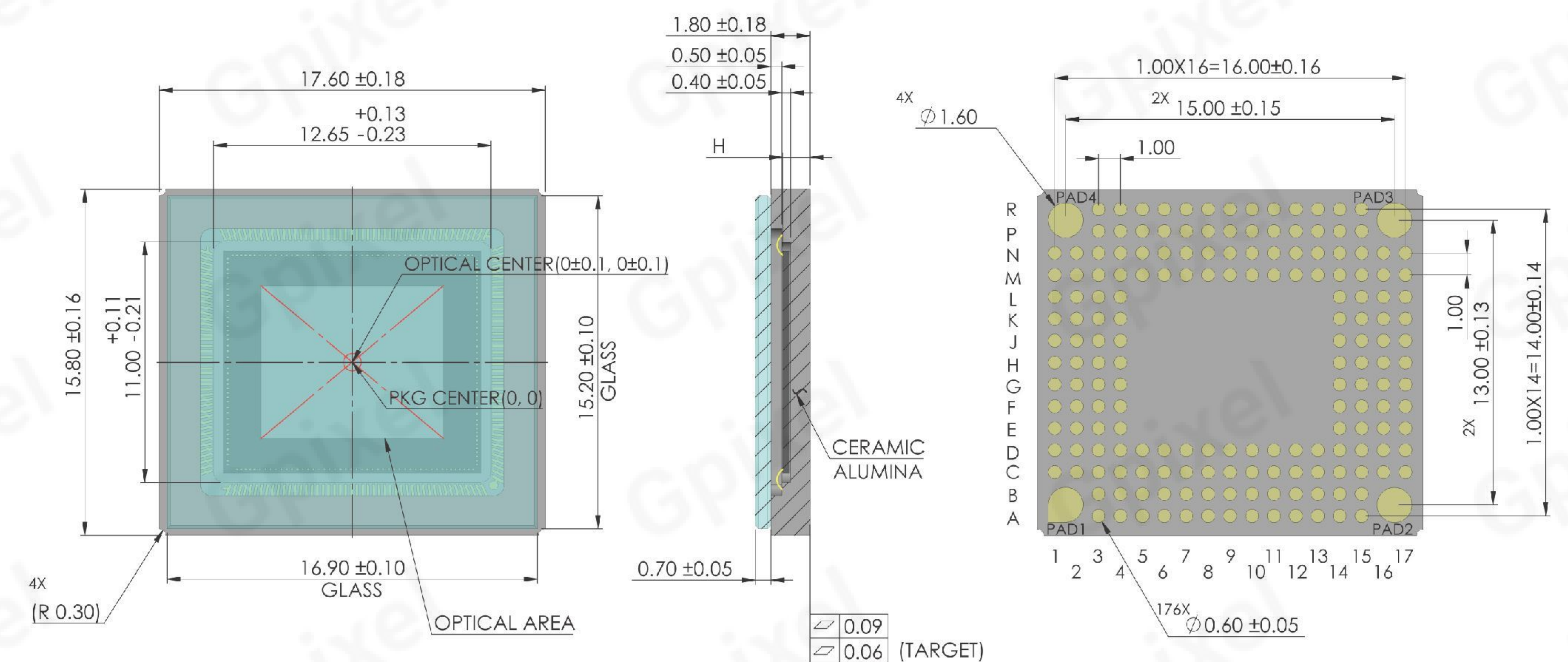
Application

- Automation & Inspection
- Intelligent Transport Systems

Specifications

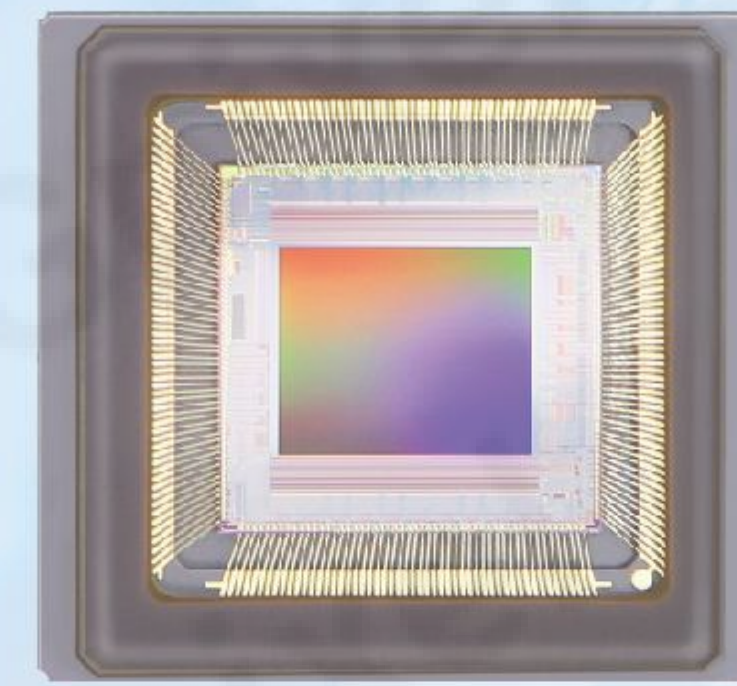
Nr of Active Pixels	2448 (H) x 2048 (V)	Pixel size	3.4 μ m x 3.4 μ m
Optical format	2/3"	Shutter type	Global shutter
Photosensitive area	8.3 mm x 7.0 mm	Full well capacity	10 ke ⁻ @ 12-bit and 1x PGA gain
Peak QE	75% @ 540 nm, 33% @ 850 nm	Temporal noise	3.6 e ⁻ @ 1x PGA gain, 1.5 e ⁻ @ 16x PGA gain
Parasitic Light Sensitivity	-88 dB	Dark Current	6.5 e ⁻ /pixel/s @ 35°C
Angular response	> 15 (80% response)	Dynamic Range	68.8 dB
Max. SNR	40.0 dB	ADC	10/12 bit
Max Frame rate	164 fps @ LVDS @ 10 bit, 100 fps @ LVDS @ 12 bit	Channel multiplexing	12/10/8/6/4/2/1
Output format	12 ch sub-LVDS	Chroma	Mono (NIR enhanced), RGB Color
Max. Data rate	9.6 Gbps @ Sub-LVDS, 4.8 Gbps @ MIPI	Supply voltage	3.3V/3.6V (analog), 1.8V-3.3V (IO), 1.2V (digital)
Power consumption	<1.5 W	Package	176 pins LGA (17.6 mm x 15.8 mm)

Package Drawing



GMAX2505

5MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX2505 achieves more than 65% peak QE and excellent angular response. Thanks to the latest light pipe technology, more than -80 dB shutter efficiency can be achieved. The sensor supports both 10 bit and 12 bit output, with frame rate up to 290 fps and 121 fps respectively. It is assembled in a ceramic LGA package, allowing easy integration and mass production.

GMAX2505 is pin-compatible with GMAX0505, GMAX2509 and GMAX2518. All four sensors are designed with the same 2.5 μm global shutter pixel architecture and sequencer operation, allowing reduced system costs and simplified camera development.

Key features and Benefits

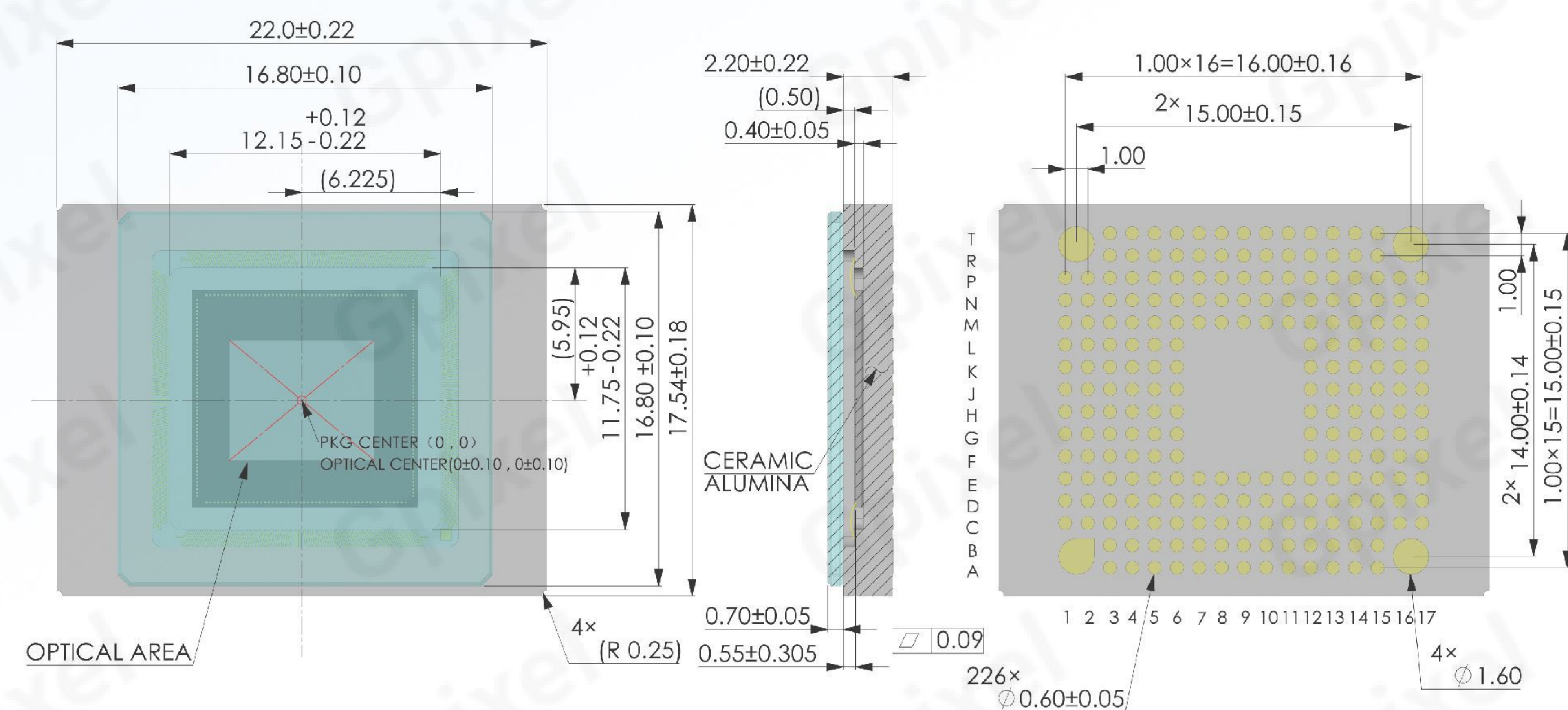
- High resolution in 1/2" optical format
- High data throughput > 26 Gbps
- Low noise global shutter

Application

- Automation & Inspection
- Logistic & Positioning
- Metrology
- Motion Capture

Specifications			
Nr of Active Pixels	2600 (H) x 2160 (V)	Pixel size	2.5 μm x 2.5 μm
Optical format	1/2"	Shutter type	Global shutter
Photosensitive area	6.5 mm x 5.4 mm	Full well capacity	6.7 ke ⁻
Peak QE	65.5% @ 500 nm	Temporal noise	1.8 e ⁻
Parasitic Light Sensitivity	-80.0 dB	Dark Current	1.2 e ⁻ /pixel/s @ 30°C
Angular response	> 13 (80% response)	Dynamic Range	65.5 dB @12 bit, 62.1 dB @10 bit
Max. SNR	38.2 dB	ADC	10/12 bit
Max Frame rate	290 fps @ 10 bit	Channel multiplexing	20/10/8/6/4/2
Output format	20 ch sub-LVDS	Chroma	Mono & RGB Color
Max. Data rate	19.20 Gbps	Supply voltage	3.3 V/1.3 V(analog), 1.8 V-3.3 V(IO), 1.3 V(digital)
Power consumption	<0.6 W @ 12 bit, <0.9 W @ 10 bit	Package	226 pins LGA (19.0 mm x 17.5 mm)

Package Drawing



GMAX2509

9MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX2509 achieves more than 65% peak QE and excellent angular response. Thanks to the latest light pipe technology, more than -80 dB shutter efficiency can be achieved. The sensor supports both 10 bit and 12 bit output, with frame rate up to 290 fps and 121 fps respectively. It is assembled in a ceramic LGA package, allowing easy integration and mass production.

GMAX2509 is pin-compatible with GMAX0505, GMAX2505 and GMAX2518. All four sensors are designed with the same 2.5 μm global shutter pixel architecture and sequencer operation, allowing reduced system costs and simplified camera development.

Key features and Benefits

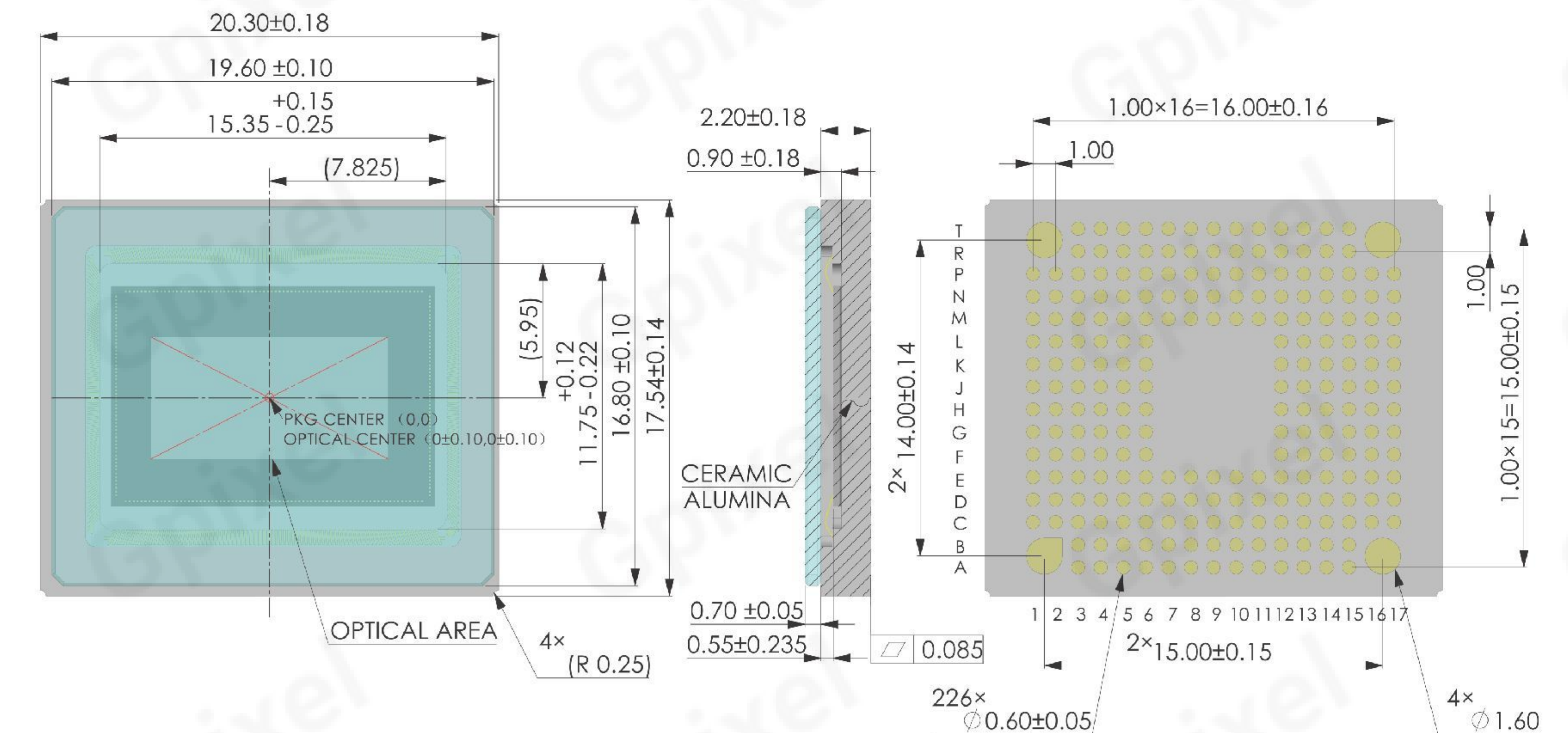
- High resolution in 2/3" optical format
- High data throughput > 26 Gbps
- Low noise global shutter

Application

- Automation & Inspection
- Logistic & Positioning
- Metrology
- Motion Capture

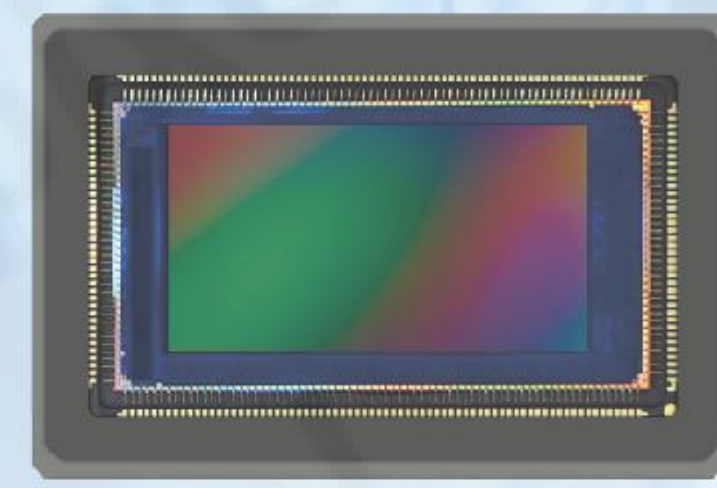
Specifications			
Nr of Active Pixels	4200 (H) x 2160 (V)	Pixel size	2.5 μm x 2.5 μm
Optical format	2/3"	Shutter type	Global shutter
Photosensitive area	10.5 mm x 5.4 mm	Full well capacity	6.7 ke ⁻
Peak QE	65.5% @ 500 nm	Temporal noise	1.8 e ⁻
Parasitic Light Sensitivity	-80.0 dB	Dark Current	1.2 e ⁻ /pixel/s @ 30°C
Angular response	> 13 (80% response)	Dynamic Range	65.5 dB @12 bit, 62.1 dB @10 bit
Max. SNR	38.2 dB	ADC	10/12 bit
Max Frame rate	290 fps @ 10 bit	Channel multiplexing	32/16/12/8/4/2
Output format	32 ch sub-LVDS	Chroma	Mono & RGB Color
Max. Data rate	30.72 Gbps	Supply voltage	3.3 V/1.3 V(analog), 1.8 V-3.3 V(IO), 1.3 V(digital)
Power consumption	<0.9 W @ 12 bit, <1.2 W @ 10 bit	Package	226 pins LGA (20.3 mm x 17.5 mm)

Package Drawing



GMAX3809

9MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX3809 delivers 9 MP resolution in a wide 1.1" optical format with low noise, charge domain global shutter pixels and frame rate of 65 fps with 12 bit ADC resolution and over 70 dB dynamic range. GMAX3809 is configurable through SPI or I2C and supports on-chip color offset calibration, LED flicker mitigation, multiple region HDR, and OTP functions. GMAX3809 is housed in a 163-pin ceramic LGA package with outer dimensions of 27.1 mm x 17.9 mm and an LGA pad pattern optimized for reliable solder connections. The sensor assembly includes a double sided, AR coated cover glass.

Key features and Benefits

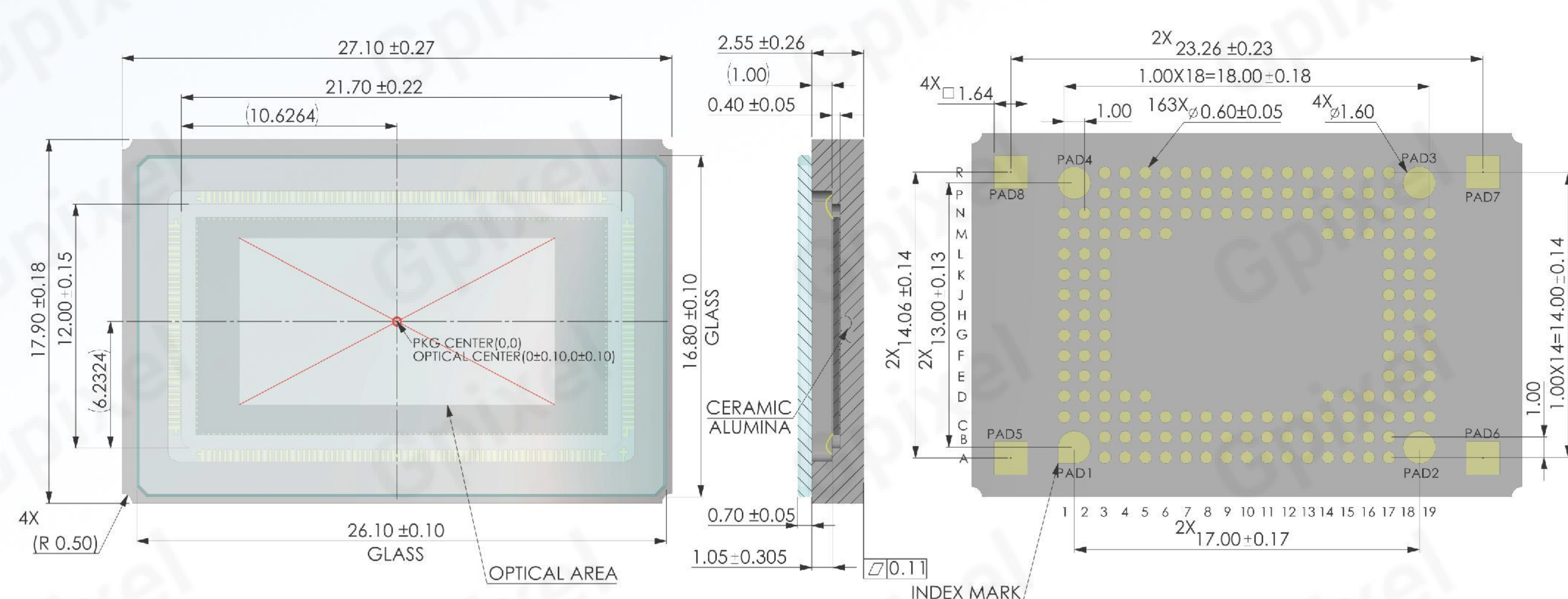
- Low noise global shutter
- On-chip color offset calibration
- Excellent PLS and angular response

Application

- Automation & Inspection
- Intelligent Transport Systems

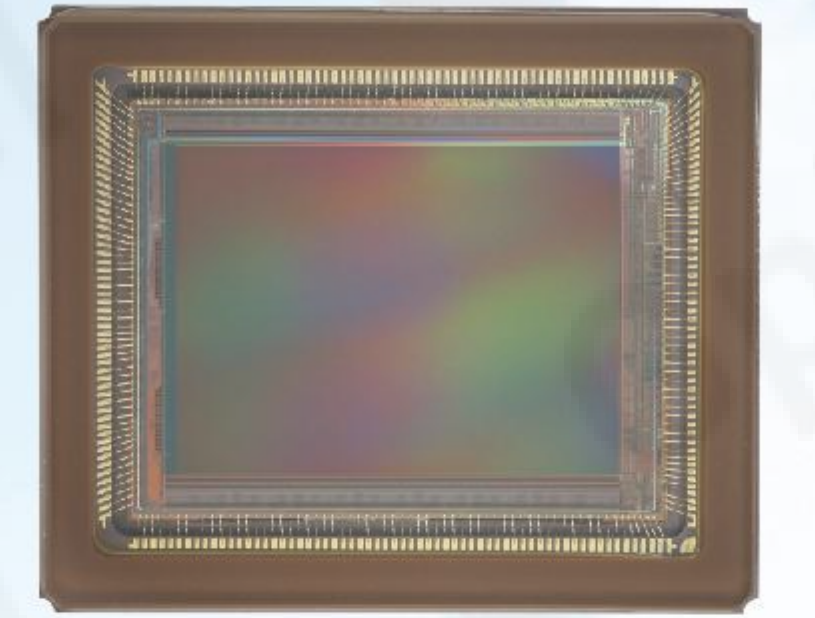
Specifications			
Nr of Active Pixels	4096 (H) x 2160 (V)	Pixel size	3.8 μm x 3.8 μm
Optical format	1.1"	Shutter type	Global shutter
Photosensitive area	15.6 mm x 8.2 mm	Full well capacity	11.2 ke ⁻
Peak QE	61.7% @ 540 nm	Temporal noise	2.2 e ⁻
Parasitic Light Sensitivity	-92.0 dB	Dark Current	31.5 e ⁻ /pixel/s @ 41°C
Angular response	> 15 (80% response)	Dynamic Range	70.7 dB
Max. SNR	40.5 dB	ADC	12 bit
Max Frame rate	54 fps @ 12bit	Channel multiplexing	8/4
Output format	8 ch sub-LVDS	Chroma	Mono (NIR enhanced),RGB Color
Max. Data rate	7.68 Gbps	Supply voltage	3.3 V/3.6 V(analog), 1.8 V-3.3 V(IO), 1.2 V(digital)
Power consumption	<1.0 W	Package	163 pins LGA (27.1 mm x 17.9 mm)

Package Drawing



GMAX3412

12MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX3412 is a 1.1" optical format CMOS image sensor with 4096 X 3072 effective pixels with frame rates up to 128/60 fps in 10/12-bit mode with sub-LVDS interface and 30 fps over the alternative 4 MIPI DPHY channels. Based on a high-performance 3.4 μm charge-domain global shutter pixel, GMAX3412 achieves a maximum full well capacity of 10 ke⁻ and minimum dark noise of 1.5 e⁻, delivering 68.8 dB linear dynamic range. Red Fox technology delivers QE of 75% @540 nm, and NIR QE of 33% @850 nm. GMAX3412 is housed in a 176 pin ceramic LGA package with outer dimensions 22.93 mm x 19.39 mm, and is pin-compatible with GMAX3405.

Key features and Benefits

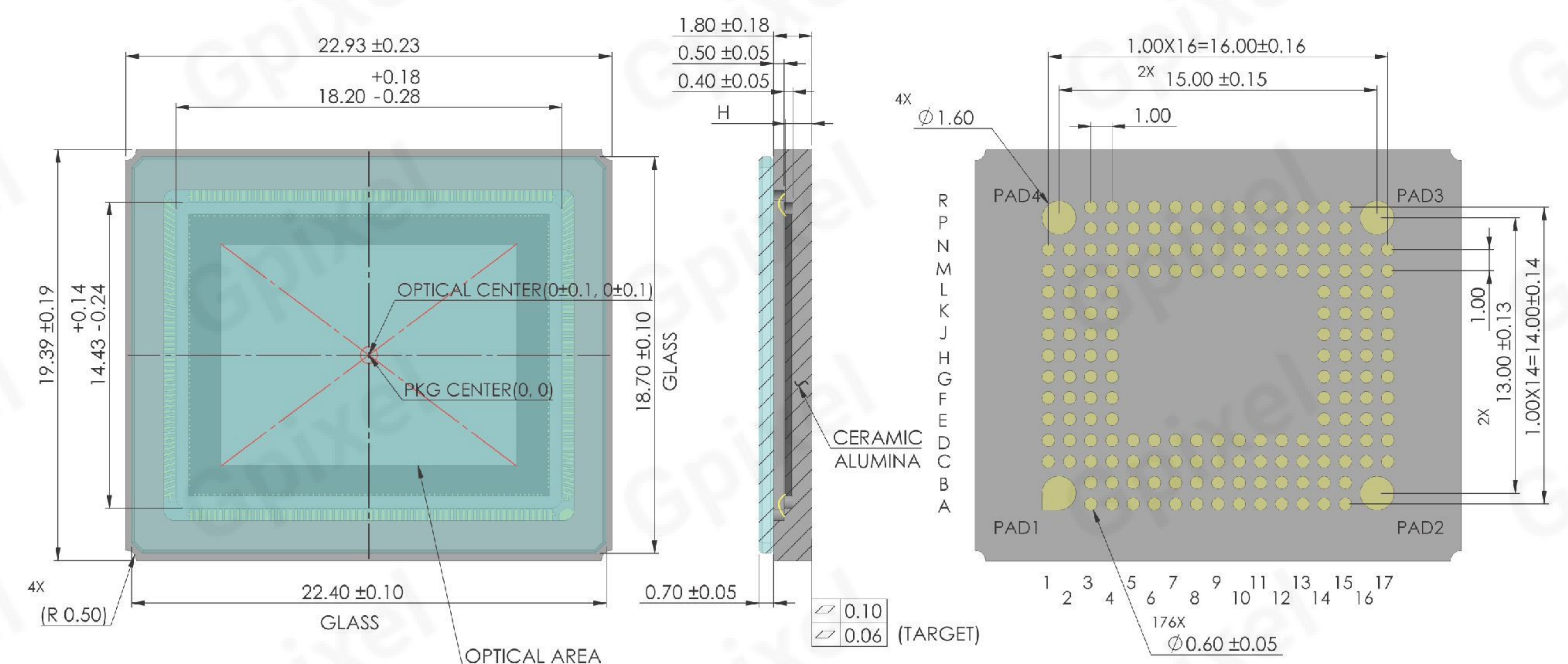
- NIR enhanced
- High dynamic range
- Low noise global shutter

Application

- Automation & Inspection
- Intelligent Transport Systems

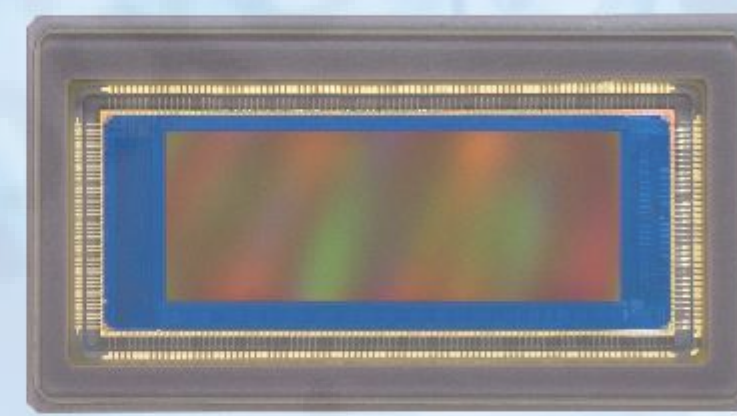
Specifications			
Nr of Active Pixels	4096 (H) x 3072 (V)	Pixel size	3.4 μm x 3.4 μm
Optical format	1.1"	Shutter type	Global shutter
Photosensitive area	14.0 mm x 10.5 mm	Full well capacity	10 ke ⁻ @ 12-bit and 1x PGA gain
Peak QE	75% @ 540 nm, 33% @ 850 nm	Temporal noise	1.5 e ⁻ at gain x16, 3.6 e ⁻ at gain x1
Parasitic Light Sensitivity	-88 dB	Dark Current	6.5 e ⁻ /pixel/s @ 35°C
Angular response	> 15 (80% response)	Dynamic Range	68.8 dB
Max. SNR	40.0 dB	ADC	10/12 bit
Max Frame rate	128 fps @LVDS @ 10 bit, 60 fps @LVDS @ 12 bit	Channel multiplexing	16/14/12/10/8/6/4/2/1
Output format	16 ch sub-LVDS ; 4 lanes MIPI	Chroma	Mono (NIR enhanced),RGB Color
Max. Data rate	19.2 Gbps @Sub-LVDS, 4.8 Gbps @ MIPI	Supply voltage	3.3V/3.6V (analog), 1.8V-3.3V (IO), 1.2V (digital)
Power consumption	<1.5 W	Package	176 pins LGA (22.93 mm x 19.39 mm)

Package Drawing



GMAX3413

12.7MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX3413 offers 12.7 MP resolution in a 4/3" optical format with a wide aspect ratio, providing optimal coverage of the field of view in applications such as Intelligent Transportation Systems (ITS), logistics, and parcel sorting. GMAX3413 supports on-chip color offset calibration, LED flicker mitigation, multiple region HDR, and OTP functions. GMAX3413 is housed in a 163-pin ceramic LGA package with outer dimensions of 32.7 mm x 17.9 mm and an LGA pad pattern optimized for reliable solder connections.

Key features and Benefits

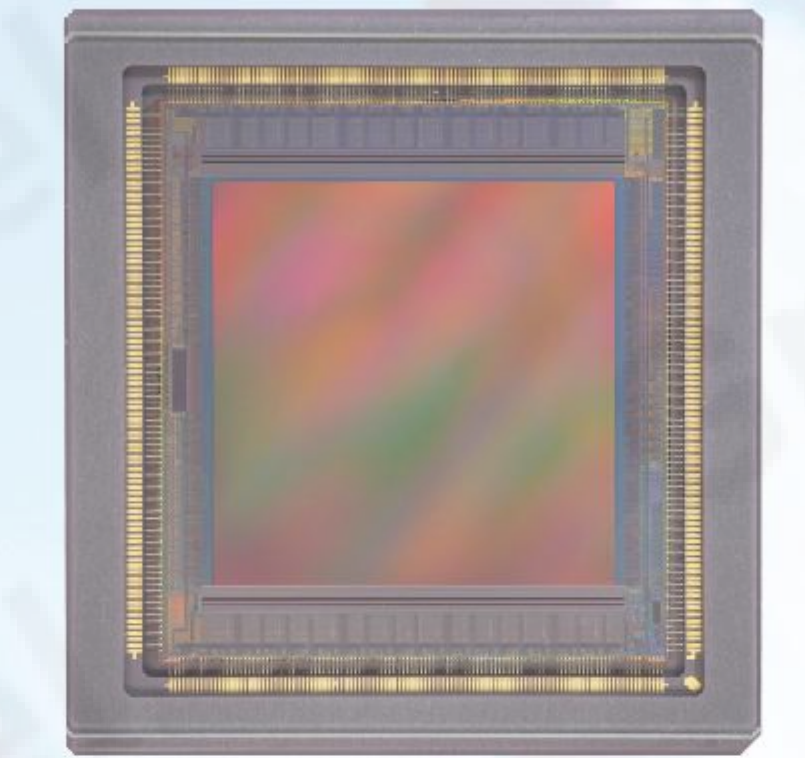
- Low noise, large size global shutter pixel provides optimal SNR
- LED flicker mitigation
- Vertical and horizontal ROI
- Excellent PLS and angular response
- Wide aspect ratio
- Multiple region HDR
- Vertical and horizontal image flipping
- On-chip color offset calibration

Application

- Automation & Inspection
- Intelligent Transport Systems

GMAX4416

16MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX4416 is a 1.6" optical format square CMOS image sensor with 4096 x 4096 (16.7 MP) effective pixels. Using advanced processing technology, the 4.4 μm global shutter pixel achieves a maximum full well capacity of 15 ke⁻ and minimum dark noise of 3.0 e⁻, delivering 73.9 dB linear dynamic range. GMAX4416 is housed in 152-pin ceramic μPGA package with outer dimensions of 31.70 mm x 30.40 mm. GMAX4416 can reach 80 fps in 12-bit standard high-speed mode utilizing 32 pairs sub-LVDS. It also supports 2x2 binning and a 2x2 binning HDR mode with frame rates of 42 fps and 80 fps respectively.

Key features and Benefits

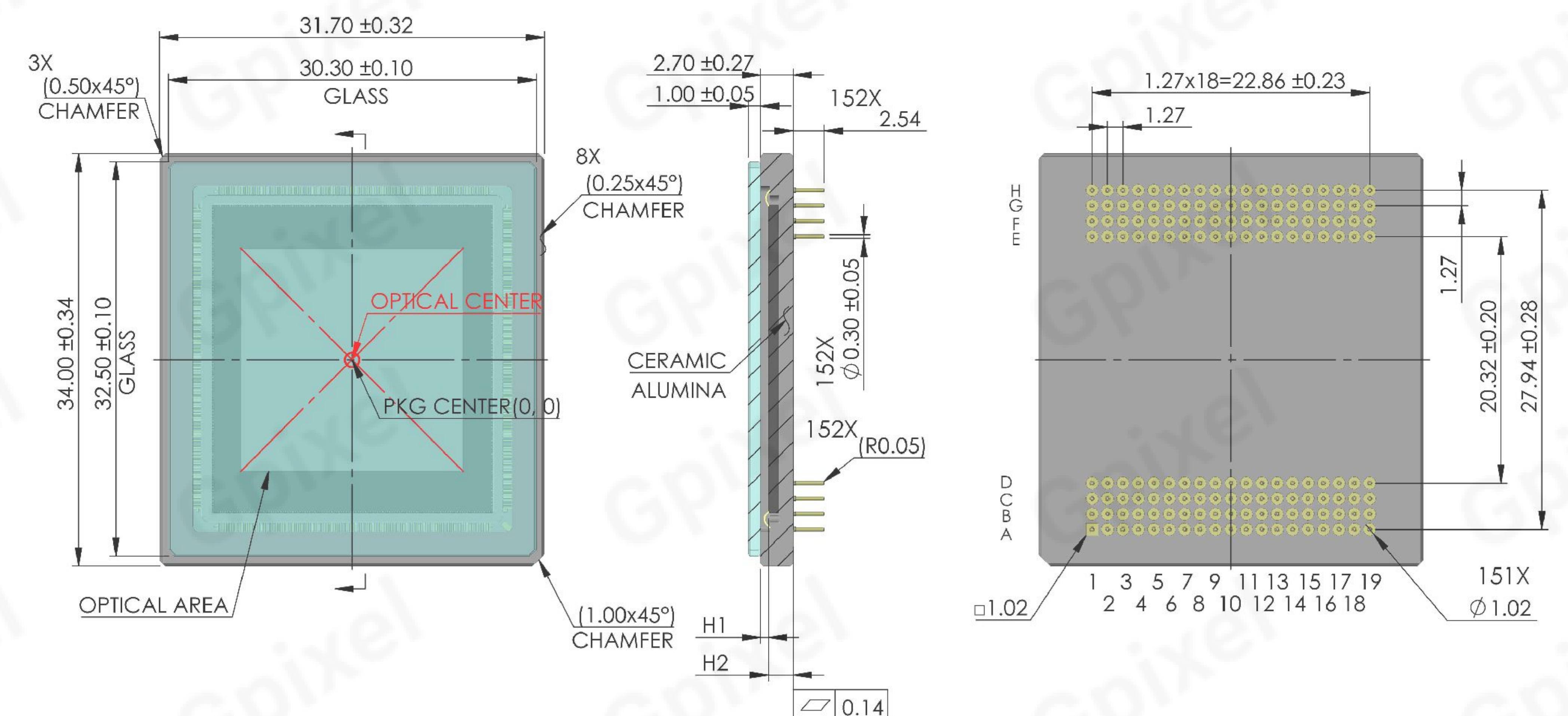
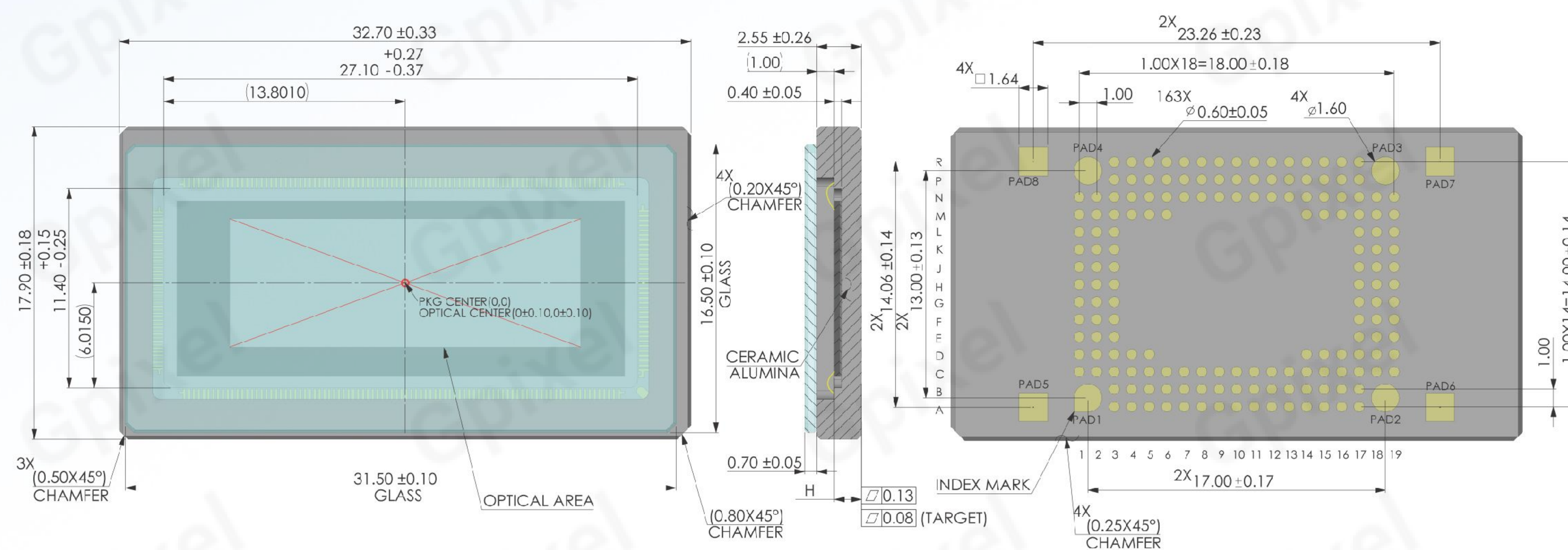
- Square format
- Dual Gain HDR
- High sensitivity
- High frame rate

Application

- Automation & Inspection
- Life Sciences
- Microscopy
- Motion Capture

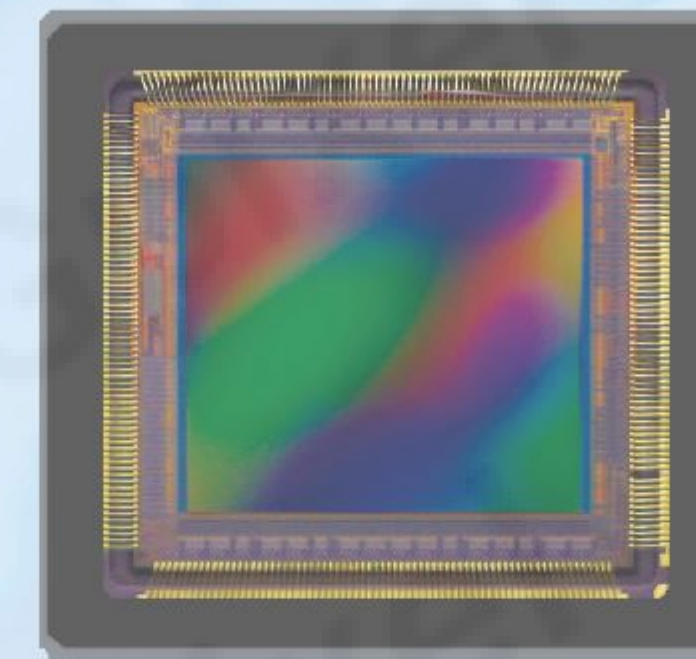
Specifications			
Nr of Active Pixels	5900 (H) x 2160 (V)	Pixel size	3.4 μm x 3.4 μm
Optical format	4/3"	Shutter type	Global shutter
Photosensitive area	20.1 mm x 7.3 mm	Full well capacity	8.6 ke ⁻
Peak QE	62.7% @ 540 nm	Temporal noise	2.31 e ⁻
Parasitic Light Sensitivity	< -92.0 dB	Dark Current	81 e ⁻ /pixel/s @ 35°C
Angular response	> 15 (80% response)	Dynamic Range	71.4 dB
Max. SNR	39.3 dB	ADC	12 bit
Max Frame rate	32 fps	Channel multiplexing	8/4
Output format	8 ch sub-LVDS	Chroma	Mono (NIR enhanced), RGB Color
Max. Data rate	7.68 Gbps	Supply voltage	3.3 V/3.6 V(analog), 1.8 V-3.3 V(IO), 1.3 V(digital)
Power consumption	<1.2 W	Package	163 pins LGA (32.7 mm x 17.9 mm)

Specifications			
Nr of Active Pixels	4096 (H) x 4096 (V)	Pixel size	4.4 μm x 4.4 μm
Optical format	1.6" (25.5 mm)	Shutter type	Global shutter
Photosensitive area	18.0 mm x 18.0 mm	Full well capacity	15 ke ⁻
Peak QE	70.5% @ 550 nm	Temporal noise	3.0 e ⁻
Parasitic Light Sensitivity	-91 dB	Dark Current	< 5 e ⁻ /pixel/s @ 28 C
Angular response	> 15 (80% response)	Dynamic Range	73.9 dB @HDR/68.7 dB @High speed mode/76.9 dB @Bin HDR
Max. SNR	41.7 dB	ADC	12 bit
Max Frame rate	42 fps @ HDR /80 fps @ High speed mode /80 fps @ Binning HDR	Channel multiplexing	16/14/12/10/8/6/4/2/1
Output format	32 pairs Sub-LVDS	Chroma	Mono
Max. Data rate	50 MHz	Supply voltage	3.3V (analog), 1.8V-3.3V (IO), 1.2V (digital)
Power consumption	<1.5 W	Package	152 pins μPGA (31.7 mm x 34.0 mm)



GMAX2518

18MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX2518 has an optical format of 1" and features 18 MP (4508 × 4096) global shutter pixels based on the proven GMAX 2.5 μm architecture, operating with true correlated double sampling (CDS) for low read noise and high dynamic range. In addition, the dual light pipe technology provides excellent PLS and angular response. With 32 pairs of sub-LVDS, each running at 960 MHz, the sensor outputs a maximum data rate of 30.72 Gbps, achieving a maximum frame rate of 139 fps in 10 bit mode and 64 fps in 12 bit mode. The sensor integrates an on-chip sequencer, programmable through SPI, and is designed to be fully pin-compatible with GMAX0505, GMAX2509 and GMAX2505 to significantly shorten time to market for camera manufactures.

Key features and Benefits

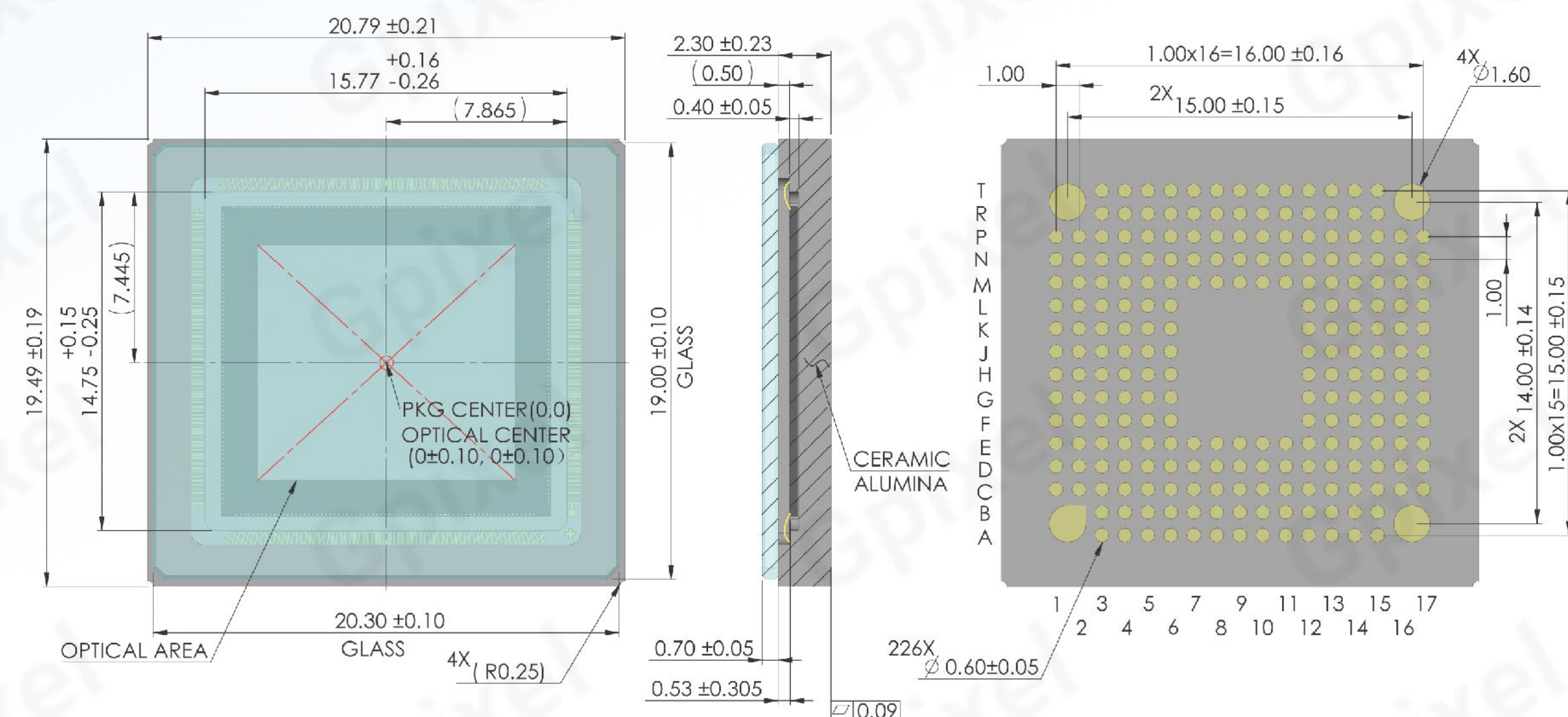
- High resolution in a 1" optical format
- Low noise global shutter
- Pin-compatible with GMAX0505/2509/2505

Application

- Automation & Inspection
- Logistic & Positioning
- Metrology

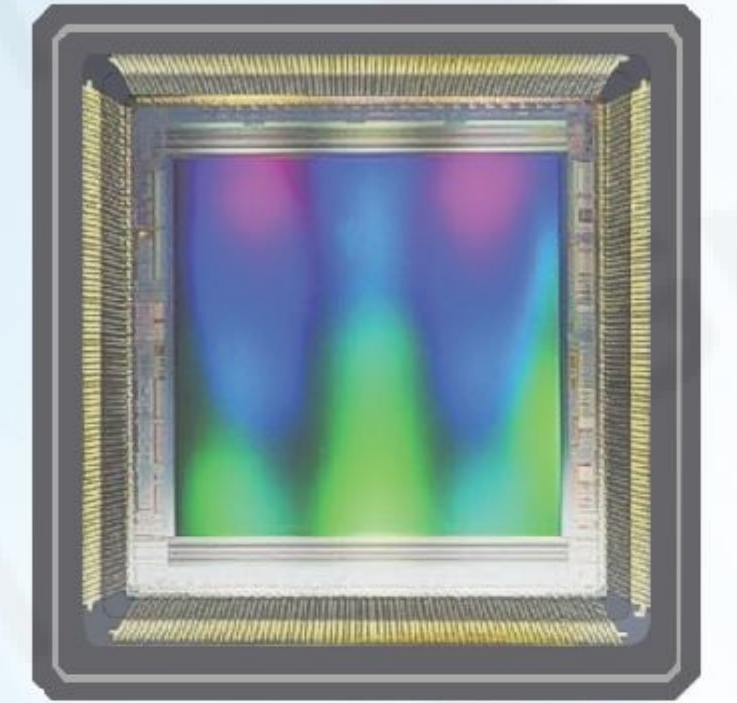
Specifications			
Nr of Active Pixels	4508 (H) x 4096 (V)	Pixel size	2.5 μm x 2.5 μm
Optical format	1"	Shutter type	Global shutter
Photosensitive area	11.3 mm x 10.2 mm	Full well capacity	8.0 ke ⁻
Peak QE	64.0% @ 520 nm	Temporal noise	1.7 e ⁻
Parasitic Light Sensitivity	-80 dB	Dark Current	6.5 e ⁻ /pixel/s @ 45°C
Angular response	> 12 (80% response)	Dynamic Range	66.9 dB @ 12 bit, 61.9 dB @ 10 bit
Max. SNR	39 dB	ADC	10/12 bit
Max Frame rate	139 fps @ 10 bit	Channel multiplexing	32/16/12/8/4/2
Output format	32 ch sub-LVDS	Chroma	Mono & RGB Color
Max. Data rate	30.72 Gbps	Supply voltage	3.3 V/1.3 V(analog), 1.8 V-3.3 V(IO), 1.3 V(digital)
Power consumption	<1.2 W @ 12 bit, <1.2 W @ 10 bit	Package	226 pins LGA (20.8 mm x 19.5 mm)

Package Drawing



GMAX0505

26MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX0505 offers 26 MP resolution in a square 1.1" optical format using a 2.5 μm charge domain global shutter pixel. Despite its small pixel pitch, GMAX0505 achieves more than 65% peak QE and dynamic range up to 65.8 dB. The optional Red Fox NIR enhanced version of the sensor delivers 33% QE at 850 nm. GMAX0505 provides excellent angular response thanks to the latest light pipe technology, and with optimized tungsten shielding structure on top of the pixel's memory node, the sensor's shutter efficiency is more than 80 dB. GMAX0505 supports 10 bit and 12 bit output modes and a maximum frame rate of 150 fps. The sensor is assembled in a 226-pin ceramic LGA package for easy integration and mass production.

Key features and Benefits

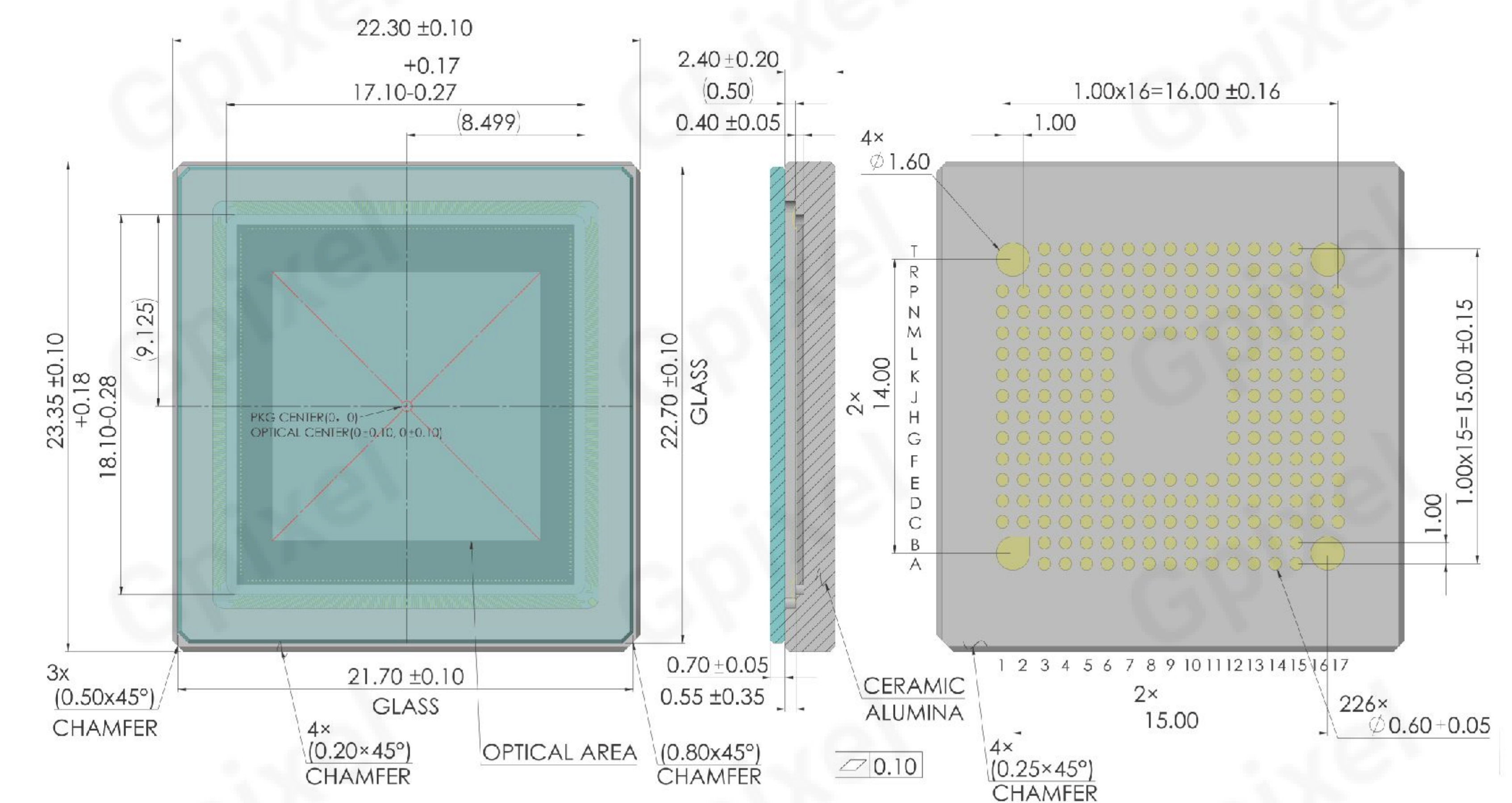
- 2.5 μm global shutter pixel
- High resolution in a 1.1" optical format
- Square optical format
- NIR enhanced option with Red Fox technology
- High speed and Good PLS
- Pin-compatible with GMAX2505, GMAX2509 and GMAX2518

Application

- Automation & Inspection
- Logistic & Positioning
- Metrology

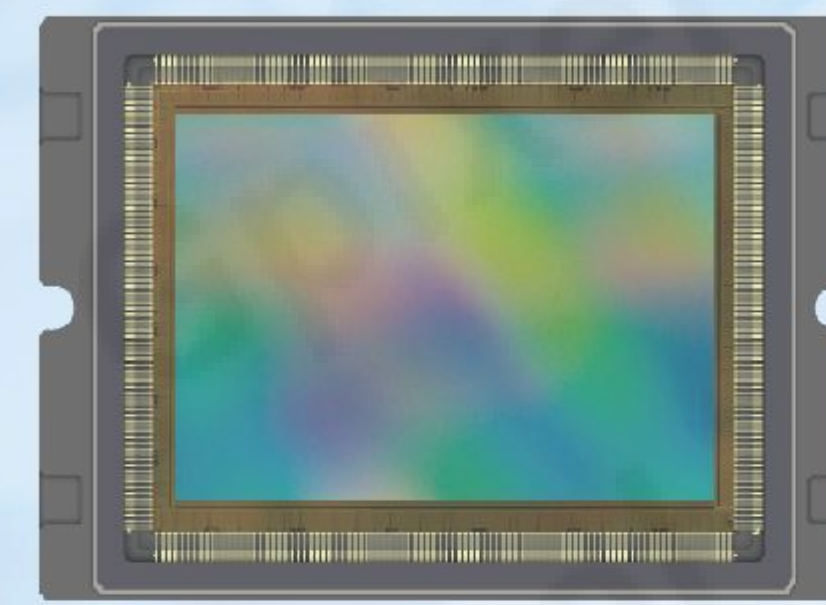
Specifications			
Nr of Active Pixels	5120 (H) x 5120 (V)	Pixel size	2.5 μm x 2.5 μm
Optical format	1.1"	Shutter type	Global shutter
Photosensitive area	12.8 mm x 12.8 mm	Full well capacity	6.5 ke ⁻
Peak QE	65.5% @ 500 nm	Temporal noise	1.6 e ⁻
Parasitic Light Sensitivity	-80 dB	Dark Current	1.0 e ⁻ /pixel/s @ 30°C
Angular response	> 13 (80% response)	Dynamic Range	65.8 dB @ 12 bit, 61.4 dB @ 10 bit
Max. SNR	38.1 dB	ADC	10/12 bit
Max Frame rate	150 fps @ 10 bit	Channel multiplexing	48/24/16/12/8/6/4/2
Output format	48 ch sub-LVDS	Chroma	Mono, Mono (NIR enhanced), RGB Color
Max. Data rate	46.08 Gbps	Supply voltage	3.3 V/1.3 V(analog), 1.8 V-3.3 V(IO), 1.3 V(digital)
Power consumption	<1.1W @ 12bit, <1.5 W @ 10 bit	Package	226 pins LGA (20.8 mm x 19.5 mm)

Package Drawing



GMAX4651

51MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX4651 is a 51 MP CMOS image sensor delivering 8k video at 30 fps in a 35 mm optical format, making it ideal for applications in broadcast imaging, surveillance, aerial mapping, inspection, and biometrics. It's large 4.6 μm pixel provides 65.5 dB of dynamic range, excellent sensitivity with a peak QE of 67%, and exceptional PLS at -92 dB. At full resolution and full speed, the power dissipated is less than 2.8 W. 12 bit data is delivered via 24 pairs of sub-LVDS channels, and channel multiplexing allows operation of the sensor through 14, 8, 6 or 4 channels. The sensor is assembled in a 238-pin PGA package for excellent reliability and heat dissipation.

Key features and Benefits

- High resolution in a 35 mm optical format
- Large, high sensitivity pixels
- Low noise global shutter

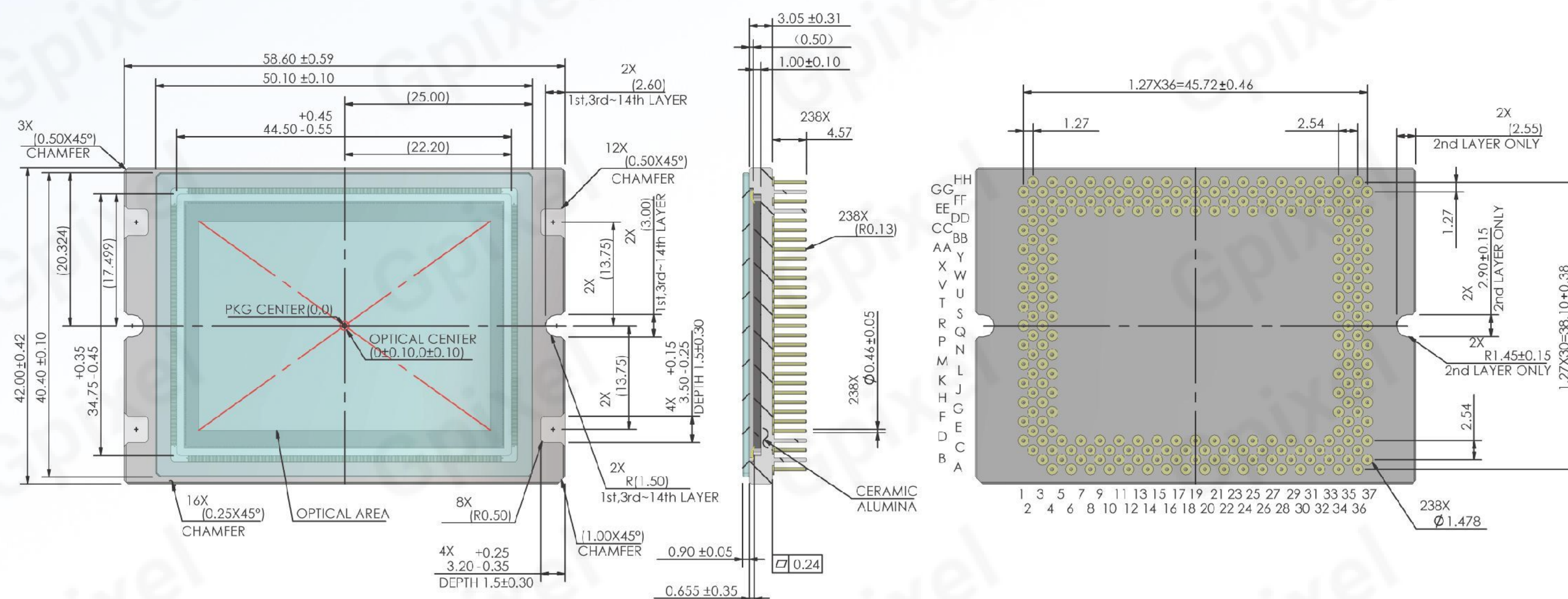
Application

- Automation & Inspection

Specifications

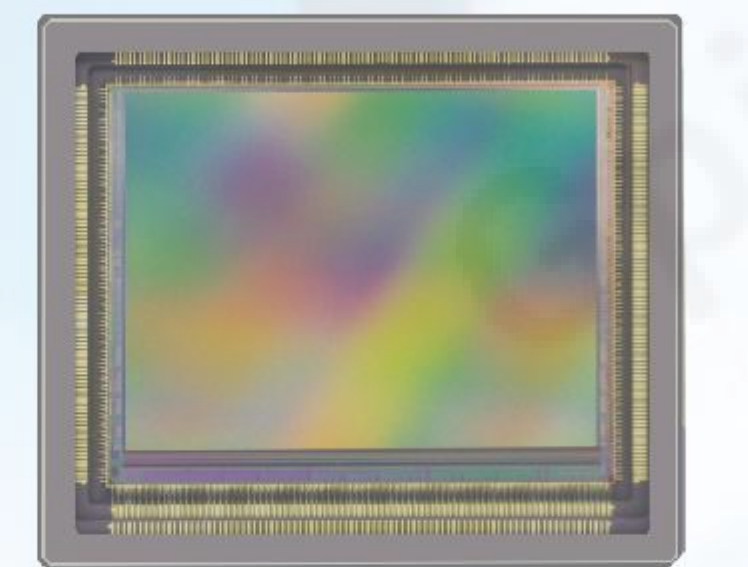
Nr of Active Pixels	8424 (H) x 6032 (V)	Pixel size	4.6 μm x 4.6 μm
Optical format	35mm Full Frame	Shutter type	Global shutter
Photosensitive area	38.8 mm x 27.8 mm	Full well capacity	18 ke ⁻
Peak QE	67.1% @ 510 nm	Temporal noise	7.6 e ⁻
Parasitic Light Sensitivity	-92 dB	Dark Current	6 e ⁻ /pixel/s @ 45°C
Angular response	> 15 (80% response)	Dynamic Range	65.5 dB
Max. SNR	42.5 dB	ADC	12 bit
Max Frame rate	30 fps @ 12 bit	Channel multiplexing	24/14/8/6/4
Output format	24 ch sub-LVDS	Chroma	Mono, RGB Color
Max. Data rate	20.74 Gbps	Supply voltage	3.3 V/1.3 V(analog), 1.8 V-3.3 V(IO), 1.3 V(digital)
Power consumption	<2.8 W	Package	238 pins PGA (58.6 mm x 42.0 mm)

Package Drawing



GMAX3265

65MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX3265 is a 65 MP CMOS image sensor sized to fit comfortably behind a 35 mm lens, making it a cost-effective solution for applications ranging from high end surveillance to high resolution inspection. Using advanced processing technology, the 3.2 μm global shutter pixel achieves 65% peak QE, excellent angular response, and a parasitic light sensitivity less than -83.5 dB. The sensor supports both 10 bit operation for a maximum frame rate of 71 fps, and 12 bit operation for a dynamic range over 66 dB at 31 fps and <2.1 W. The sensor is available in both monochrome and Bayer versions to support use in a variety of applications including machine vision, QA inspection, surveillance, biometrics, document imaging and flat panel inspection.

Key features and Benefits

- High resolution in compact optical format
- Low noise global shutter
- High speed and good PLS

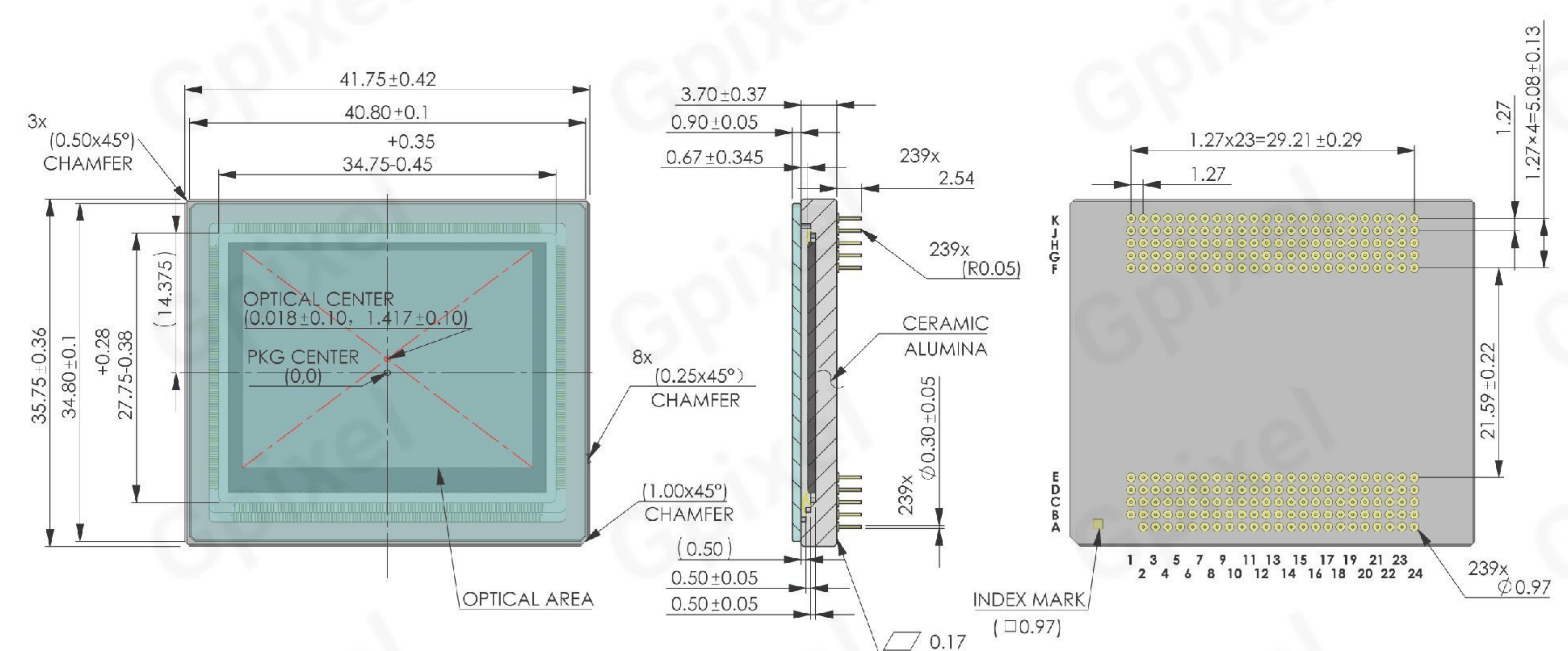
Application

- Automation & Inspection

Specifications

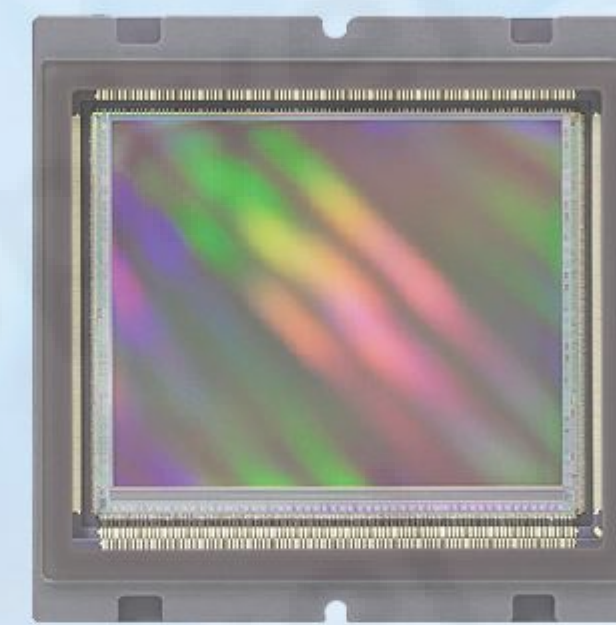
Nr of Active Pixels	9344 (H) x 7000 (V)	Pixel size	3.2 μm x 3.2 μm
Optical format	2.3"	Shutter type	Global shutter
Photosensitive area	29.9 mm x 22.4 mm	Full well capacity	10.9 ke ⁻
Peak QE	65.3% @ 500 nm	Temporal noise	1.9 e ⁻
Parasitic Light Sensitivity	-83.5 dB	Dark Current	5.3 e ⁻ /pixel/s @ 40°C
Angular response	> 15 (80% response)	Dynamic Range	66.0 dB @ 12 bit, 62.3 dB @ 10 bit
Max. SNR	40.3 dB	ADC	10/12 bit
Max Frame rate	71 fps @10 bit	Channel multiplexing	56/28/14/8/7/4/2/1
Output format	56 ch sub-LVDS	Chroma	Mono, RGB Color
Max. Data rate	50.40 Gbps	Supply voltage	3.3 V/1.3 V(analog), 1.8 V-3.3 V(IO), 1.3 V(digital)
Power consumption	<2.1 W @ 12 bit, <2.3 W @ 10 bit	Package	239 pins uPGA (41.8 mm x 35.8 mm)

Package Drawing



GMAX32103

103MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX32103 is a 103 MP CMOS image sensor in a 2.9" optical format. Using advanced processing technology, the 3.2 μm global shutter pixel achieves 66.9% peak QE @ 500nm, excellent angular response, and a parasitic light sensitivity of -83.9 dB. The sensor supports 12 bit operation for a maximum frame rate of 24 fps. Channel multiplexing of the 52 pairs of sub-LVDS channels allows for optimization between speed and dynamic range to suit the application. The sensor is available in both monochrome and Bayer versions to support use in a variety of applications including machine vision, QA inspection, aerial imaging, surveillance, biometrics, document imaging and flat panel inspection.

Key features and Benefits

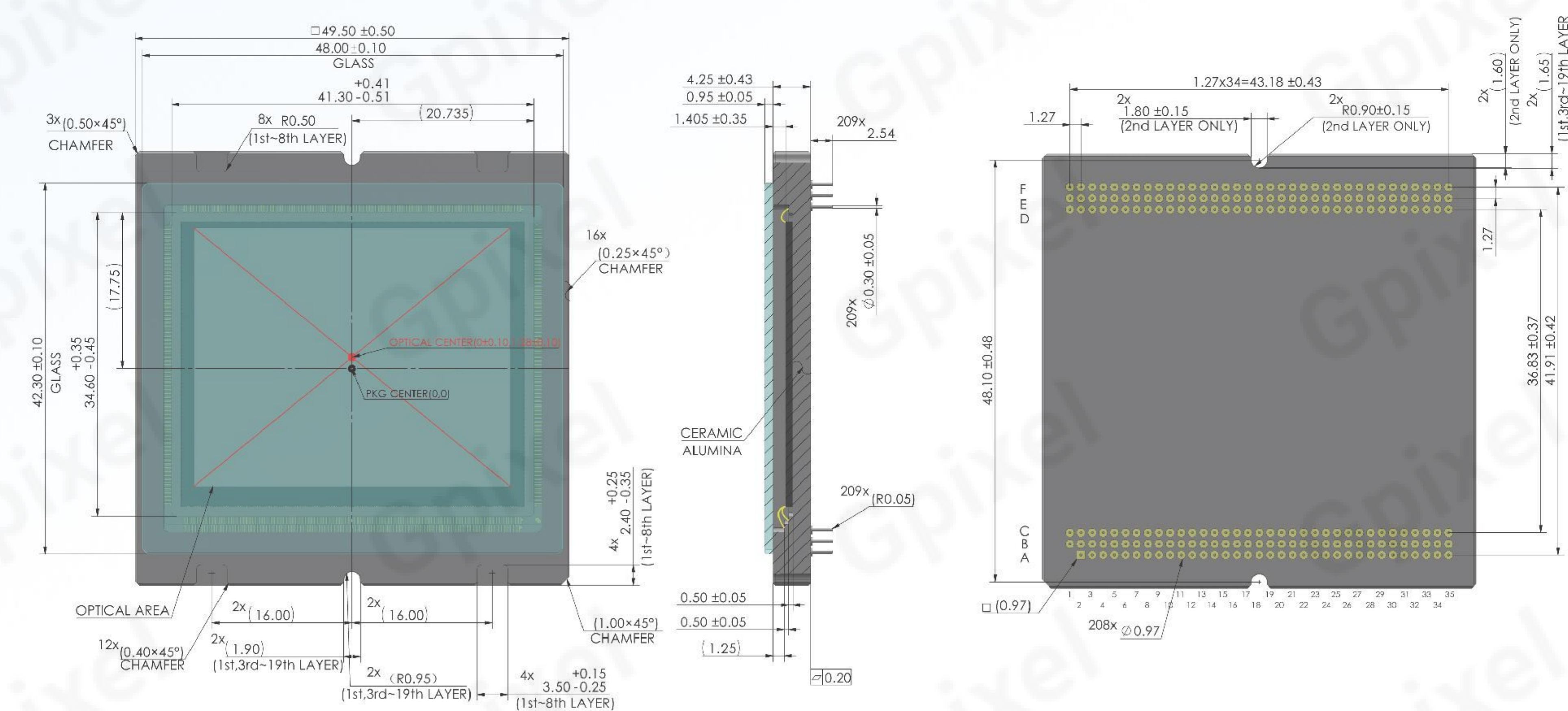
- High resolution in compact optical format
- High speed and good PLS
- High data throughput

Application

- Automation & Inspection
- Aerial Imaging

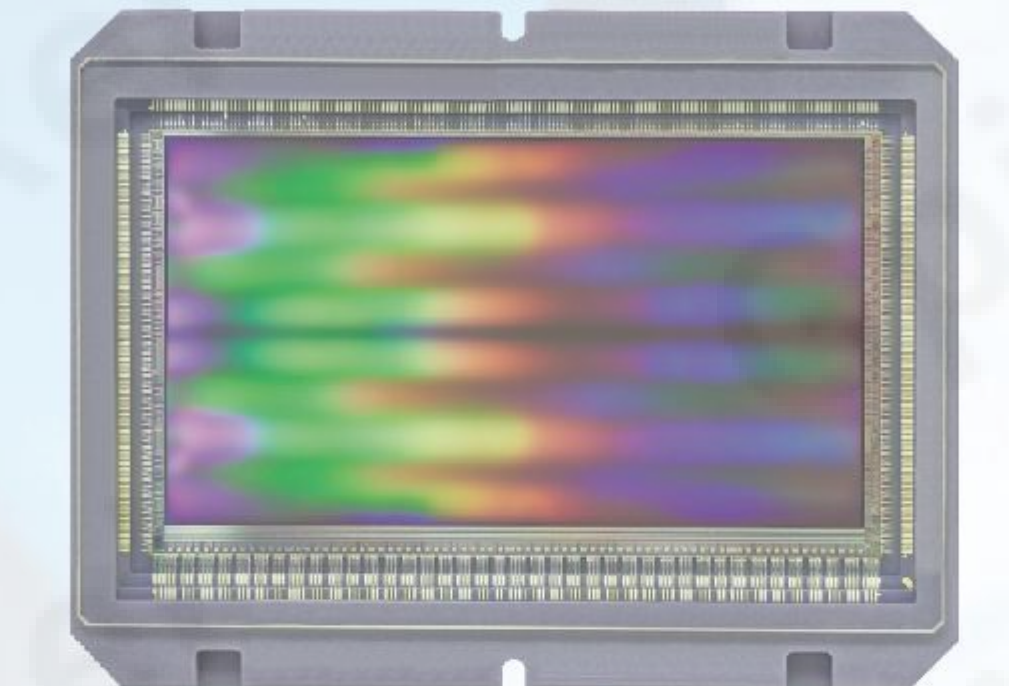
Specifications			
Nr of Active Pixels	11276 (H) x 9200 (V)	Pixel size	3.2 μm x 3.2 μm
Optical format	2.9"	Shutter type	Global shutter
Photosensitive area	36.1 mm x 29.4 mm	Full well capacity	9 ke ⁻
Peak QE	66.9% @ 500 nm	Temporal noise	2.8 e ⁻
Parasitic Light Sensitivity	-83.5 dB	Dark Current	1.4 e ⁻ /pixel/s @ 30°C
Angular response	> 15 (80% response)	Dynamic Range	66.4 dB
Max. SNR	39.5 dB	ADC	12 bit
Max Frame rate	24 fps @12 bit	Channel multiplexing	52/26/18/14/10/8/6
Output format	52 ch sub-LVDS	Chroma	Mono, RGB Color
Max. Data rate	49.92 Gbps	Supply voltage	3.3 V/1.3 V(analog), 1.8 V – 3.3 V(I/O), 1.2 V(digital)
Power consumption	<2.5 W	Package	209 pins uPGA (49.5 mm x 42.3 mm)

Package Drawing



GMAX32152

152MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GMAX32152 is a 152 MP CMOS image sensor in a wide 3.7" optical format. Using advanced processing technology, the 3.2 μm global shutter pixel achieves 66.9% peak QE @ 500nm, excellent angular response, and a parasitic light sensitivity of -83.5 dB. The sensor supports 12 bit operation for a maximum frame rate of 16 fps. Channel multiplexing of the 38 pairs of sub-LVDS allows for optimization between speed and dynamic range to suit the application. The sensor is available in both monochrome and Bayer versions to support use in a variety of applications including machine vision, aerial imaging, and document imaging.

Key features and Benefits

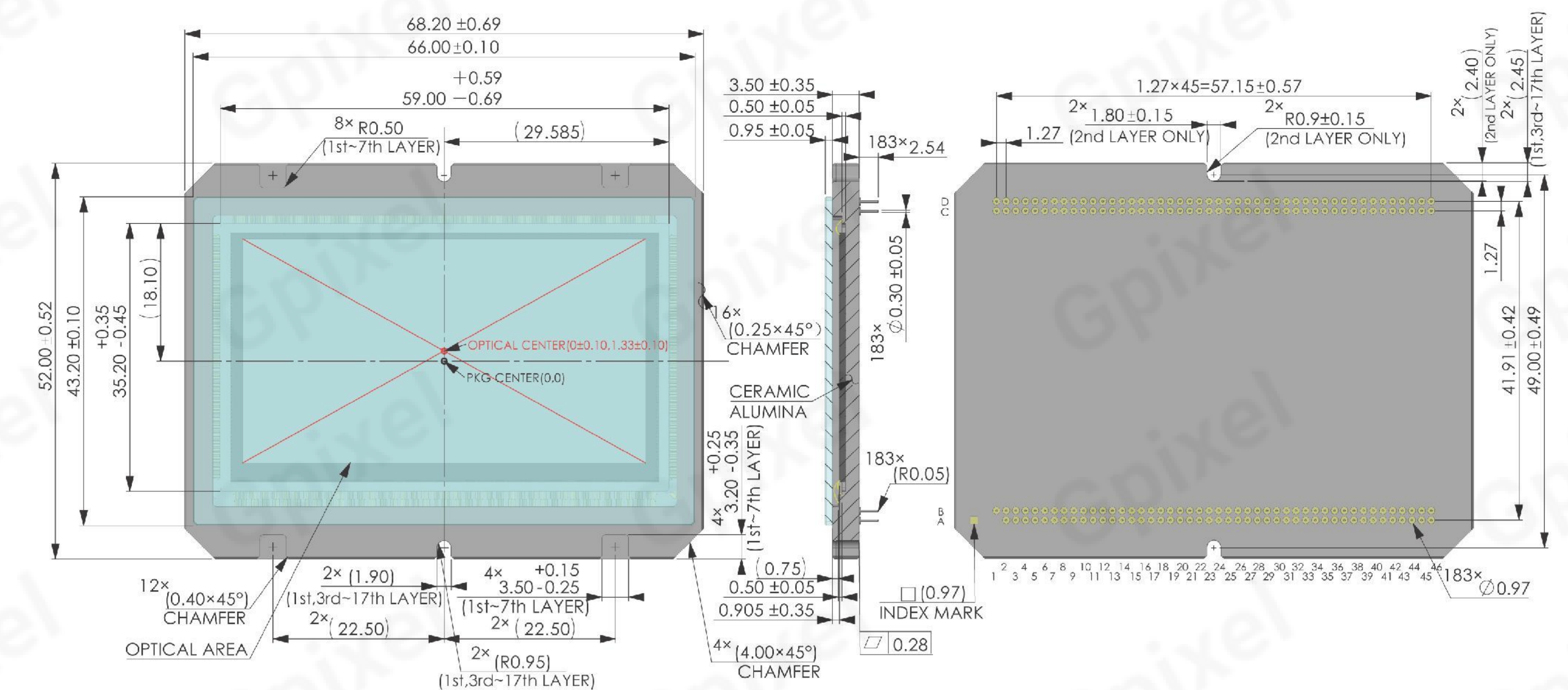
- Highest resolution global shutter
- Low noise global shutter
- 1.8:1 wide aspect ratio

Application

- Automation & Inspection
- Aerial Imaging
- Document Imaging

Specifications			
Nr of Active Pixels	16556 (H) x 9200 (V)	Pixel size	3.2 μm x 3.2 μm
Optical format	3.7"	Shutter type	Global shutter
Photosensitive area	53.0 mm x 29.4 mm	Full well capacity	9.3 ke ⁻
Peak QE	66.9% @ 500 nm	Temporal noise	4.0 e ⁻
Parasitic Light Sensitivity	-83.5 dB	Dark Current	1.4 e ⁻ /pixel/s @ 30°C
Angular response	> 15 (80% response)	Dynamic Range	67.3 dB
Max. SNR	39.5 dB	ADC	12 bit
Max Frame rate	16 fps @ 12 bit	Channel multiplexing	38/20/14/11/8/5
Output format	38 ch sub-LVDS	Chroma	Mono, RGB Color
Max. Data rate	36.48 Gbps	Supply voltage	3.3 V/1.3 V(analog), 2.5 V – 3.3 V(I/O), 1.2 V(digital)
Power consumption	<2.8 W	Package	183 pins μPGA (68.2 mm x 52.0 mm)

Package Drawing



GMAX | **GSPRINT** | GSENSE | GLUX | GTOF | GCINE | GL

Area Scan CMOS Image Sensor

The GSPRINT series is Gpixel's high-speed global shutter product family, with resolutions ranging from 2 MP to 21MP and frame rates up to 3462 fps.

GSPRINT6502BSI

GSPRINT4502

GSPRINT4510

GSPRINT5514BSI

GSPRINT4521

Product Family Features

- Global Shutter
- High speed
- 2MP-21MP resolution
- Low noise

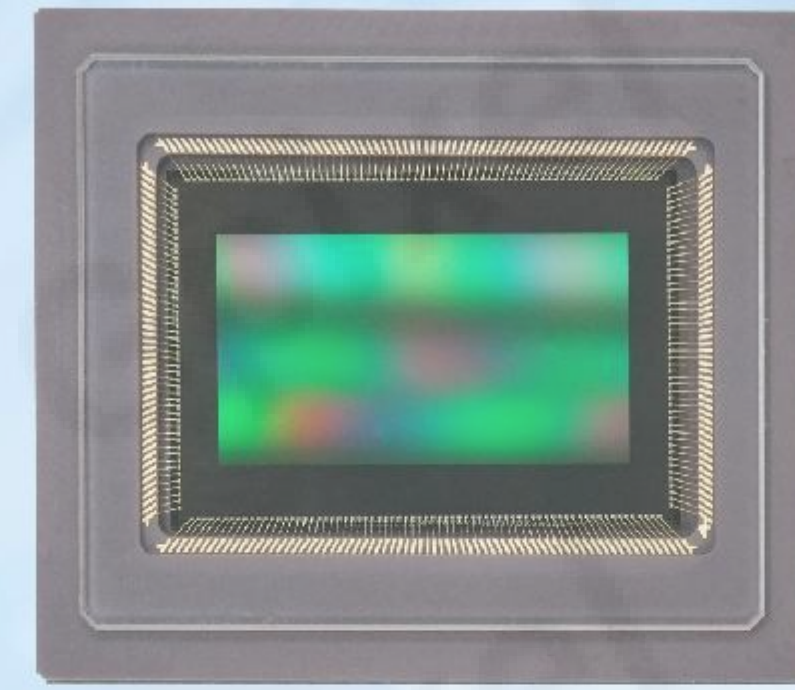
Applications

- Automation & Inspection
- High-throughput scientific imaging
- Slow motion video
- 3D Laser Profiling



GSPRINT6502BSI

2MP GLOBAL SHUTTER CMOS IMAGE SENSOR



GSPRINT6502BSI is a backside illuminated global shutter CMOS image sensor with 2048 (H) x 1152 (V) pixels, each 6.5 μm square, providing a wide format and compatibility with 1" optics. The combination of backside illumination and a large 6.5 μm pixel maximize light collection in high-speed imaging applications including 3D laser profiling and scientific imaging. With 10-bit output and 32 pairs of sub-LVDS outputs each operating at 1.2 Gbps, the GSPRINT6502BSI achieves 1500 frames per second. Up to 8 vertically oriented regions of interest can be defined to operate the sensor at increased frame rates. For applications in which the maximum frame rate is not required, multiplexing modes are available to reduce the number out output channels by any multiple of 2.

Key features and Benefits

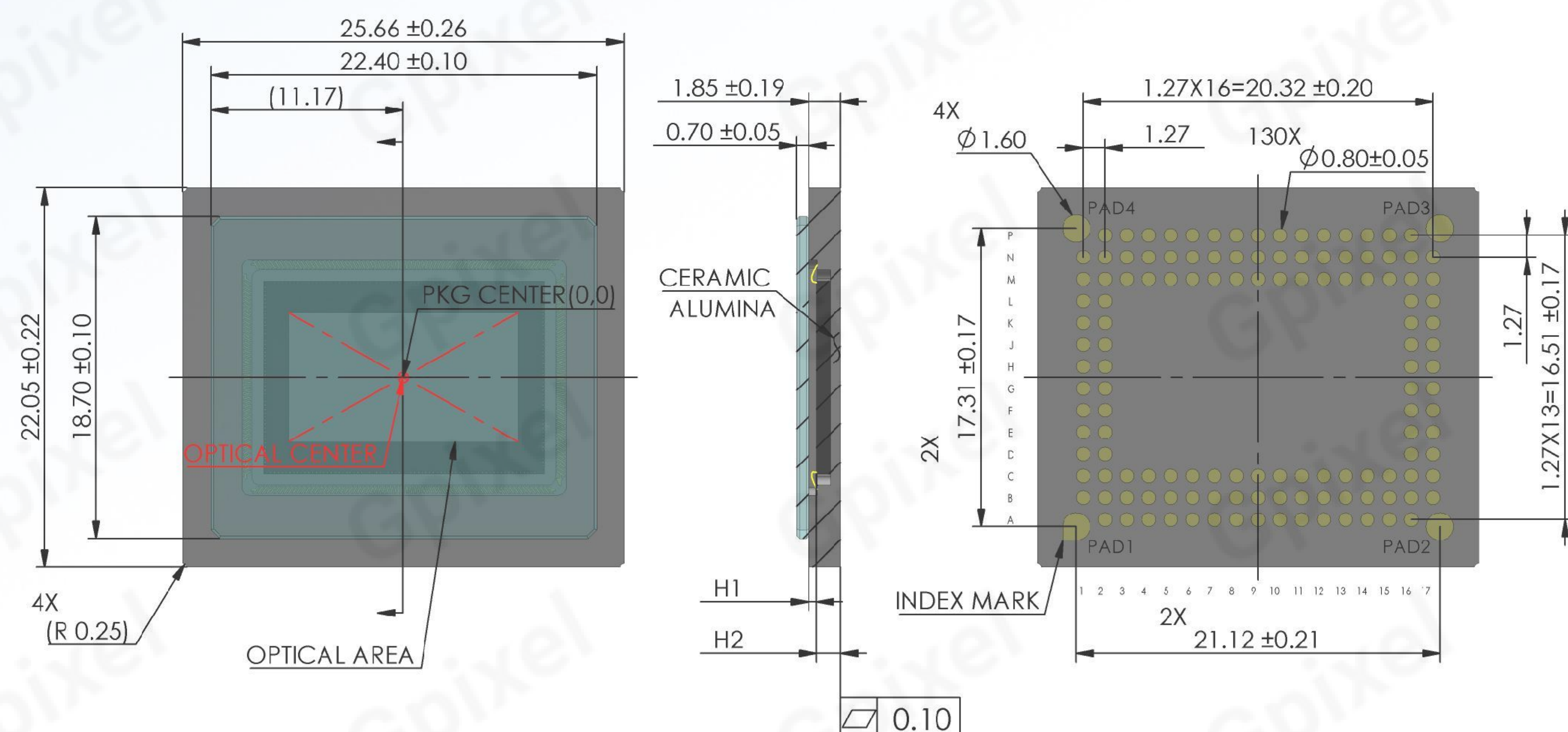
- BSI
- Multi-slope HDR
- High frame rate
- High speed
- High QE

Application

- Automation & Inspection
- Spectroscopy
- Life Sciences
- Microscopy
- High Speed Imaging

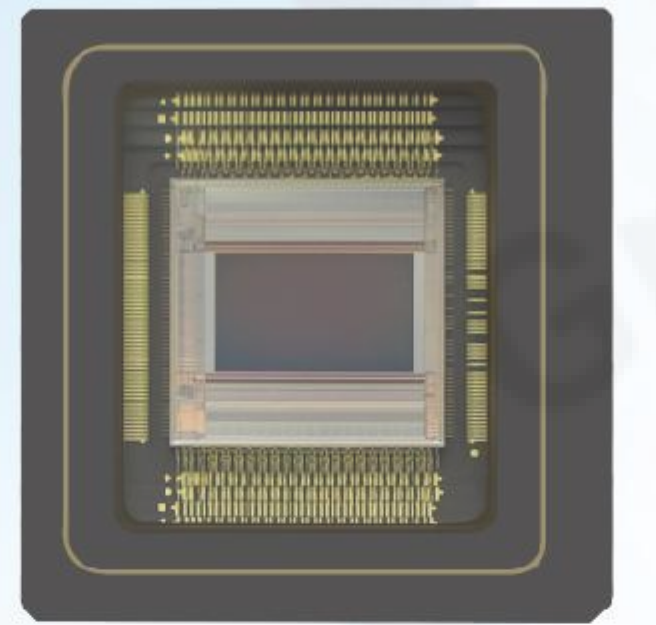
Specifications			
Nr of Active Pixels	2048 (H) x 1152(V)	Pixel size	6.5 μm x 6.5 μm
Optical format	1" (15.3 mm)	Shutter type	Global shutter
Photosensitive area	13.3 mm x 7.5 mm	Full well capacity	20.0 ke ⁻
Peak QE	>80 %	Temporal noise	24.3 e ⁻
Angular response	50°(60% response)	Dynamic Range	57 dB
Max. SNR	TBD	ADC	10 bit
Max Frame rate	1500 fps,2941 fps @ 1x2 binned	Channel multiplexing	Yes(any multiple of 2)
Output format	32 pairs LVDS	Chroma	Mono
Max. Data rate	38.4 Gbps	Supply voltage	3.6V & 3.3V (analog), 1.8V (I/O), 1.2V (digital)
Power consumption	<1.9 W	Package	130pins LGA (25.66 mm x 22.05 mm)

Package Drawing



GSPRINT4502

2.4MP GLOBAL SHUTTER HIGH SPEED IMAGE SENSOR



GSPRINT4502 is a 2MP (2048 x 1216) 2/3" sized (10.7 mm) high speed, global shutter image sensor designed with the latest 4.5 μm charge domain global shutter pixel. It achieves more than 30k e⁻ FWC, less than 4 e⁻ rms read noise and > 68 dB dynamic range, optionally to be increased with multi-slope HDR mode. With 2x2 on-chip charge binning, FWC can be further increased to 120 ke⁻ and frame rate is quadrupled. GSPRINT4502 consists of 64 pairs sub-LVDS channels running at 1.2Gbps, which delivers a stunning 3462 fps at 8 bits per pixel and full resolution and over 10000 fps in binning mode. These unique features make it an ideal solution for demanding imaging in applications such as 3D laser profiling, industrial inspection, motion analysis and high speed imaging.

Key features and Benefits

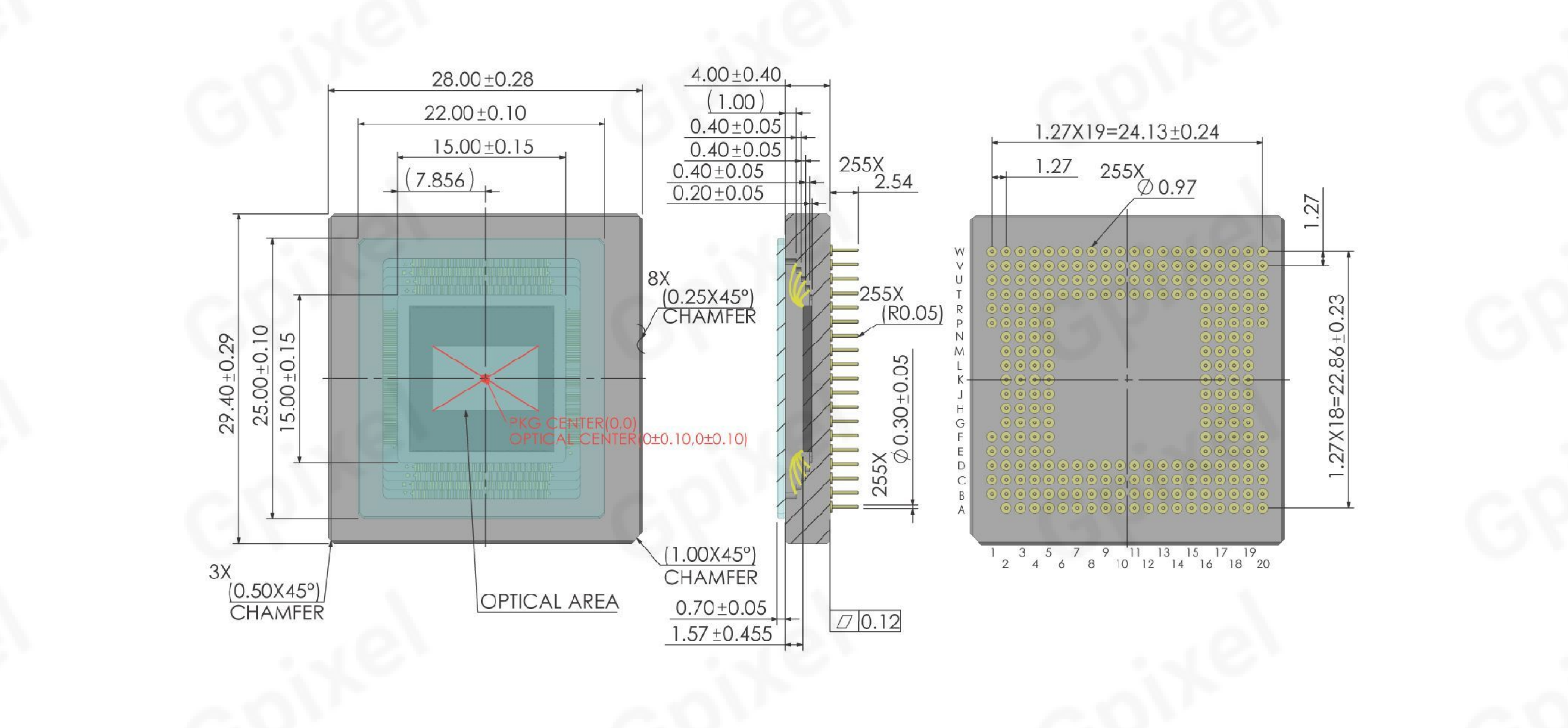
- High Frame Rate
- Low noise Global Shutter
- Multi-slope HDR

Application

- Automation & Inspection
- Cinematography
- High Speed Imaging

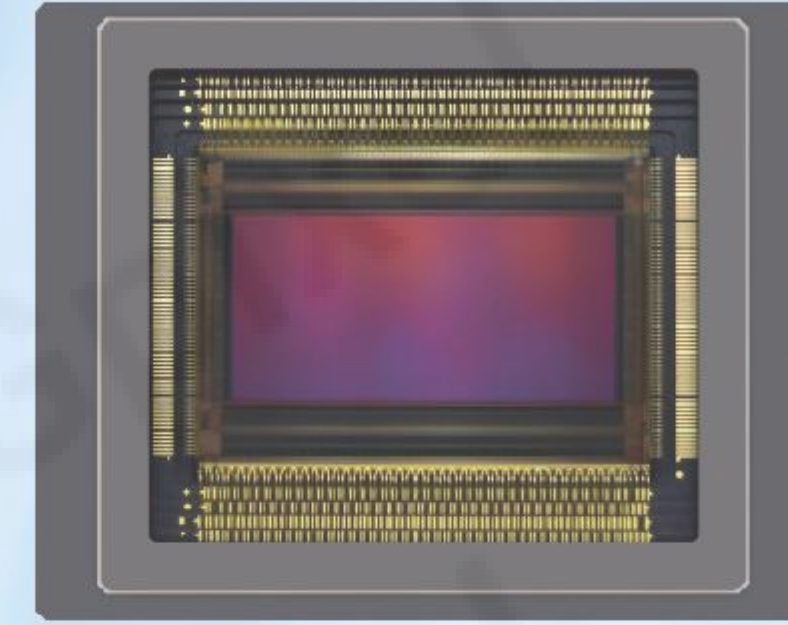
Specifications			
Nr of Active Pixels	2048 (H) x 1216 (V)	Pixel size	4.5 μm x 4.5 μm
Optical format	2/3"	Shutter type	Global shutter
Photosensitive area	9.21 mm x 5.47 mm	Full well capacity	>30 ke ⁻
Peak QE	65.7% @ 515 nm	Temporal noise	3.8 e ⁻
Parasitic Light Sensitivity	-84.6 dB	Dark Current	21 e ⁻ /pixel/s @ 60°C
Angular response	20°(80% response)	Dynamic Range	68.2 dB @ 12 bit
Max. SNR	44.8 dB	ADC	8/10/12 bit
Max Frame rate	3462 fps @ 8 bit, 1782 fps @ 10 bit, 852 fps @ 12 bit	Channel multiplexing	160/156/152/.../4 (any multiple of 4)
Output format	64 ch sub-LVDS	Chroma	Mono,RGB Color
Max. Data rate	76.8 Gbps	Supply voltage	3.3 V(analog), 1.8 V(I/O), 1.2 V(digital)
Power consumption	2.5 W	Package	255 pins μPGA (28.0 mm x 29.4 mm)

Package Drawing



GSPRINT4510

10MP GLOBAL SHUTTER HIGH SPEED IMAGE SENSOR



GSPRINT4510 is a 10MP (4608 x 2176) 4/3" (22.9 mm) high speed image sensor designed with the latest 4.5 μm charge domain global shutter pixel. It achieves more than 30 ke⁻ charge capacity and less than 3 e⁻ rms read noise. Using an advanced 65 nm CIS process with light pipe technology, the sensor achieves >67% QE and more than 1/40,000 shutter efficiency. With on-chip charge binning, full well capacity can be further increased and frame rate is almost quadrupled. GSPRINT4510 is well suited for many high-speed applications such as slow motion video capture, drone-mounted videography, and 3D laser profiling.

Key features and Benefits

- High Frame Rate
- Low noise Global Shutter
- Multi-slope HDR

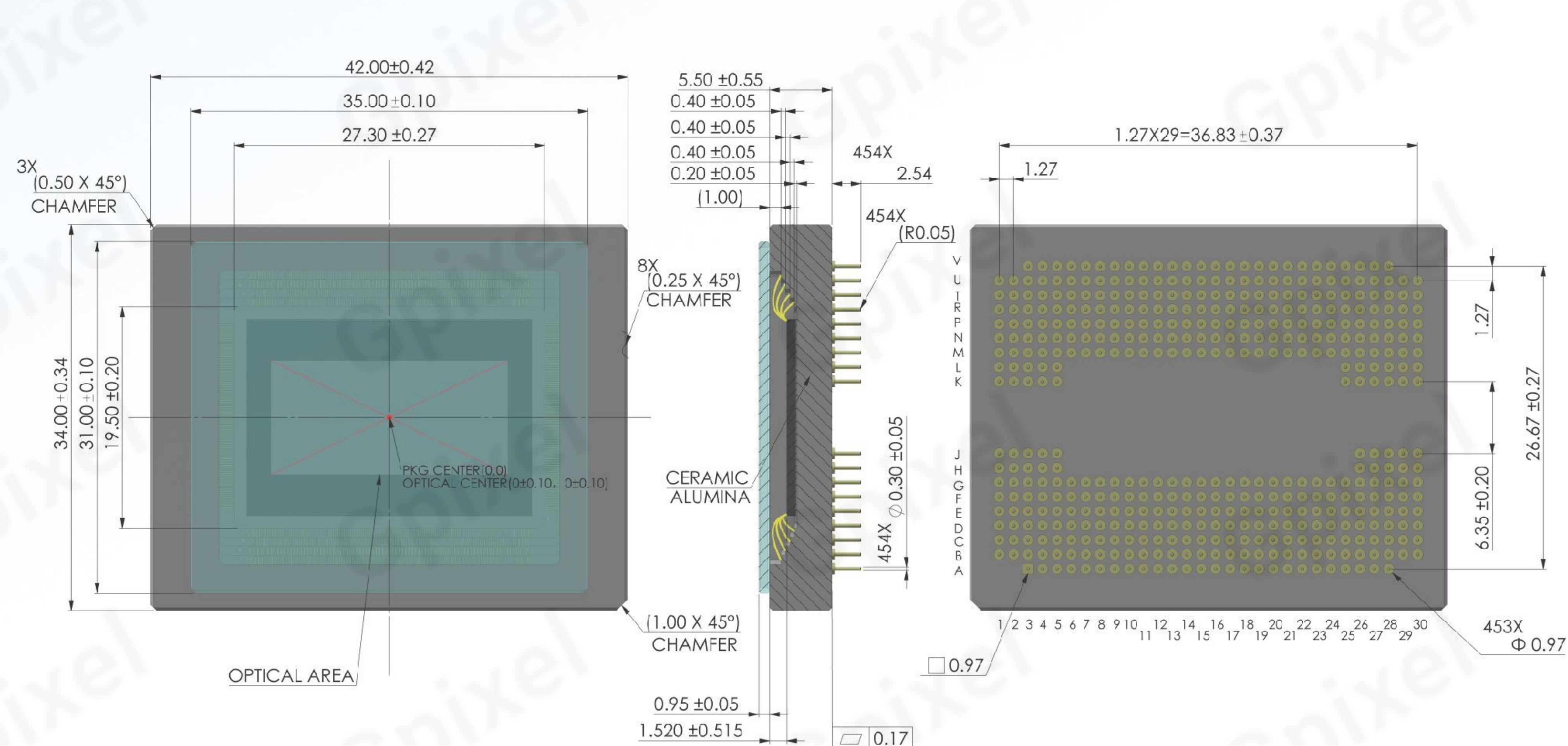
Application

- Automation & Inspection
- Cinematography
- High Speed Imaging

Specifications

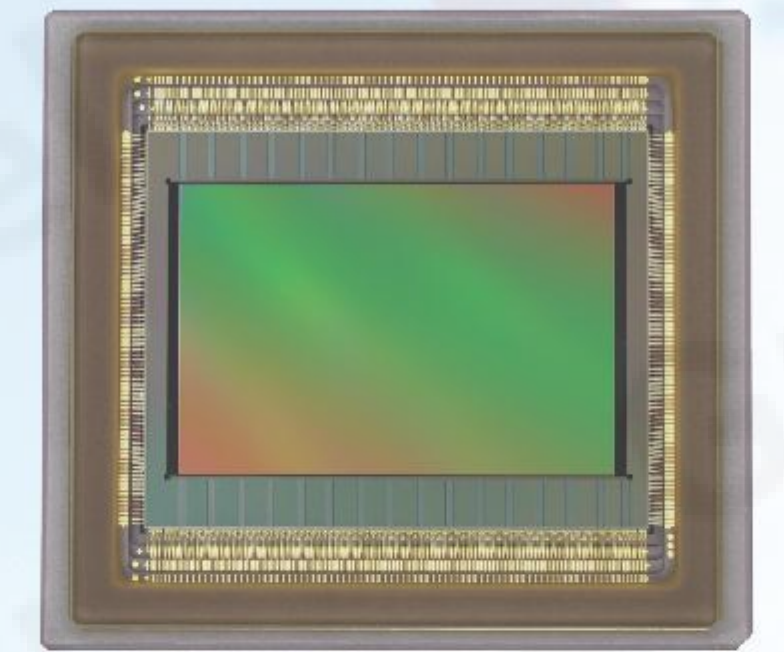
Nr of Active Pixels	4608 (H) x 2176 (V)	Pixel size	4.5 μm x 4.5 μm
Optical format	4/3" (MFT)	Shutter type	Global shutter
Photosensitive area	20.7 mm x 9.79 mm	Full well capacity	>30 ke ⁻
Peak QE	>67% @ 550 nm	Temporal noise	4 e ⁻
Parasitic Light Sensitivity	<-86 dB	Dark Current	11.4 e ⁻ /pixel/s @ 50°C
Angular response	20°(80% response)	Dynamic Range	68.2 dB @ 12 bit
Max. SNR	44.7 dB	ADC	8/10/12 bit
Max Frame rate	1920 fps @ 8 bit, 1000 fps @ 10 bit, 480 fps @ 12 bit	Channel multiplexing	160/156/152/.../4 (any multiple of 4)
Output format	144 ch sub-LVDS	Chroma	Mono, RGB Color
Max. Data rate	172.8 Gbps	Supply voltage	3.3 V(analog), 1.8 V(I/O), 1.2 V(digital)
Power consumption	2.5 W	Package	454 pins μPGA (42.0 mm x 34.0 mm)

Package Drawing



GSPRINT5514BSI

14MP HIGH SPEED CMOS IMAGE SENSOR



GSPRINT5514BSI features 4608 x 3072 pixels, each 5.5 μm square – a 4/3 aspect ratio 4k sensor compatible with APS-C optics. With 10-bit output GSPRINT5514BSI achieves 670 frames per second. In 12-bit mode the sensor outputs 350 fps. Using backside illumination technology, the sensor achieves 86% quantum efficiency at 510 nm and 17% at 200 nm for UV applications. The sensor offers dual gain HDR readout, maximizing 15 ke⁻ full well capacity with a < 2.0 e⁻ noise to achieve an outstanding 78.3 dB of dynamic range. Analog 1 x 2 binning increases the full well capacity to 30 ke⁻. Up to 8 vertically oriented regions of interest can be defined to operate the sensor at increased frame rates. The image data is output via 84 sub-LVDS channels at 1.2 Gbps. For applications in which the maximum frame rate is not required, multiplexing modes are available to reduce the number of output channels by any multiple of two.

Key features and Benefits

- Back Side Illuminated (BSI) Global Shutter pixels
- High Sensitivity
- High Speed: up to 670 fps @ 10 bit
- 86% QE @ 510nm

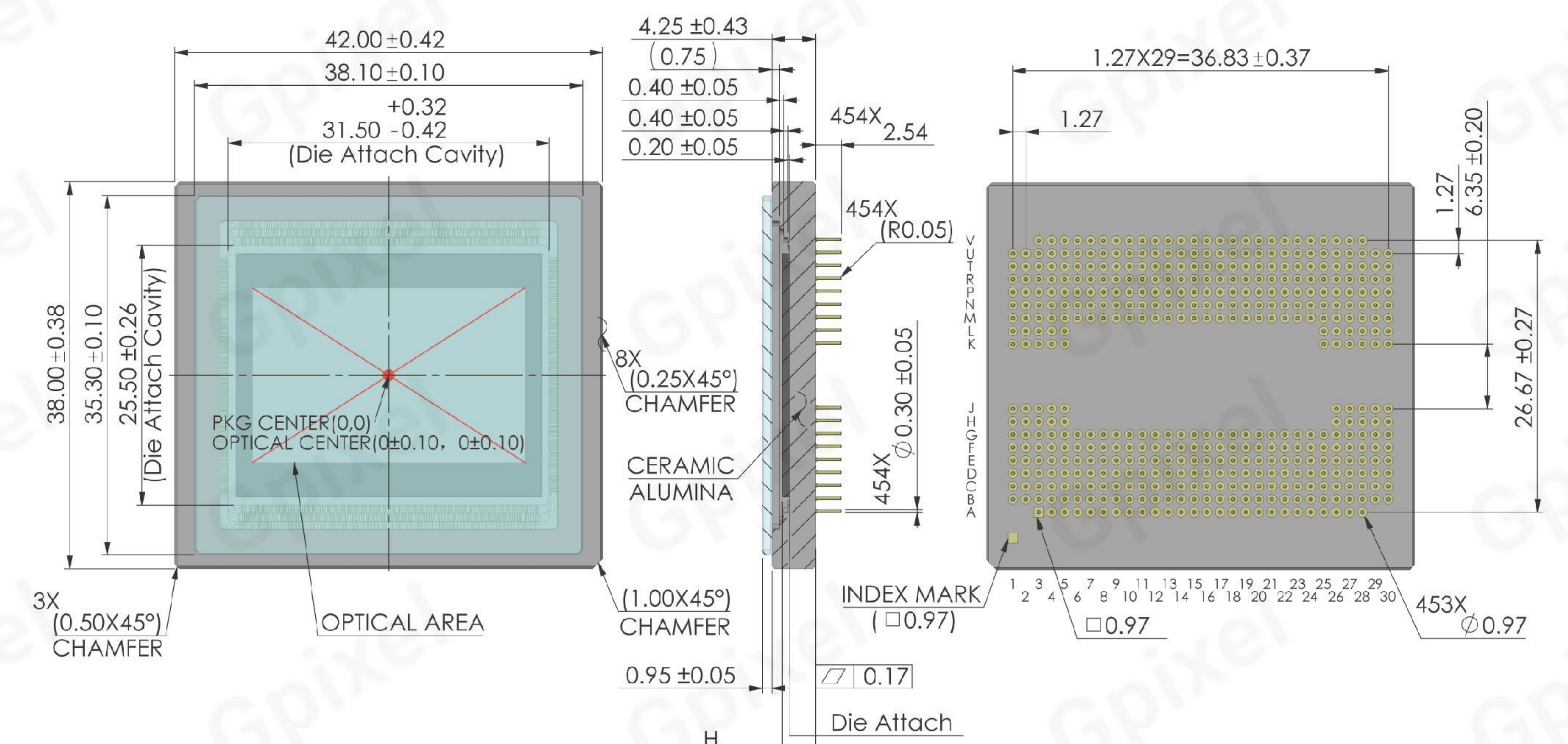
Application

- Automation & Inspection
- Cinematography
- High Speed Imaging

Specifications

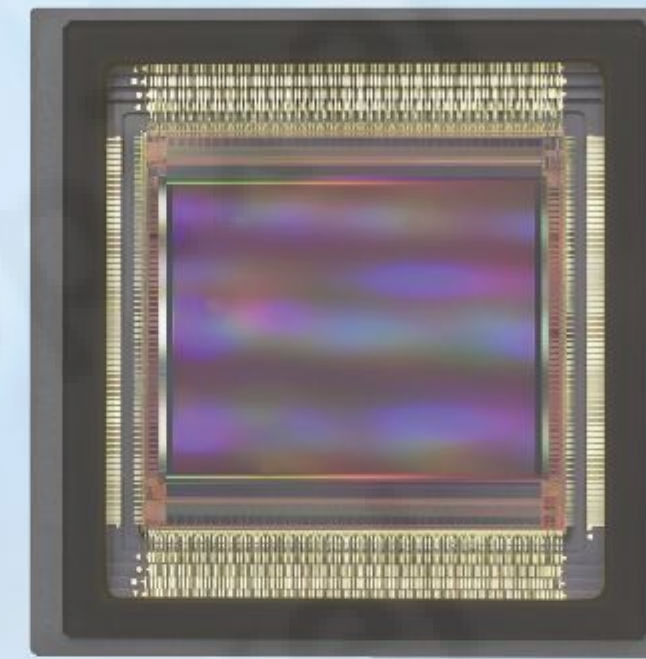
Nr of Active Pixels	4608 (H) x 3072(V)	Pixel size	5.5 μm x 5.5 μm
Optical format	APS (30.5 mm diagonal)	Shutter type	Global shutter
Photosensitive area	25.3 mm x 16.9 mm	Full well capacity	15.0 ke ⁻ /30.0 ke ⁻ with binning
Peak QE	>86 %	Temporal noise	3.0 e ⁻ @ 10 bit/1.9 e ⁻ @ 12 bit/< 2e ⁻ @ 12 bit HDR
Parasitic Light Sensitivity	-86 dB	Dark Current	83 e ⁻ /s @ 60°C die temperature
Angular response	30°(80% response)	Dynamic Range	< 78.3 dB (HDR Dual 12 bit, intra-scene)
Max. SNR	40 dB	ADC	10 bit & 12 bit
Max Frame rate	670fps @ 10bit/350fps @ 12bit/80fps @ Dual-12bit	Channel multiplexing	Yes (any multiple of 4)
Output format	84 ch sub-LVDS	Chroma	Mono, RGB Color, Mono without lens
Max. Data rate	94.84 Gbps	Supply voltage	3.3 V(analog), 1.8 V(I/O), 1.2 V(digital)
Power consumption	4.7 W @ 10 bit/4.5 W @ 12 bit/3.9 W @ 12 bit HDR	Package	454 pins μPGA (42.0 mm x 38.0 mm)

Package Drawing



GSPRINT4521

21MP GLOBAL SHUTTER HIGH SPEED IMAGE SENSOR



GSPRINT4521 is a 21MP (5120 x 4096) APS sized (29.5 mm diameter) high speed, global shutter image sensor designed with the latest 4.5 μm charge domain global shutter pixel. It achieves 32 ke⁻FWC, less than 3 e⁻rms read noise and >69 dB dynamic range, optionally increased to 81 dB with a dual gain HDR mode. In 8 bit mode, the sensor delivers 1000 fps. Its state-of-the-art 65 nm CIS process allows the sensor to use on-chip charge binning, further increasing FWC and almost quadrupling frame rate. These unique features make it an ideal solution for demanding imaging in high-end applications such as high speed 4K video, industrial inspection, motion analysis and high-throughput life science imaging.

Key features and Benefits

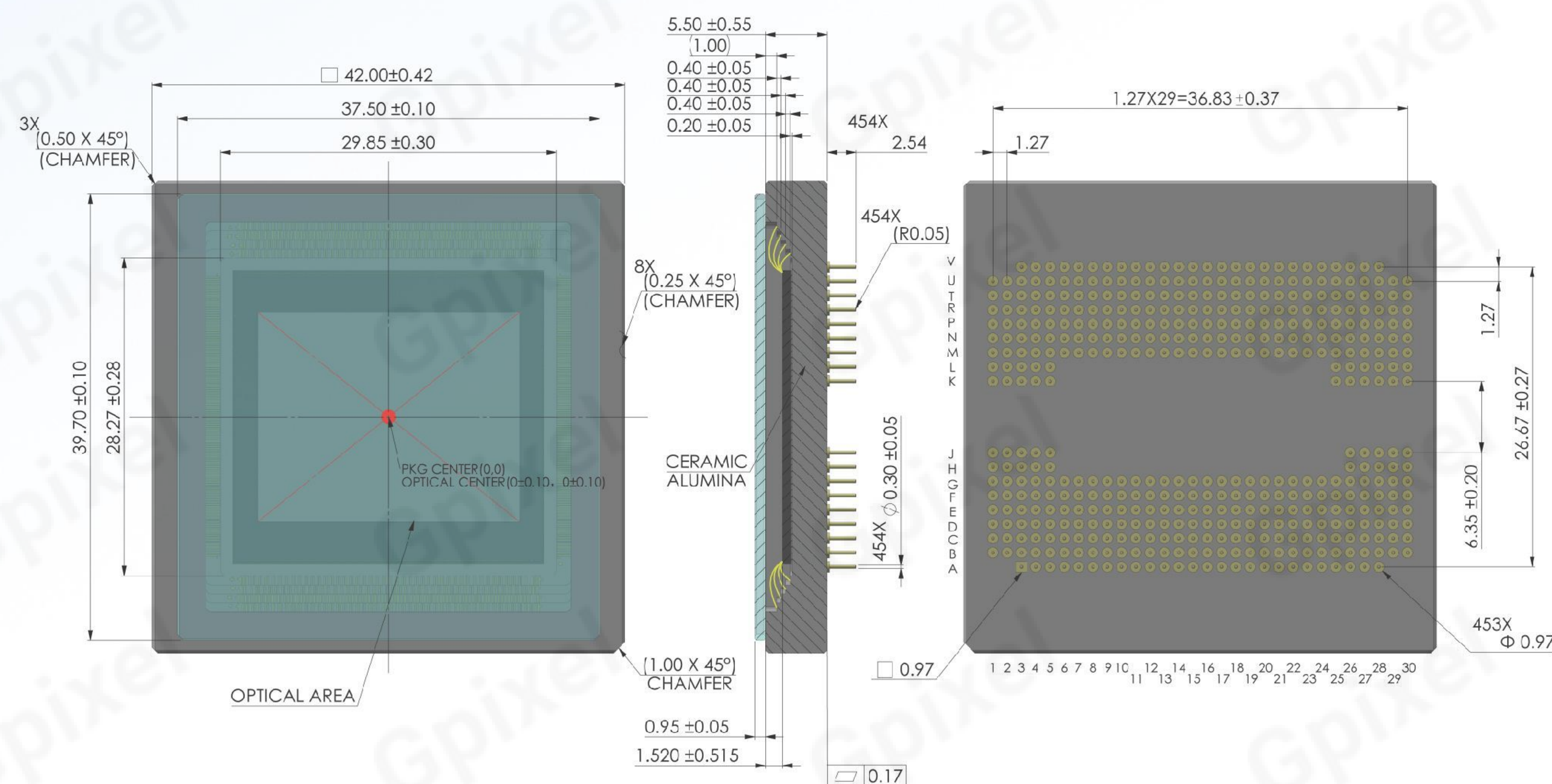
- High Frame Rate
- Low noise Global Shutter
- dual gain HDR mode

Application

- Automation & Inspection
- Cinematography
- High Speed Imaging

Specifications			
Nr of Active Pixels	5120 (H) x 4096 (V)	Pixel size	4.5 μm x 4.5 μm
Optical format	1.84" (APS-C)	Shutter type	Global shutter
Photosensitive area	23.04 mm x 18.43 mm	Full well capacity	32 ke ⁻
Peak QE	>63% @ 500 nm	Temporal noise	3.5 e ⁻
Parasitic Light Sensitivity	<-86 dB	Dark Current	11.4 e ⁻ /pixel/s @ 50°C
Angular response	17°(80% response)	Dynamic Range	68.2 dB @ 12 bit
Max. SNR	45 dB	ADC	8/10/12 bit
Max Frame rate	1000 fps @ 8 bit	Channel multiplexing	160/156/152/.../4 (any multiple of 4)
Output format	160 ch sub-LVDS	Chroma	Mono,RGB Color
Max. Data rate	192 Gbps	Supply voltage	3.3 V(analog), 1.8 V(I/O), 1.2 V(digital)
Power consumption	6 W	Package	454 pins μPGA (42.0 mm x 42.0 mm)

Package Drawing



Area Scan CMOS Image Sensor

The GSENSE series is a world leading scientific CMOS image sensor family, designed with correlated multiple sampling for extreme low noise, true HDR for high dynamic range and optional backside illumination technology for quantum efficiency of up to 95%. Optional Pulsar technology extends sensitivity into the soft x-ray region. Primary applications include scientific imaging, medical imaging, spectroscopy, fluorescence imaging, astronomy, high energy physics, and high-end surveillance.

- GSENSE2020
- GSENSE4040
- GSENSE6060
- GSENSE3243BSI
- GSENSE400BSI
- GSENSE1081BSI
- GSENSE2020BSI
- GSENSE4040BSI
- GSENSE6060BSI
- GSENSE6510BSI
- GSENSE2011

Product Family Features

- Large Format
- High Dynamic
- BSI
- Low Noise

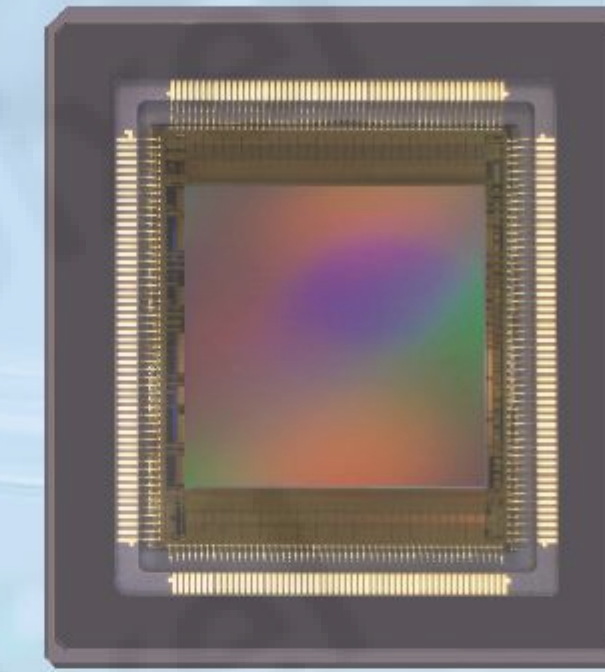
Applications

- Life Sciences
- Microscopy
- Spectroscopy
- Astronomy
- X-Ray



GSENSE2020

4MP SCIENTIFIC CMOS IMAGE SENSOR



GSENSE2020 is a 4MP resolution scientific CMOS image sensor, capable of operating with either global or rolling shutter. The sensor's six transistor (6T) pixel design on a 6.5 μm pitch has a very low readout noise of 2.1 e⁻ in rolling shutter HDR mode with maximum frame rate of 47 fps, and up to 370 fps in global shutter mode. With dual gain HDR the sensor outputs two separate images after each exposure which can be combined off-chip to achieve dynamic range up to 87 dB.

Key features and Benefits

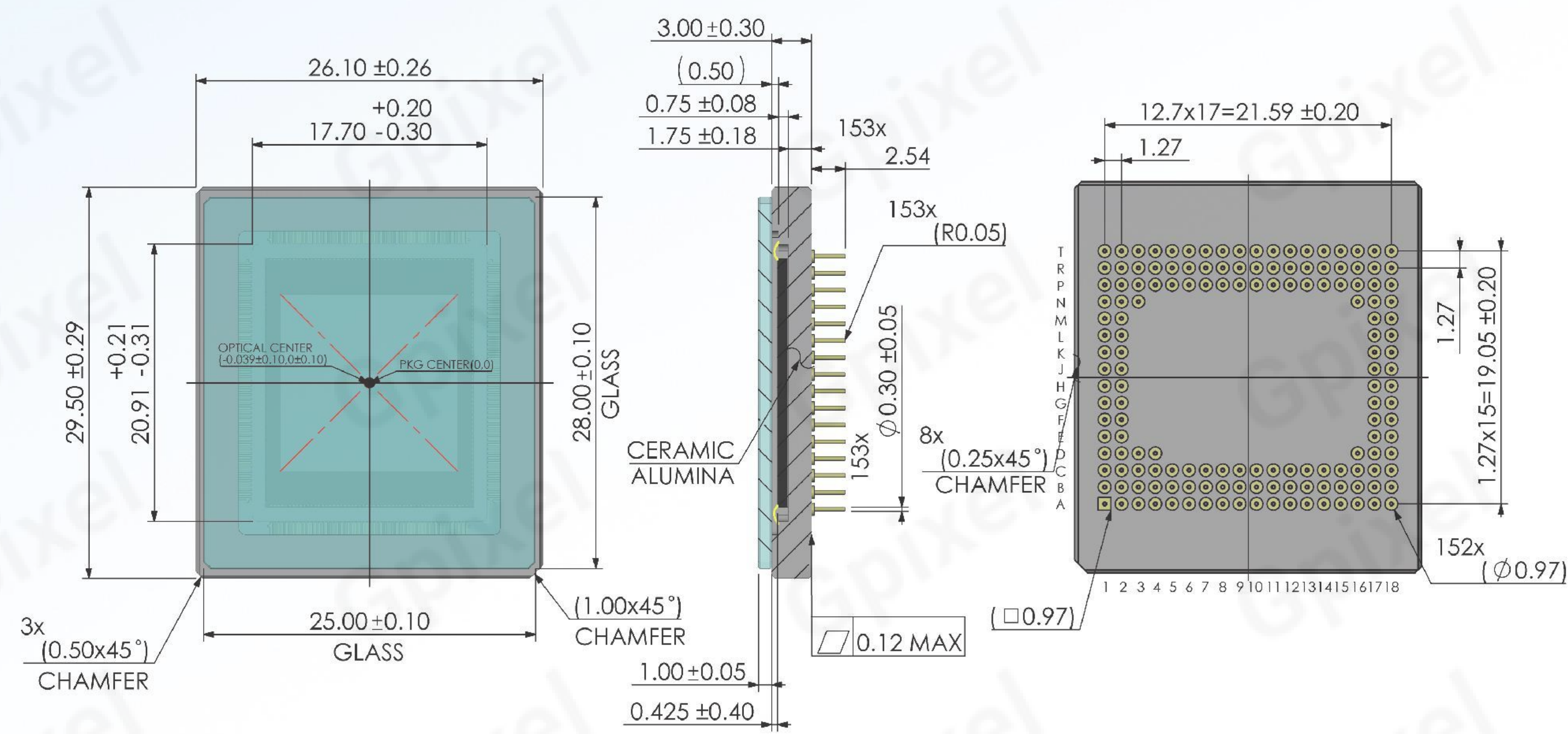
- Scientific CMOS
- Peak QE of 72%
- Low noise, low power for long exposure modes

Application

- Spectroscopy
- Life Sciences
- Astronomy
- Microscopy
- X-Ray

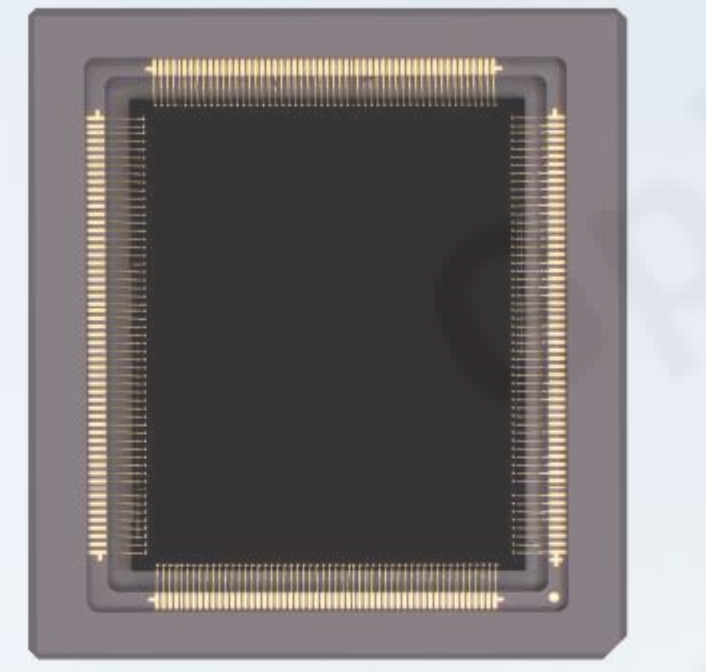
Specifications			
Nr of Active Pixels	2048 (H) x 2048 (V)	Pixel size	6.5 μm x 6.5 μm
Optical format	1.2"	Shutter type	Rolling & Global shutter
Photosensitive area	13.3 mm x 13.3 mm	Input clock rate	50 MHz
Peak QE	72% @ 595 nm	Full well capacity	45 ke ⁻
Dark Current	13 e ⁻ /pixel/s @ 30°C	Temporal noise	2.1 e ⁻
Max Frame rate	47 fps @ RS HDR, 370 fps @ GS DDS	Dynamic Range	86.6 dB
Output format	32 ch LVDS	Max. Data rate	4.8 Gbps
Chroma	Mono, RGB Color	Power consumption	811 mW
Supply voltage	3.3 V(analog), 1.8 V(I/O), 1.2 V(digital)	Package	153 pins μPGA (26.1 mm x 29.5 mm)

Package Drawing



GSENSE2020BSI

4MP SCIENTIFIC BSI CMOS IMAGE SENSOR



GSENSE2020BSI is a backside illuminated (BSI) scientific CMOS image sensor, with 4MP resolution and 6.5 μm pixel size. With six-transistor (6T) pixel architecture, GSENSE2020BSI features readout noise of 1.6 e⁻, full well of 55 ke⁻, and peak QE of 95%. The sensor supports correlated multiple sampling (CMS), further reducing the read noise to 1.2 e⁻ with 2-CMS operation. In addition, GSENSE2020BSI is pin-compatible with GSENSE2020 and GSENSE2011, allowing easy hardware integration and fast time-to-market. The GSENSE2020BSI is an ideal solution for life sciences applications including fluorescence microscopy.

Key features and Benefits

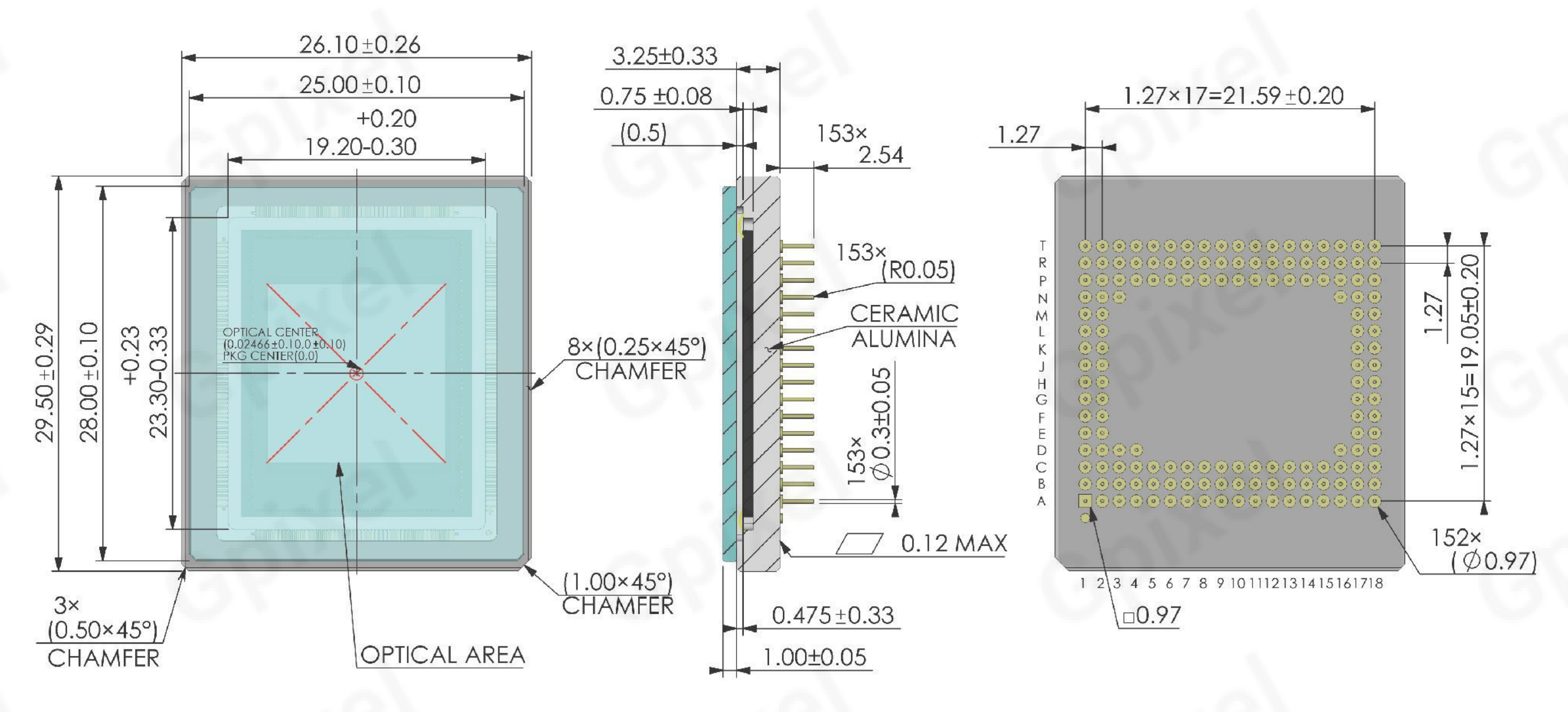
- Scientific CMOS
- Peak QE of 95%
- Low noise, low power for long exposure modes

Application

- Spectroscopy
- Life Sciences
- Astronomy
- Microscopy
- X-Ray

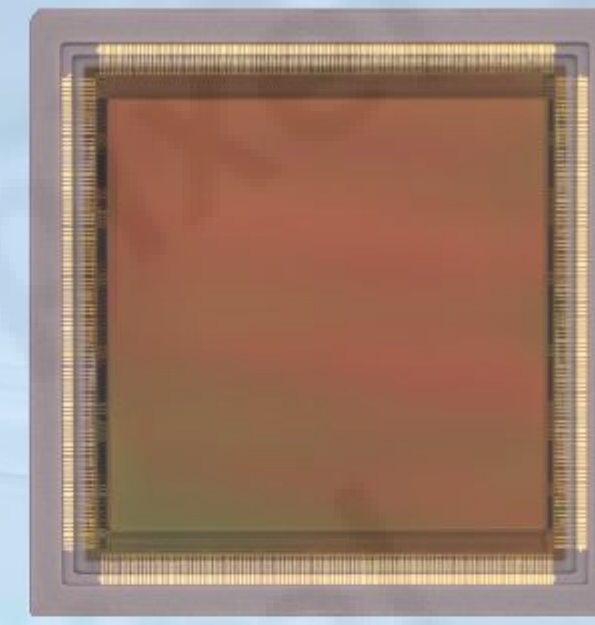
Specifications			
Nr of Active Pixels	2048 (H) x 2048 (V)	Pixel size	6.5 μm x 6.5 μm
Optical format	1.2"	Shutter type	Rolling shutter
Photosensitive area	13.3 mm x 13.3 mm	Input clock rate	600 MHz
Peak QE	95% @ 560 nm	Full well capacity	55 ke ⁻
Dark Current	0.07 e ⁻ /pixel/s @ 30 °C	Temporal noise	1.2 e ⁻
Max Frame rate	43 fps @ 12 bit, 74 fps @ 11 bit	Dynamic Range	90.5 dB
Output format	8 ch LVDS @ 12 bit, 16 ch LVDS @ 11 bit	Max. Data rate	9.6 Gbps @ 11 bit
Chroma	Mono	Power consumption	<1.2 W
Supply voltage	3.5 V(analog), 2.0 V(digital)	Package	153 pins μPGA (26.1 mm x 29.5 mm)

Package Drawing



GSENSE4040

16.8MP SCIENTIFIC CMOS IMAGE SENSOR



GSENSE4040 is a 16.8MP resolution CMOS image sensor. With a five transistor (5T) HDR pixel design on a 9 μm pitch, the sensor can achieve 3.7 e⁻ dark noise and 74 ke⁻ FWC simultaneously in HDR mode. It supports 2x2 charge binning in which frame rate is quadrupled. GSENSE4040 is offered in two variants: CMN and CMT. CMN is a monochrome sensor without microlens array and protected by a removable glass lid, which is ideal for X-ray imaging, charged particle detection, and micro-CT applications; while CMT is a monochrome sensor with microlens array and sealed with D263T glass lid with anti-reflective coating on both sides, ideal for medical imaging and astronomy applications.

Key features and Benefits

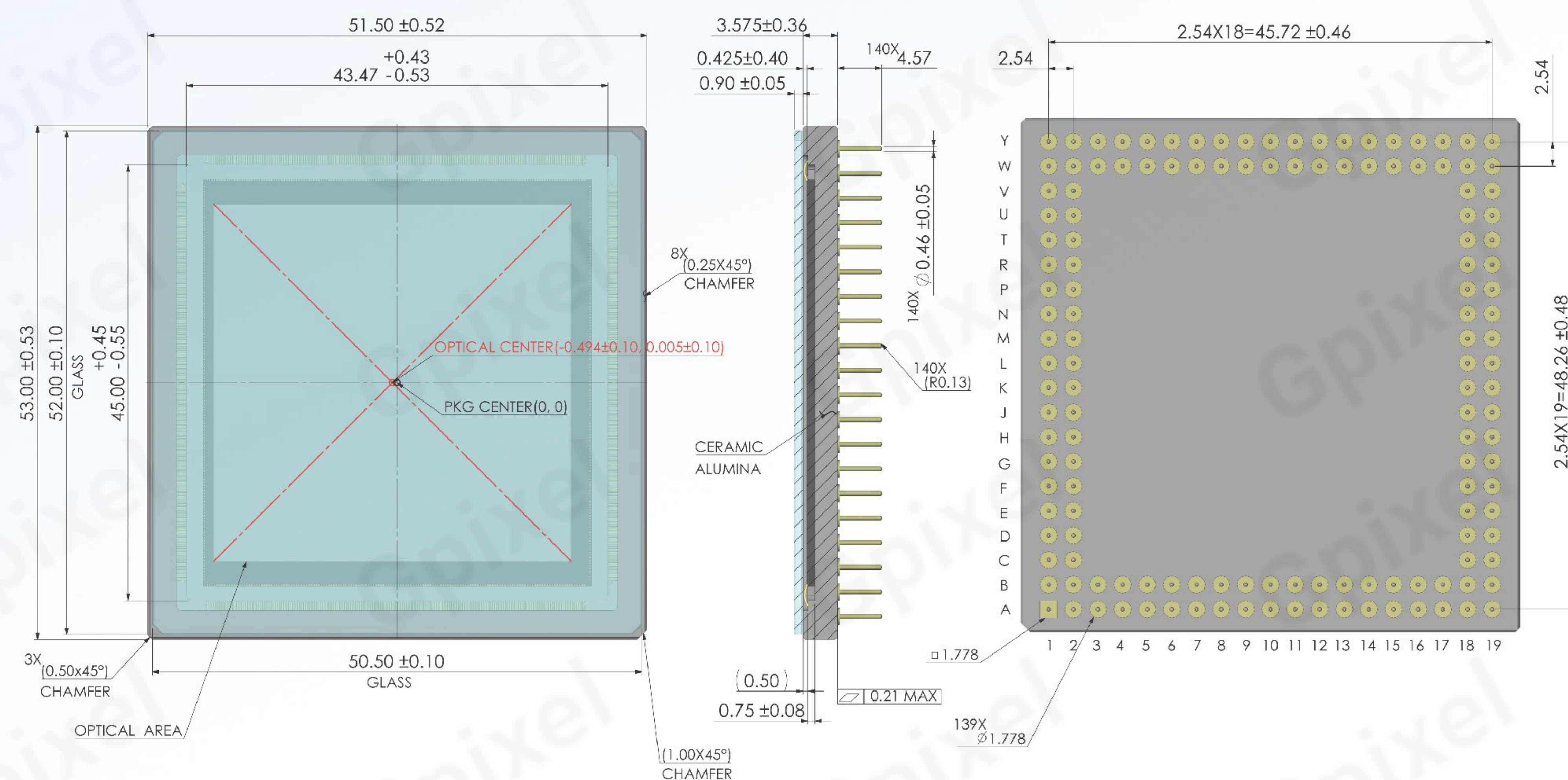
- Peak QE of 74%
- High dynamic range
- Large format

Application

- Spectroscopy
- Life Sciences
- Astronomy
- Microscopy
- X-Ray

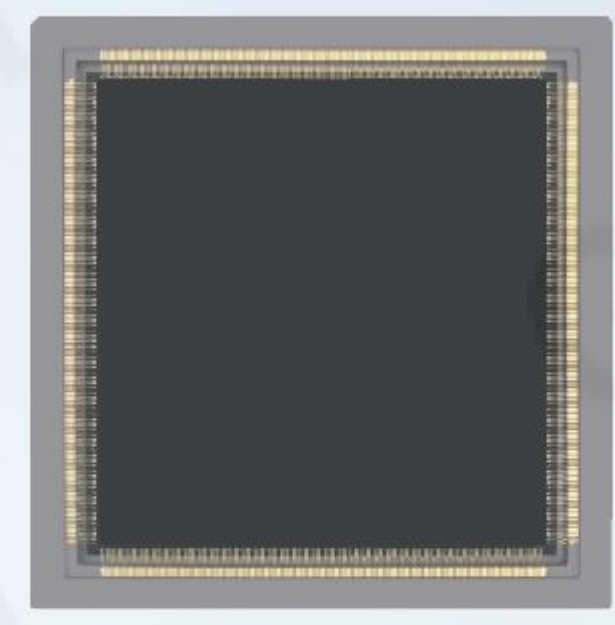
Specifications			
Nr of Active Pixels	4096 (H) x 4096 (V)	Pixel size	9 μm x 9 μm
Optical format	3.3"	Shutter type	Rolling shutter
Photosensitive area	36.864 mm x 36.864 mm	Input clock rate	50 MHz
Peak QE	74% @ 600nm	Full well capacity	>70 ke ⁻
Dark Current	12.2 e ⁻ /pixel/s @ 25°C	Temporal noise	2.3 e ⁻
Max Frame rate	24 fps	Dynamic Range	86 dB
Output format	18 ch LVDS	Max. Data rate	10.8 Gbps
Chroma	Mono	Power consumption	<1.4 W
Supply voltage	3.3 V(analog), 1.8 V(digital)	Package	140 pins PGA (51.5 mm x 53.0 mm)

Package Drawing



GSENSE4040BSI

16.8MP SCIENTIFIC BSI CMOS IMAGE SENSOR



GSENSE4040BSI is a backside illuminated scientific CMOS image sensor of 16.8MP (4096 x 4096) resolution with 9 μm x 9 μm pixel size, and a photosensitive area of 36.8 mm x 36.8 mm (52 mm diagonal). Using dual gain HDR operation mode, 84.6 dB is achieved with 39k e⁻ full well capacity and 2.3 e⁻ readout noise. 18 pairs of LVDS channels running at 600 MHz per channel support full-resolution imaging at a frame rate of 24 fps. GSENSE4040BSI is assembled in 140-pin PGA ceramic package with a removable glass lid. This sensor is pin compatible with GSENSE4040 for fast and easy integration.

Key features and Benefits

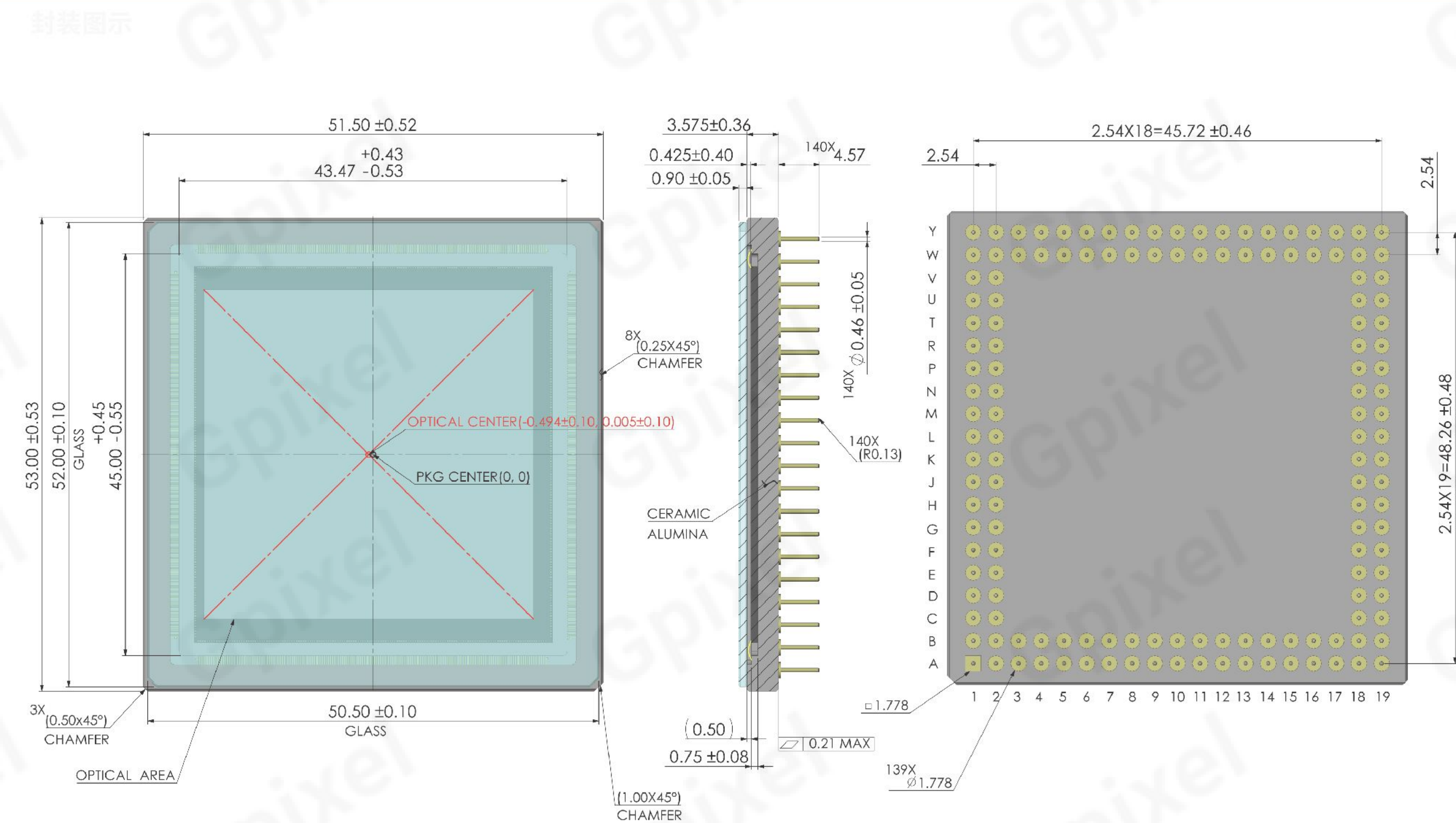
- Large format BSI scientific CMOS
- Low readout noise

Application

- Spectroscopy
- Life Sciences
- Astronomy
- Microscopy
- X-Ray

Specifications			
Nr of Active Pixels	4096 (H) x 4096 (V)	Pixel size	9 μm x 9 μm
Optical format	3.3"	Shutter type	Rolling shutter
Photosensitive area	36.864 mm x 36.864 mm	Input clock rate	50 MHz
Peak QE	90% @ 550 nm	Full well capacity	39 ke ⁻
Dark Current	0.04 e ⁻ /pixel/s @ -40 °C	Temporal noise	2.3 e ⁻
Max Frame rate	24 fps	Dynamic Range	84.6 dB
Output format	18 ch LVDS	Max. Data rate	10.8 Gbps
Chroma	Mono	Power consumption	<1.4 W
Supply voltage	3.3 V(analog), 1.8 V(digital)	Package	140 pins PGA (51.5 mm x 53.0 mm)

Package Drawing



GSENSE6060

37MP SCIENTIFIC CMOS IMAGE SENSOR



GSENSE6060 and its pin-compatible back-thinned version **GSENSE6060BSI**, are designed with a large imaging area for demanding astronomical and scientific imaging applications. With its top and bottom readout chains consisting of 2x25 LVDS pairs running up to 630MHz, **GSENSE6060**'s frame rate is up to 44 fps with 12bit ADC. The two readout chains also provide the possibility for HDR combination up to 89 dB. The Aluminum Nitride package of **GSENSE6060** provides 10x thermal conductivity compared to the traditional Alumina package, as well as excellent flatness both at the room temperature and deep-cooled temperatures.

Key features and Benefits

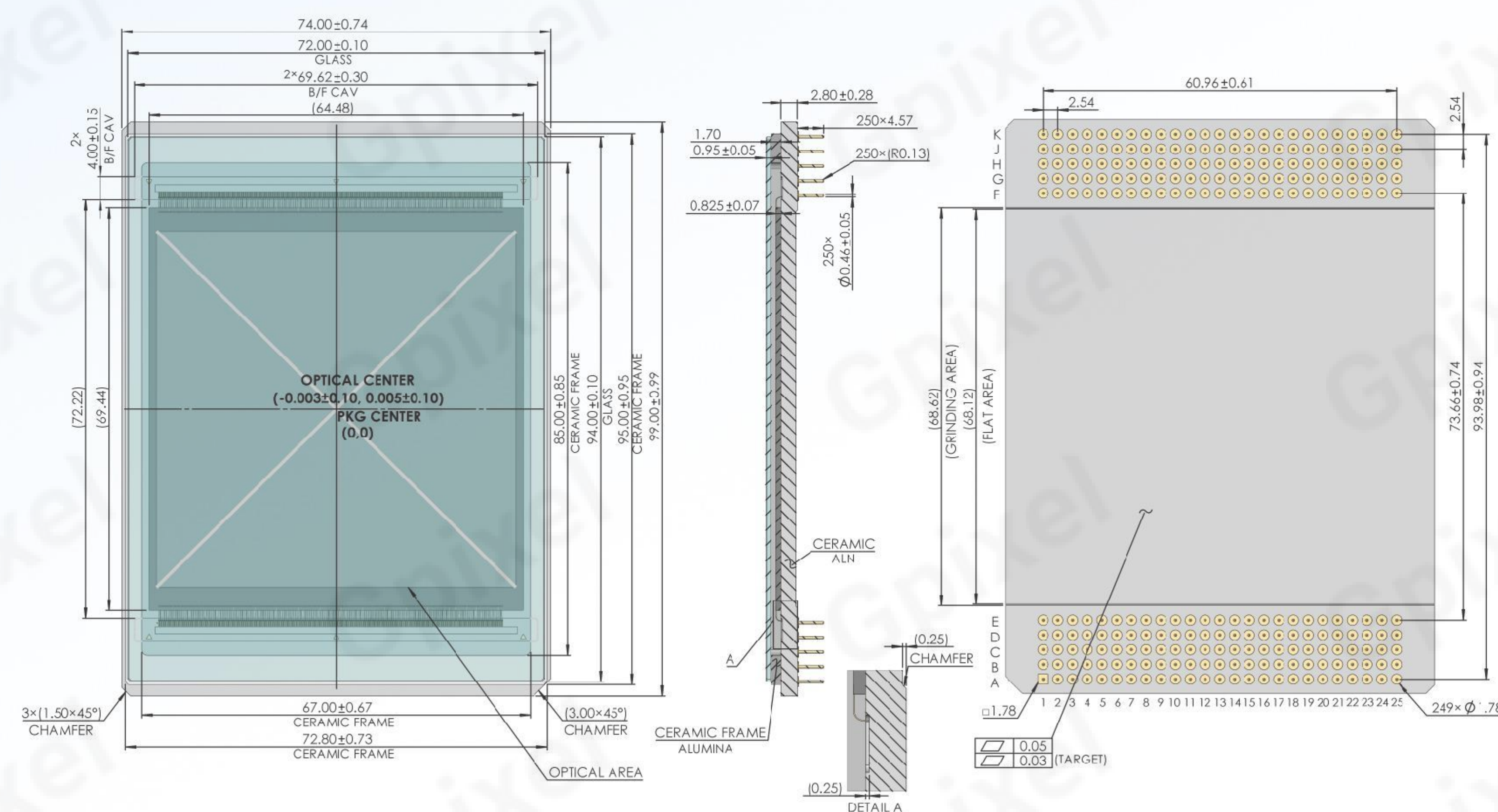
- Large format scientific CMOS
- 14bit with CMS
- Peak QE of 71.6%

Application

- Spectroscopy
- Life Sciences
- Astronomy
- Microscopy
- X-Ray

Specifications			
Nr of Active Pixels	6144 (H) x 6144 (V)	Pixel size	10 μm x 10 μm
Optical format	5.4"	Shutter type	Rolling shutter
Photosensitive area	61.44 mm x 61.44 mm	Input clock rate	52.5 MHz @ 12 bit, 45 MHz @ 14 bit
Peak QE	72% @ 550 nm	Full well capacity	133 ke ⁻
Dark Current	0.01 e ⁻ /pixel/s @ -70°C	Temporal noise	4.6 e ⁻
Max Frame rate	44 fps @ 12 bit STD	Dynamic Range	89 dB @12 bit HDR
Output format	52 ch LVDS	Max. Data rate	31.5 Gbps
Chroma	Mono	Power consumption	5.42 W
Supply voltage	6.5 V(analog),1.85 V(digital)	Package	250 pins PGA (74.0 mm x 99.0 mm)

Package Drawing



GSENSE6060BSI

37MP SCIENTIFIC BSI CMOS IMAGE SENSOR



GSENSE6060BSI is a backside illuminated scientific CMOS image sensor designed with a large imaging area for demanding astronomical and scientific imaging applications. With its top and bottom readout chains consisting of 2x25 LVDS pairs running up to 420 MHz, **GSENSE6060BSI**'s frame rate is up to 26 fps with 12 bit ADC. The Aluminum Nitride package of **GSENSE6060BSI** provides 10x thermal conductivity compared to the traditional Alumina package, as well as excellent flatness both at the room temperature and deep-cooled temperatures. **GSENSE6060BSI** is equipped with a removable glass lid.

Key features and Benefits

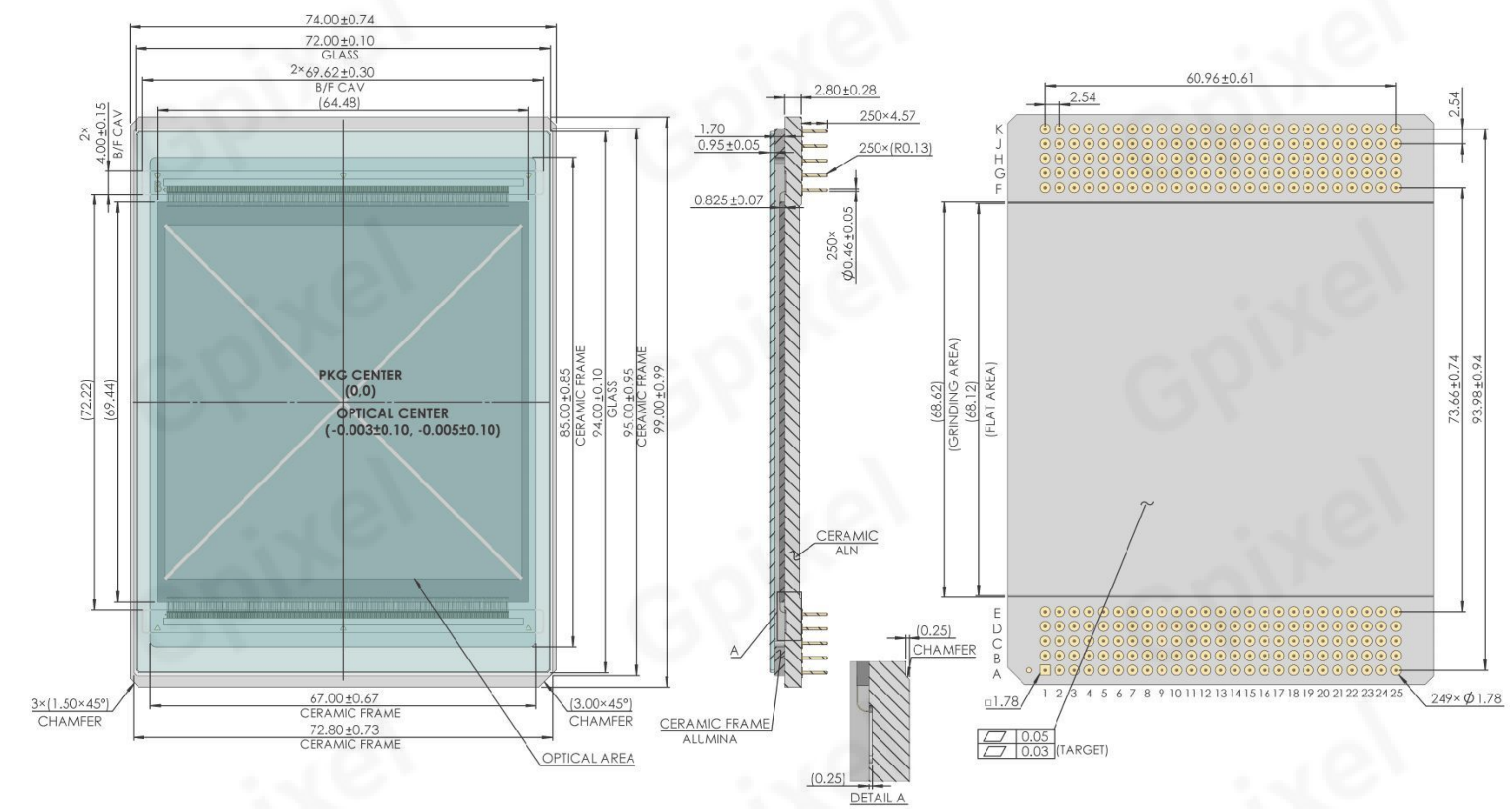
- Large format scientific CMOS
- 14bit with CMS
- Peak QE of 95%

Application

- Spectroscopy
- Life Sciences
- Astronomy
- Microscopy
- X-Ray

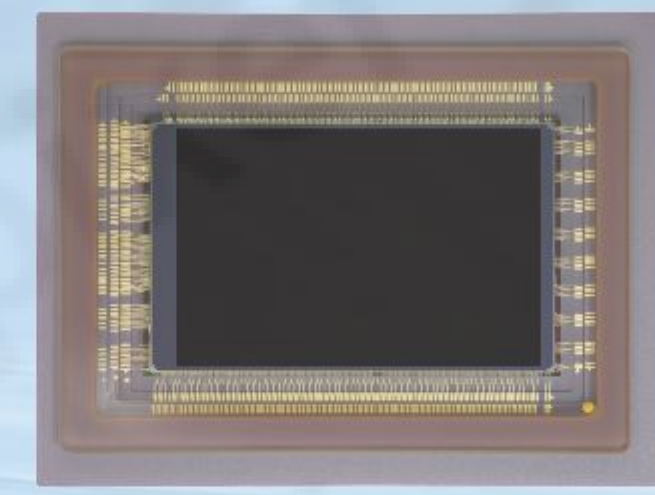
Specifications			
Nr of Active Pixels	6144 (H) x 6144 (V)	Pixel size	10 μm x 10 μm
Optical format	5.4"	Shutter type	Rolling shutter
Photosensitive area	61.44 mm x 61.44 mm	Input clock rate	35 MHz @ 12 bit, 30 MHz @ 14 bit
Peak QE	95% @ 580 nm	Full well capacity	95 ke ⁻
Dark Current	0.019 e ⁻ /pixel/s @ -53°C	Temporal noise	2.3 e ⁻
Max Frame rate	26 fps @ 12 bit STD	Dynamic Range	90 dB @ 12 bit HDR mode, 73 dB @ 12 bit STD mode, 77 dB @ 14 bit STD mode
Output format	52 ch LVDS	Max. Data rate	31.5 Gbps
Chroma	Mono	Power consumption	4.6 W
Supply voltage	6.5 V(analog),1.85 V(digital)	Package	250 pins PGA (74.0 mm x 99.0 mm)

Package Drawing



GSENSE3243BSI

43MP SCIENTIFIC CMOS IMAGE SENSOR



GSENSE3243BSI is a 31 mm diagonal stacked BSI image sensor designed with 3.2 μm pixels. The full resolution of the sensor can be read out at a bit depth of 14 bits and a maximum frame rate of 100 fps using an on-chip high speed serial interface or at 50 fps over 32 sub LVDS channels operating at 1.05 Gbps/channel. The image sensor has a peak quantum efficiency over 80%, a wide angle response, read noise of 3.3 e⁻ at full speed, and a dark current less than 1 e⁻/pixel/second at 0°C. The sensor achieves a dynamic range of 75 dB in dual gain mode and up to 104 dB using the more advanced HDR features.

Key features and Benefits

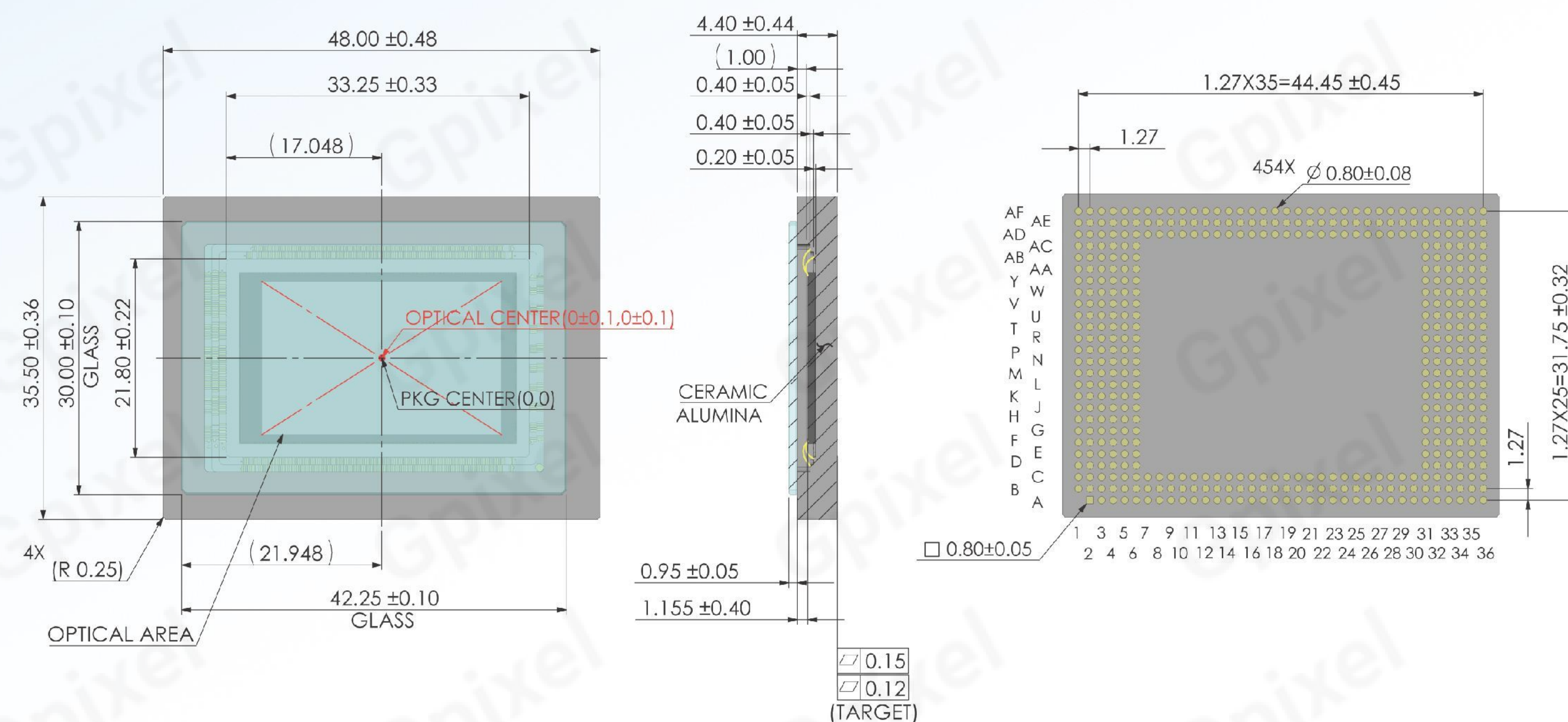
- Stacked BSI
- Low noise
- Multi-slope HDR
- High sensitivity
- High dynamic range
- Dual Gain HDR

Application

- Spectroscopy
- Life Sciences
- Astronomy
- Microscopy

Specifications			
Nr of Active Pixels	8192 (H) x 5232(V)	Pixel size	3.2 μm x 3.2 μm
Optical format	APS-C	Shutter type	Rolling shutter
Photosensitive area	26.2 mm x 16.7 mm	Max. SNR	50 dB
Peak QE	80% @550nm (Mono)	Full well capacity	96 ke ⁻ @ Multi-exposure Mode
Dark Current	1 e ⁻ /pixel/s	Temporal noise	3.3 e ⁻ (STD) / 4.4 e ⁻ (HDR)
Max Frame rate	100 fps	Dynamic Range	74.7 dB / 80.8 dB (x4)
Output format	32 pairs sLVDS / 16 pairs GSI	Max. Data rate	84 Gbps
Chroma	Mono	Power consumption	4 W
Supply voltage	3.3V / 1.8V / 1.25V -2.2V / 4.5V	Package	455 pins LGA (48.0 mm x 35.5 mm)

Package Drawing



GSENSE6510BSI

10.2MP SCIENTIFIC CMOS IMAGE SENSOR



GSENSE6510BSI is a 3200 x 3200 (10.2 MP) resolution image sensor with industry-standard 6.5 μm x 6.5 μm pixel and large 29.4 mm diagonal for increased throughput in microscopy applications compared to 19 mm sCMOS devices. With a peak QE of 95% and read noise of 0.7 e⁻ median, the sensor achieves exceptional signal-to-noise in extreme low light applications. The sensor offers five imaging modes. In 12-bit mode, the sensor delivers 62.3 dB of dynamic range with a read noise floor or 1.3 e⁻ at 88 fps. In 11-bit HDR mode, the sensor uses dual-gain readout to achieve 78.8 dB of dynamic range with a read noise of 1.8 e⁻ at the same 83 fps. Additionally, the sensor offers two high-speed modes, an 8-bit mode reaching 500 fps and an 11-bit mode reaching 166 fps.

Key features and Benefits

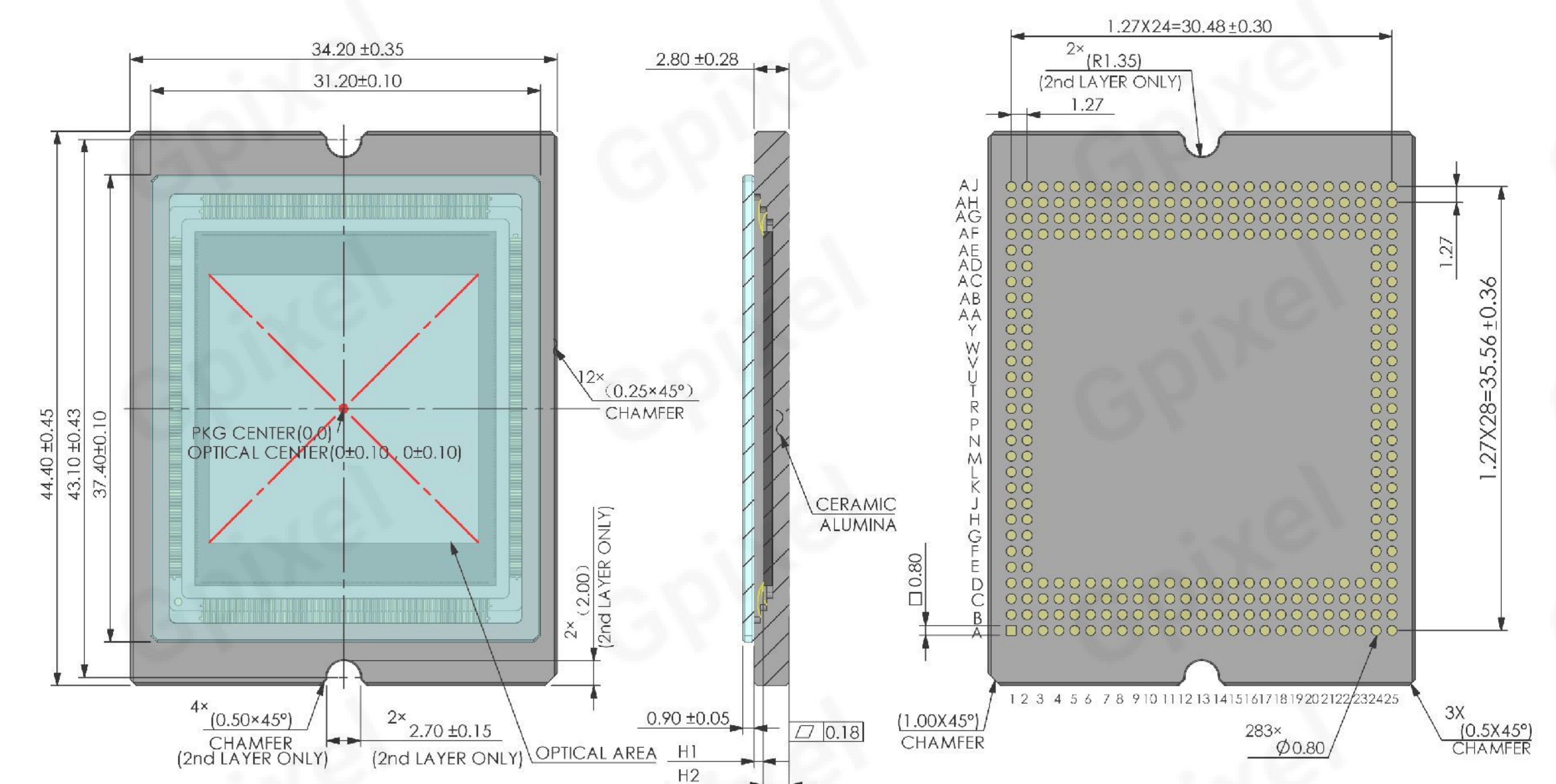
- Low noise
- High sensitivity
- Dual Gain HDR
- High frame rate

Application

- Life Sciences
- Microscopy

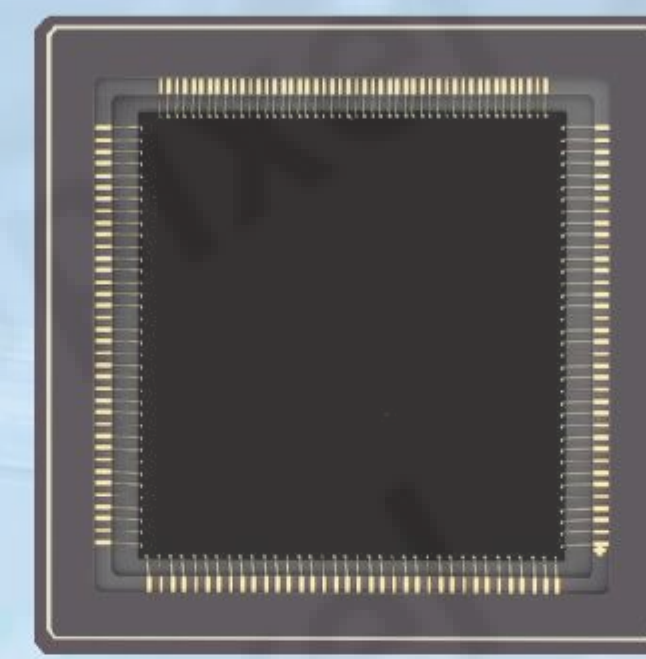
Specifications			
Nr of Active Pixels	3200 (H) x 3200(V)	Pixel size	6.5 μm x 6.5 μm
Optical format	1.83"	Shutter type	Rolling shutter
Photosensitive area	20.8 mm x 20.8 mm	Input clock rate	960 MHz
Peak QE	95% Peak QE @ 610 nm	Full well capacity	21 ke ⁻
Dark Current	0.2 e ⁻ /pixel/s @ -10°C	Temporal noise	0.7 e ⁻
Max Frame rate	500 fps @ 8bit	Dynamic Range	78.8 dB
Output format	72 pairs LVDS	Max. Data rate	69.12 Gbps @ 8 bit
Chroma	Mono	Power consumption	<5 w @ 8 bit, <2.7 w @ 12 bit
Supply voltage	3.6V (analog), 2V (digital)	Package	284 pins LGA (44.4 mm x 34.2 mm)

Package Drawing



GSENSE400BSI

4MP SCIENTIFIC BSI CMOS IMAGE SENSOR



GSENSE400BSI is a high-performance 2k x 2k backside illuminated scientific image sensor designed for the most demanding scientific applications. It's generous 11 μm rolling shutter pixel combined with the sensor's dual gain HDR functionality deliver over 94 dB of dynamic range while maintaining a frame rate of 24 fps. If higher frame rates are required, 48 fps can be sustained in standard imaging mode with a dynamic range of 65 dB. The sensor's peak QE is 95% for exceptional sensitivity.

Key features and Benefits

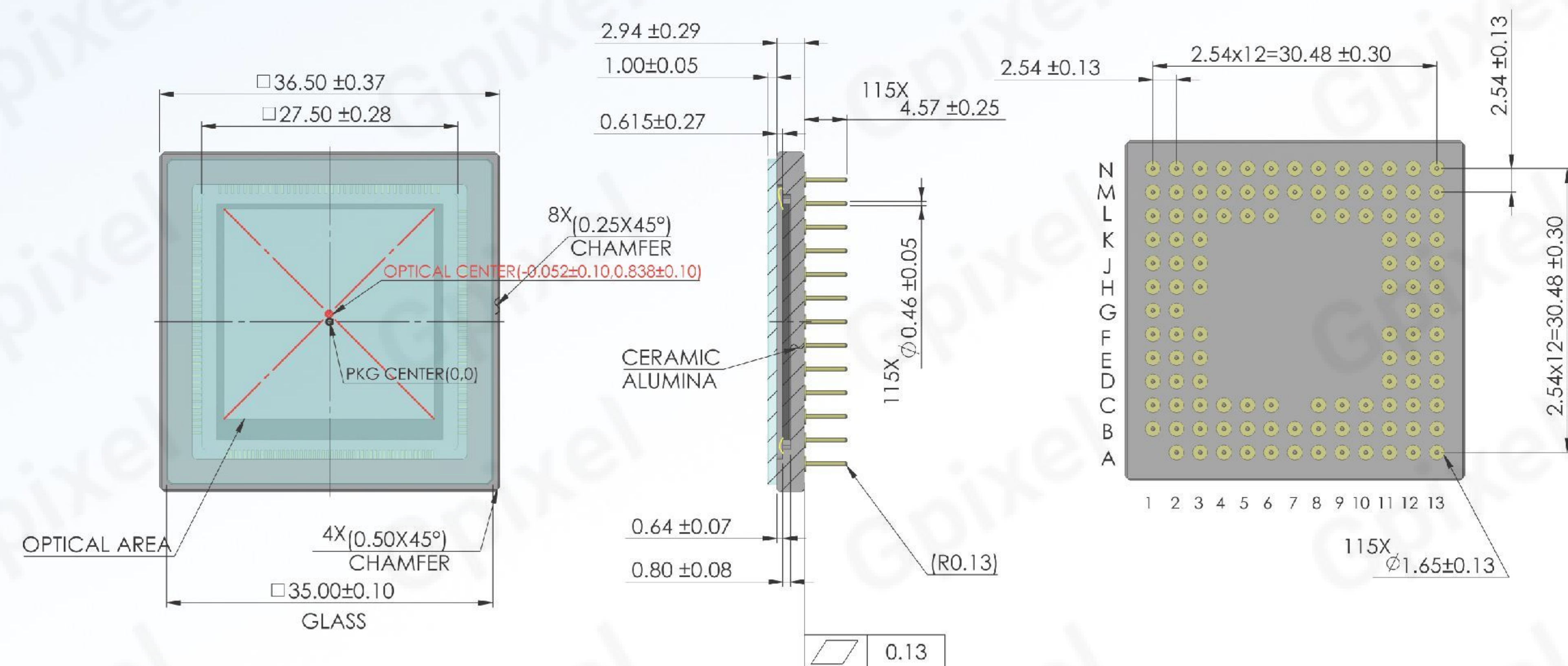
- Backside Illumination scientific CMOS
- Peak QE of 95%
- Low noise, low power for long exposure modes

Application

- Spectroscopy
- Life Sciences
- Astronomy
- Microscopy
- X-Ray

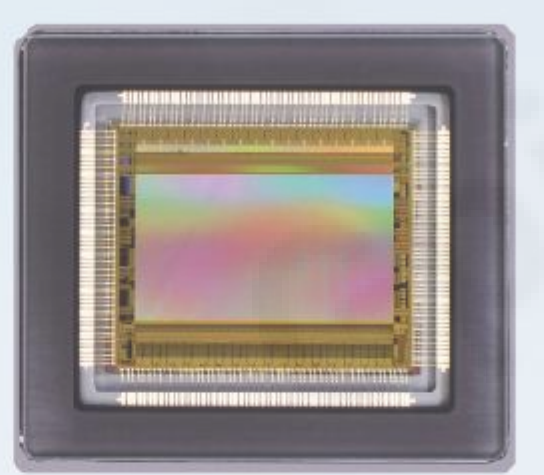
Specifications			
Nr of Active Pixels	2048 (H) x 2048 (V)	Pixel size	11 μm x 11 μm
Optical format	2"	Shutter type	Rolling shutter
Photosensitive area	22.5 mm x 22.5 mm	Input clock rate	25 MHz
Peak QE	95% @ 570 nm	Full well capacity	91 ke ⁻
Dark Current	0.27 e ⁻ /pixel/s @ -40°C	Temporal noise	1.6 e ⁻
Max Frame rate	48 fps @ STD	Dynamic Range	94 dB @ HDR
Output format	8 ch LVDS	Max. Data rate	2.4 Gbps
Chroma	Mono	Power consumption	<650 mW
Supply voltage	3.3 V(analog), 1.8 V(digital)	Package	115 pins PGA (36.5 mm x 36.5 mm)

Package Drawing



GSENSE2011

2MP SCIENTIFIC CMOS IMAGE SENSOR



GSENSE2011 is a 2MP resolution scientific CMOS image sensor, capable of operating with either global or rolling shutter. Featured with six transistor (6T) pixel design on a 6.5 μm pitch, the sensor has a very low readout noise of 2.1 e⁻ in rolling shutter HDR mode with max. frame rate is 83 fps in 12 bit rolling HDR mode. The sensor's HDR mode outputs two images after each exposure, which can be combined off-chip to achieve up to 87 dB dynamic range. The sensor also supports 653 fps in the high-speed mode with a trade-off on readout noise.

Key features and Benefits

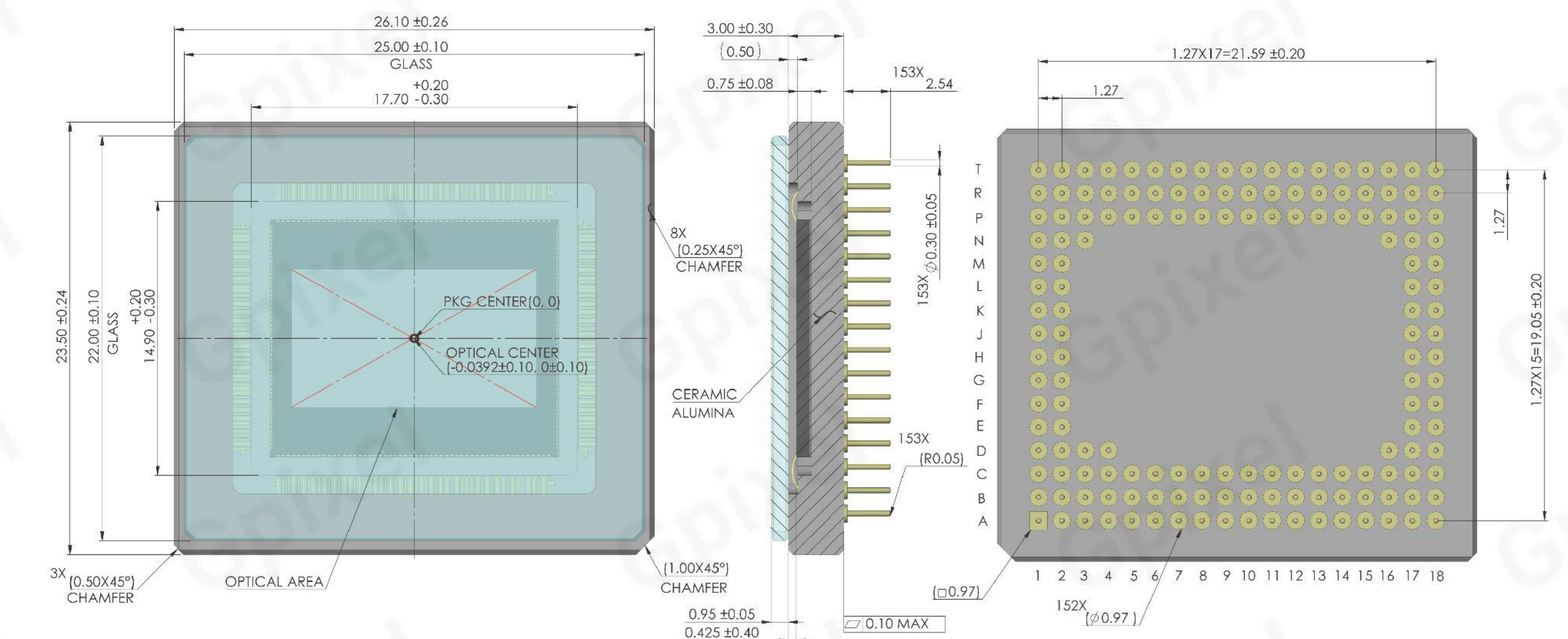
- Scientific CMOS
- Peak QE of 72%
- Low noise, low power for long exposure modes

Application

- Spectroscopy
- Life Sciences
- Astronomy
- Microscopy
- X-Ray

Specifications			
Nr of Active Pixels	2048 (H) x 1152 (V)	Pixel size	6.5 μm x 6.5 μm
Optical format	1"	Shutter type	Global & Rolling shutter
Photosensitive area	13.3 mm x 7.5 mm	Input clock rate	50 MHz
Peak QE	72% @ 595 nm	Full well capacity	45 ke ⁻
Dark Current	13 e ⁻ /pixel/s @ 30°C	Temporal noise	2.1 e ⁻
Max Frame rate	653 fps @ GS DDS, 83 fps @ RS HDR	Dynamic Range	87 dB
Output format	8 ch LVDS @ RS HDR, 32 ch LVDS @ GS DDS	Max. Data rate	4.8 Gbps
Chroma	Mono, RGB Color	Power consumption	<811 mW
Supply voltage	3.3 V(analog), 2.0 V(digital)	Package	153 pins μPGA (6.1 mm x 29.5 mm)

Package Drawing



GSENSE1081BSI

81MP SCIENTIFIC BSI CMOS IMAGE SENSOR



GSENSE1081BSI is an 81 MP backside illuminated scientific CMOS image sensor designed with large imaging area and an exceptional peak QE of 97%. The sensor provides active resolution of 8900(H) x 9120(V) with 10 μm x 10 μm pixel size. The inter-scene dynamic range is 84.5 dB, combined from maximum full well capacity of 90 ke⁻ and readout noise of 5.35 e⁻. GSENSE1081BSI supports on-chip 16 bit ADC, with 5 LVDS channels running up to 250 MHz each, providing a maximum frame rate of 0.34 fps. GSENSE1081BSI is assembled in a SiC package with one flexi-cable, reducing the gap in tiling. The thermal expansion of SiC is close to silicon die which is suitable for deep cooling applications.

Key features and Benefits

- 97% Peak QE @ 610 nm
- On-chip 16-bit column-parallel ADC
- Anti-glowing
- Silicon carbide with one flexi-cable

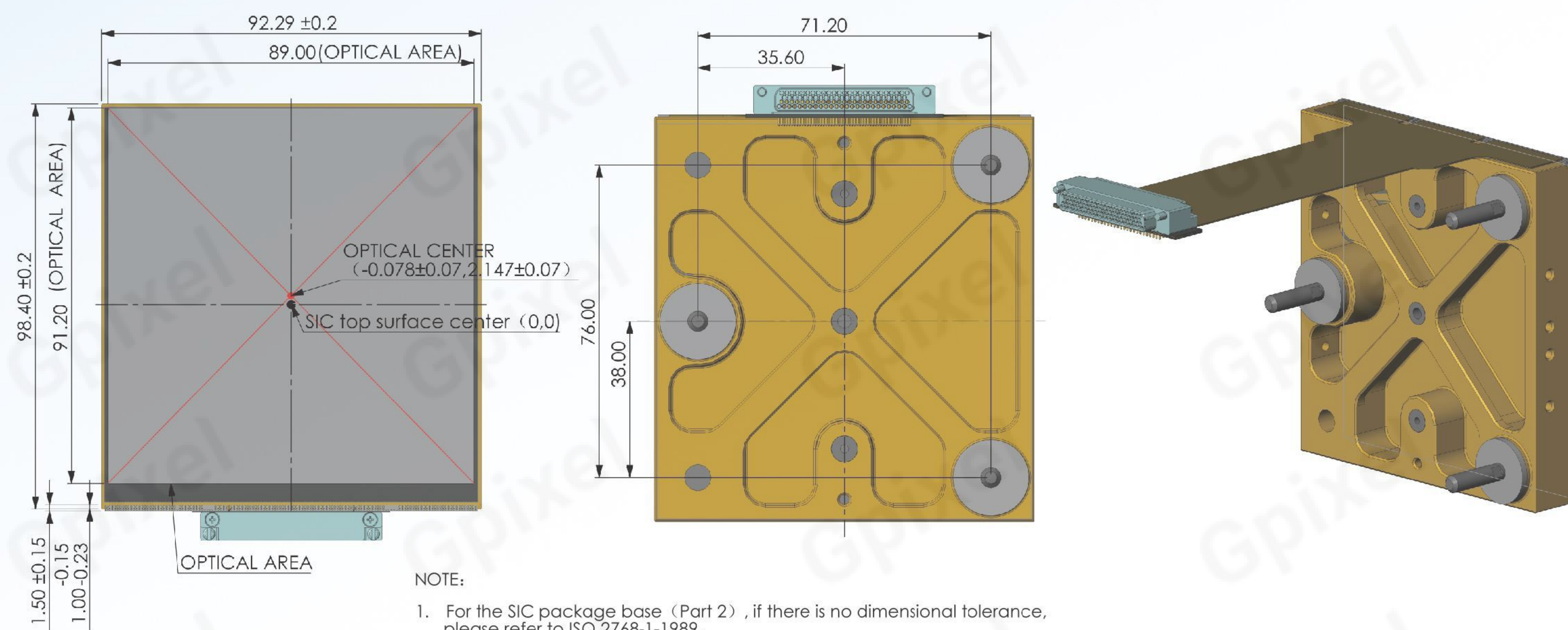
Application

- Astronomy

Specifications

Nr of Active Pixels	8900 (H) x 9120 (V)	Pixel size	10 μm x 10 μm
Optical format	7.96"	Shutter type	Rolling shutter
Photosensitive area	89.00 mm x 91.20 mm	Input clock rate	15.625 MHz
Peak QE	97.11% @ 610 nm	Full well capacity	90.68 ke ⁻
Dark Current	0.00373 e ⁻ /pixel/s @ -70°C	Temporal noise	5.35 e ⁻
Max Frame rate	0.34 fps @ 16-bit ADC, 0.94 fps @ 15-bit ADC	Dynamic Range	84.5 dB
Output format	5 ch LVDS	Max. Data rate	Max.500Mbps @ 16-bit ADC, Max.1.6Gbps @ 15-bit ADC
Chroma	Mono	Power consumption	1.4 W
Supply voltage	5 V(analog),1.8 V(digital)	Package	100-pin SiC package (92.3 mm x 98.4 mm)

Package Drawing



GMAX | GSPRINT | GSENSE | **GLUX** | GTOF | GCINE | GL

Area Scan CMOS Image Sensor

GLUX is a backside illuminated, scientific grade CMOS image sensor product family combining sub-electron noise performance, large pixel size, and high frame rates for ultra-low light imaging in scientific and surveillance applications. Products in this family are fully pin compatible and based on a 1" optical format.

GLUX9701BSI

GLUX1605BSI

Product Family Features

- Large pixel size
- Sub-electronic noise
- Low power consumption
- Back illuminated
- High sensitivity

Applications

- Scientific imaging
- Low-light Monitoring
- Ultraviolet industrial inspection



Area Scan CMOS Image Sensor

The GTOF series of products is a family of indirect time-of-flight (iToF) image sensors for 3D imaging, depth measurement, and ranging applications. This sensor family utilizes 3D wafer stacking at backside illumination technology to optimize sensitivity and precision.

GTOF0503

Product Family Features

- BSI stacked
- High sensitivity
- High measurement accuracy
- Dual frequency mode

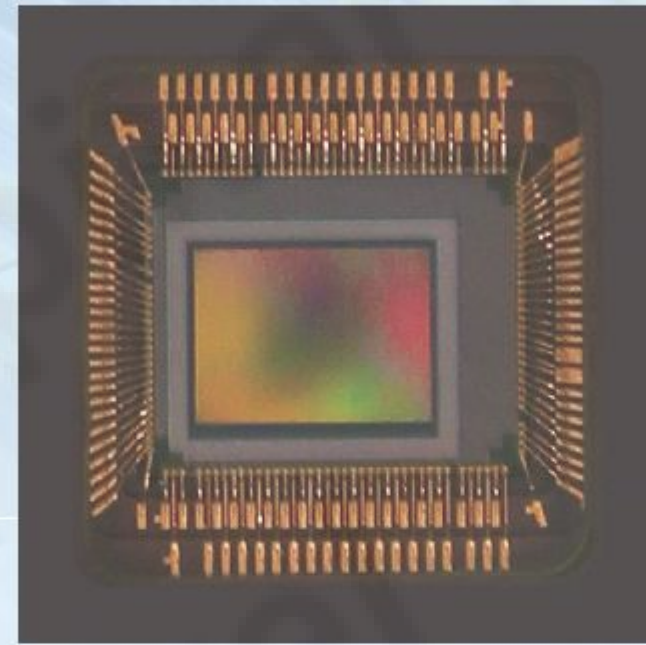
Applications

- Vision-guided Robots
- Industrial Automation
- Security monitoring
- Disorderly Grasping
- Logistics
- 3D measurement



GTOF0503

VGA ITOF CMOS IMAGE SENSOR



GTOF0503 is a VGA sensor featuring a 5 μm 3-tap state-of-the-art iToF pixel for high-precision depth measurement. The BSI technology provides excellent sensitivity at NIR wavelengths. In addition, the wafer stacking enables very high modulation frequencies of up to up to 3ns pulse width and 30 depth frames per second which results in industry-leading depth accuracy at short, mid and long-range distances, even in challenging ambient light conditions, by using pulse modulation. Advanced features such as multiple acquisition modes, depth with single and dual-frequency, low-power standby modes and an industry standard MIPI CSI-2 interface, allow very versatile and flexible operation.

Key features and Benefits

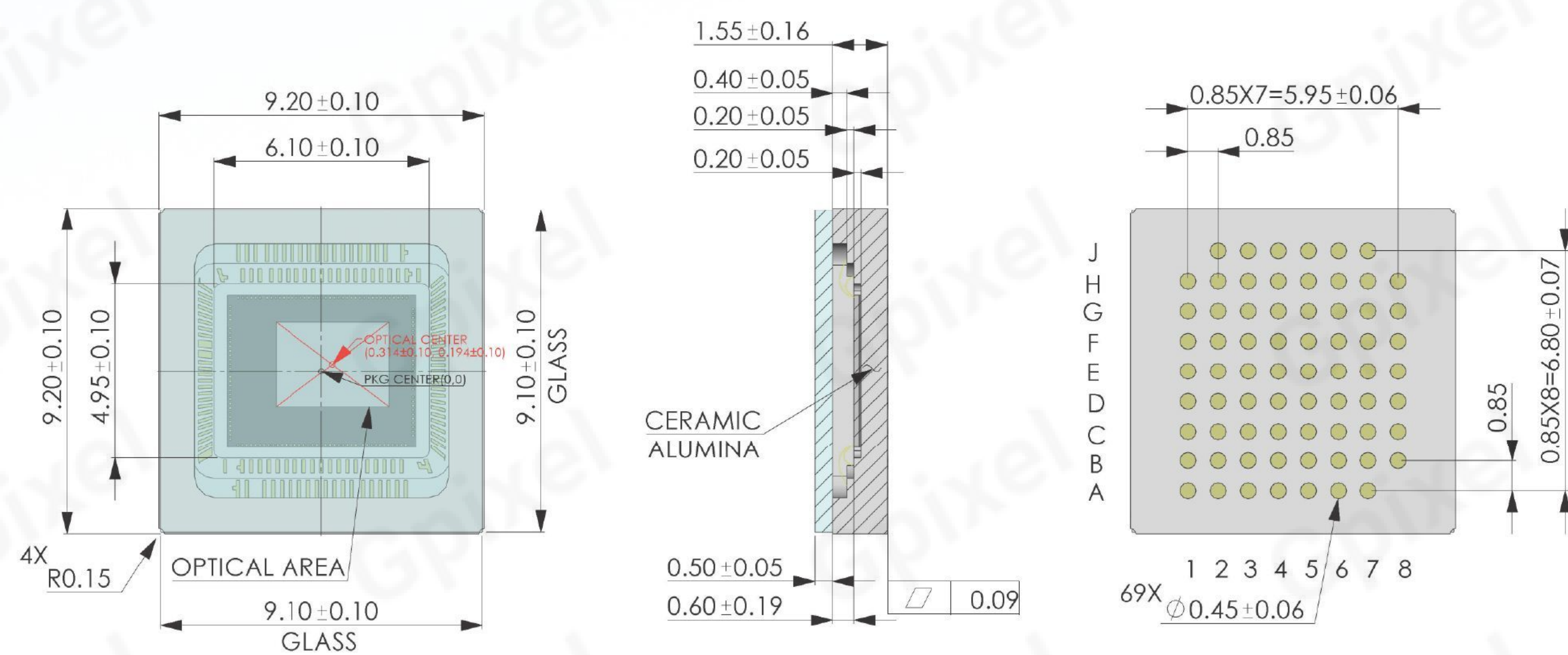
- Machine Vision
- Automated Guided Vehicle
- Industrial Automation
- Bin Picking
- Logistics
- Smart Factory

Application

- Automation & Inspection
- Logistics
- ADAS & Intelligent Driving
- Robotics
- Consumer Electronics

Specifications			
Nr of Active Pixels	640 (H) x 480 (V)	Pixel size	5 μm x 5 μm
Optical format	1/4"	Shutter type	Global Shutter
Photosensitive area	3.2 mm x 2.4 mm	Full well capacity	10 ke ⁻
Peak QE	>20% @ 940 nm	Temporal noise	<7e ⁻
Max. SNR	40 dB	ADC	11 bit
Max Frame rate	60 fps	Dynamic Range	60 dB
Output format	4 ch CSI-2 MIPI	Chroma	Mono
Binning	2x2 and 4x4	Supply voltage	2.8 V/1.8 V/1.2 V/1.3 V
Power consumption	330 mW	Package	139 pads(Die),69 pins LGA (9.2 mm x 9.2 mm)

Package drawing



GMAX | GSPRINT | GSENSE | GLUX | GTOF | **GCINE** | GL

Area Scan CMOS Image Sensor

The GCINE series is a family of image sensors for the professional imaging and broadcasting fields. The products utilize the latest stacked back-illuminated technology and feature high resolution, high frame rate, high sensitivity, and high dynamic range for broadcast, professional photography, drones, and high-end 8K video imaging.

GCINE3243

GCINE4349

Product Family Features

- Wafer stacking and backside illumination
- High dynamic range
- High frame rate
- Low noise

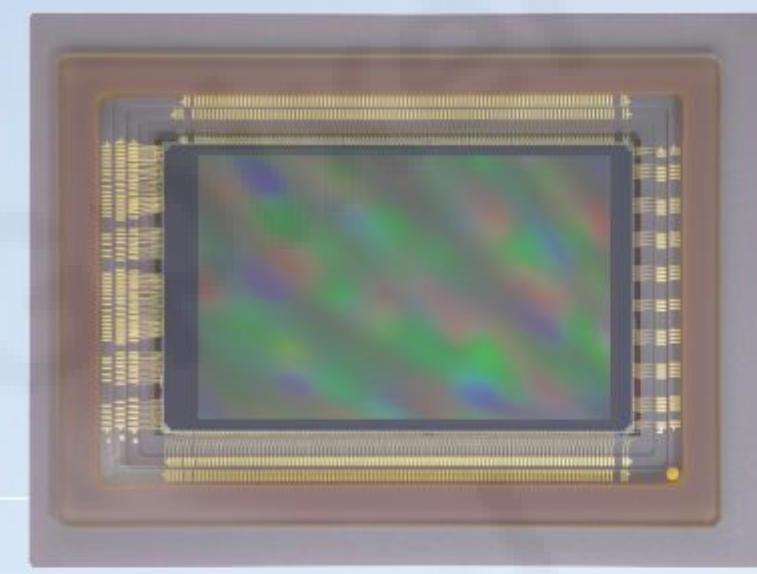
Applications

- Professional imaging



GCINE3243

8K APS-sized CMOS Image Sensor



GCINE3243 is a 43MP 26.2 mm x 16.7 mm sized APS-style image sensor with a 3.2 μm BSI pixel size designed specifically for the demands of high-end video imaging. With a resolution of 8192 x 5232 pixels and highly configurable read out, 8K video at 60 fps or binned 4K video at 120 fps is supported, all at an impressive bit depth of up to 14 bits per pixel. Readout of the image data occurs over 32 sub-LVDS channels @ 1.05 Gbps/channel. A dedicated Digital Still Camera (DSC) mode is supported, improving the readout noise and offering global reset shutter control. Additional HDR features, like dual gain readout, on-chip digital compression and multi-slope pixel response are also available.

Key features and Benefits

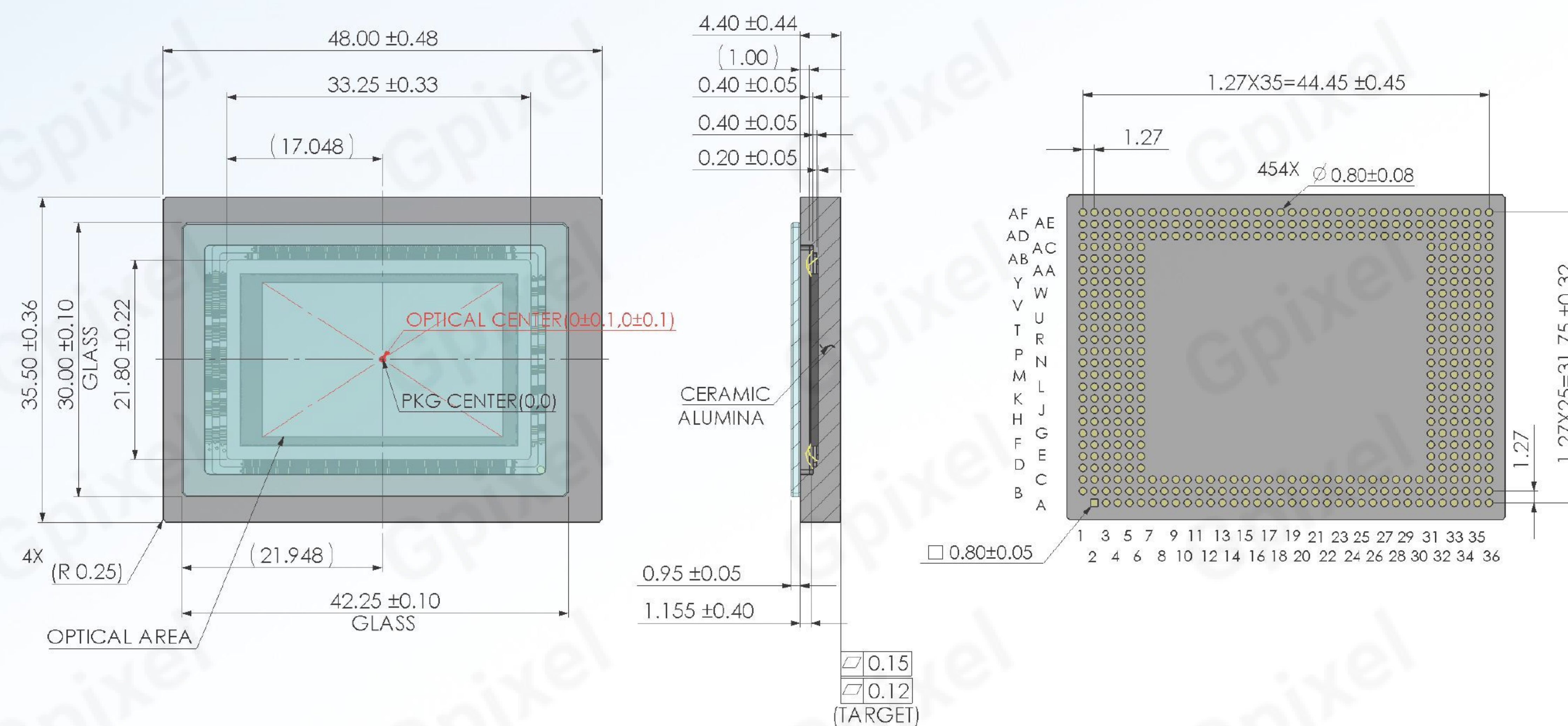
- Stacked BSI architecture
- High Full Well Charge
- High Dynamic Range
- Low noise
- Multi-slope HDR
- Dual Gain HDR

Application

- Cinematography
- Unmanned Aerial Vehicles (UAV)

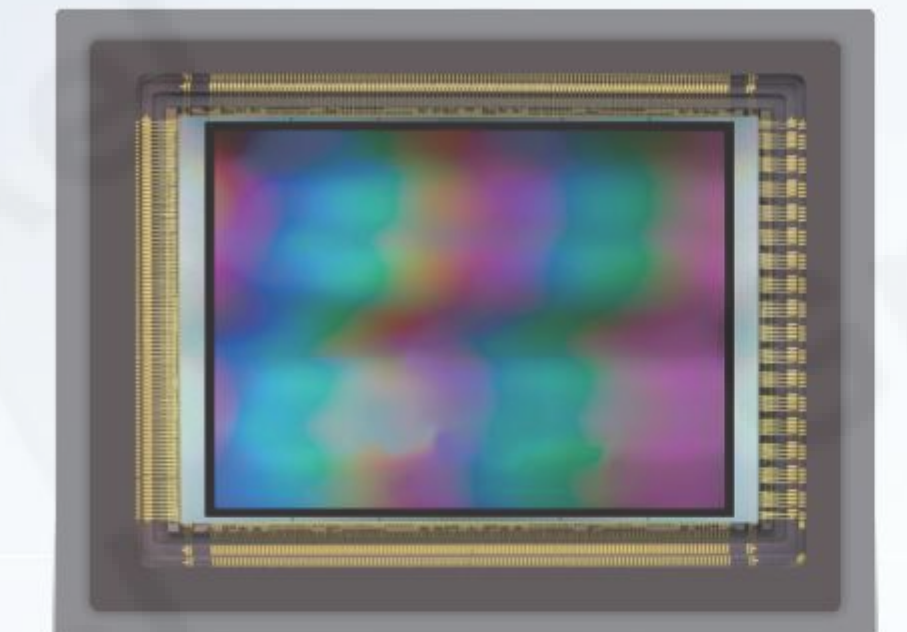
Specifications			
Nr of Active Pixels	8192 (H) x 5232(V)	Pixel size	3.2 μm x 3.2 μm
Optical format	APS-C	Shutter type	Rolling Shutter & DSC
Photosensitive area	26.2 mm x 16.7 mm	Full well capacity	96 ke ⁻ @ Multi-exposure Mode
Peak QE	80% @ 550 nm (Mono)	Temporal noise	2.5 e ⁻ @ DSC High Gain Mode
Max. SNR	50 dB	ADC	14 bit
Max Frame rate	60 fps @ 8K, 120 fps @ 4K	Dynamic Range	81dB @ 8K HDR mode
Output format	32 ch sub-LVDS	Chroma	Mono, RGB Color
Max. Data rate	33.6 Gbps	Supply voltage	3.3 V/1.8 V/1.25 V -2.2 V/4 V
Power consumption	2 W – 4 W	Package	455 pins LGA (48.0 mm x 35.5 mm)

Package Drawing



GCINE4349

8K Full Frame-sized CMOS Image Sensor



GCINE4349 is a 49MP 35.2 mm x 25.8 mm full frame image sensor with a 4.3 μm BSI pixels designed specifically for the demands and performance of high-end video imaging. With a maximum resolution of 8192 x 6000 pixels, several readout modes are supported to readout 8K video at 120 fps or binned 4K video at 240 fps, with a pixel bit depth of up to 16 bit/pixel interfaced over 64 sub-LVDS channels @ 1.2 Gbps/channel. A dedicated Digital Still Camera (DSC) mode is supported, improving the readout noise and offering global reset shutter control. Additional HDR features, like dual gain readout, on-chip digital compression and multi-slope pixel response are also available.

Key features and Benefits

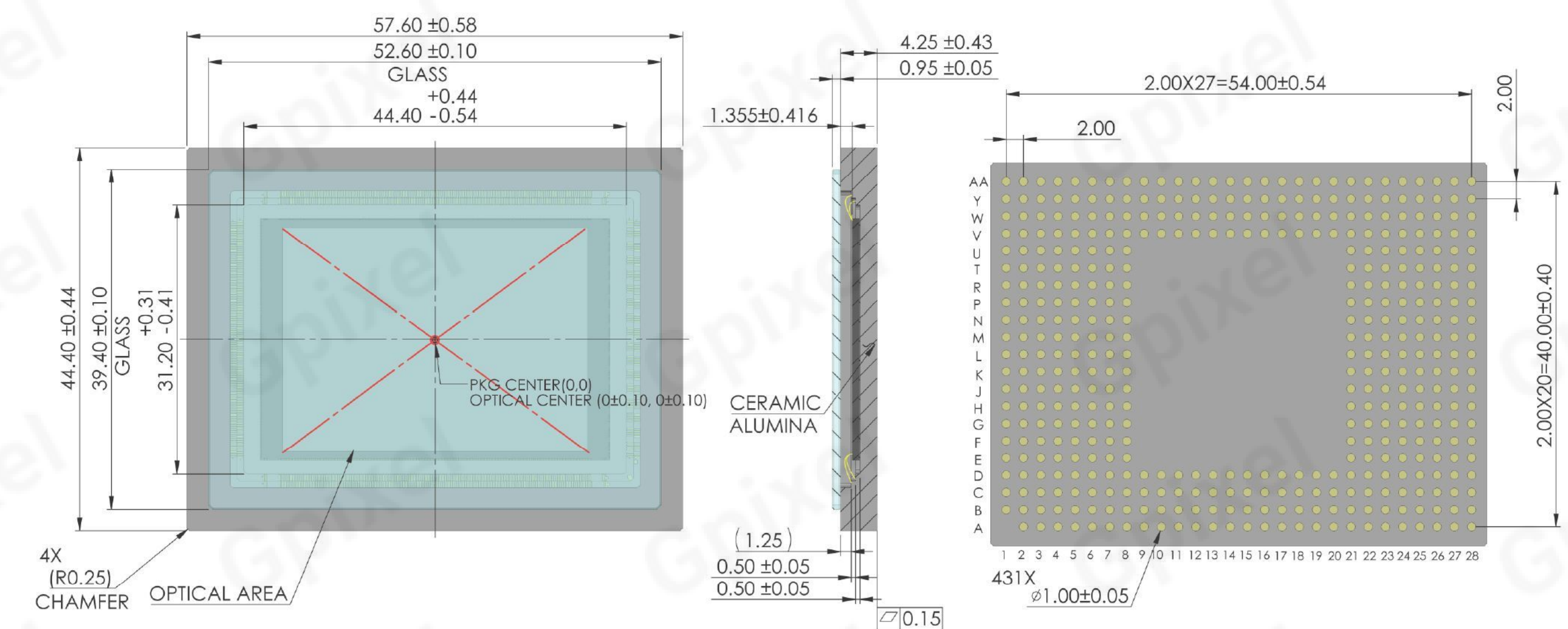
- Stacked BSI architecture
- High Full Well Charge
- High Dynamic Range
- Low noise
- Multi-slope HDR
- Dual Gain HDR

Application

- Cinematography
- Unmanned Aerial Vehicles (UAV)

Specifications			
Nr of Active Pixels	8192 (H) x 6000 (V)	Pixel size	4.3 μm x 4.3 μm
Optical format	2.2" (Full Frame)	Shutter type	Rolling Shutter & DSC
Photosensitive area	35.2 mm x 25.8 mm	Full well capacity	152 ke ⁻
Peak QE	85%	Temporal noise	1.9 e ⁻
Max. SNR	52 dB	ADC	16 bit
Max Frame rate	120 fps @ 8K, 240fps @ 4K	Dynamic Range	86.4 dB
Output format	64 ch Sub-LVDS	Chroma	Mono, RGB Color
Max. Data rate	76.8 Gbps	Supply voltage	3.3 V/ 1.8 V/1.25 V/ -2.2V
Power consumption	4.5 W-7.6 W	Package	431 pins LGA (57.6 mm x 44.4 mm)

Package Drawing



GMAX | GSPRINT | GSENSE | GLUX | GTOF | GCINE | **GL**

Line Scan CMOS Image Sensor

This sensor family comprises GL line scan image sensors with horizontal resolutions ranging from 2k to 16k, GLT sensors utilizing true charge-domain time delay and integration (TDI), and GLR sensors with rectangular pixels for displacement meters and spectroscopic imaging.

GLR1402BSI-M

GLR1205BSI-S

GL1402

GL3504

GL0402

GL7004

GL0816

GLT5009BSI

GLT5018BSI

GLT5016BSI

GL7008

GL3516

Product Family Features

- Global shutter
- TDI
- High line frequency
- Multispectral

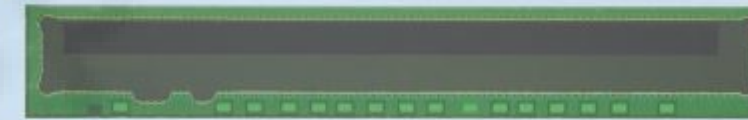
Applications

- Lithium Battery Inspection
- Printing Inspection
- Track Inspection
- PCB Testing
- Screen Inspection
- Automatic Sorting
- Semiconductor Testing
- Displacement Metering



GLR1205BSI-S

250 μm LINE SCAN CMOS IMAGE SENSOR



GLR1205BSI-S is a single-line linear image sensor with rectangular pixels and analog output designed for use in displacement sensors. The sensor's 512 pixels are each 12.5 μm (H) x 250 μm (V) and provide a full well capacity of 2.8 million electrons and a maximum signal-to-noise ratio of 71.1 dB. The large pixel also increases the photosensitive area and facilitates easy alignment of the laser spot. Backside thinning technology enables a peak quantum efficiency of 95%, and almost 50% at 650 nm. A charge transfer time of only 2.5 μs ensures excellent lag performance. The single analog output allows image processing using an MCU module, and the small CSP package enables the design of a compact displacement sensor.

Key features and Benefits

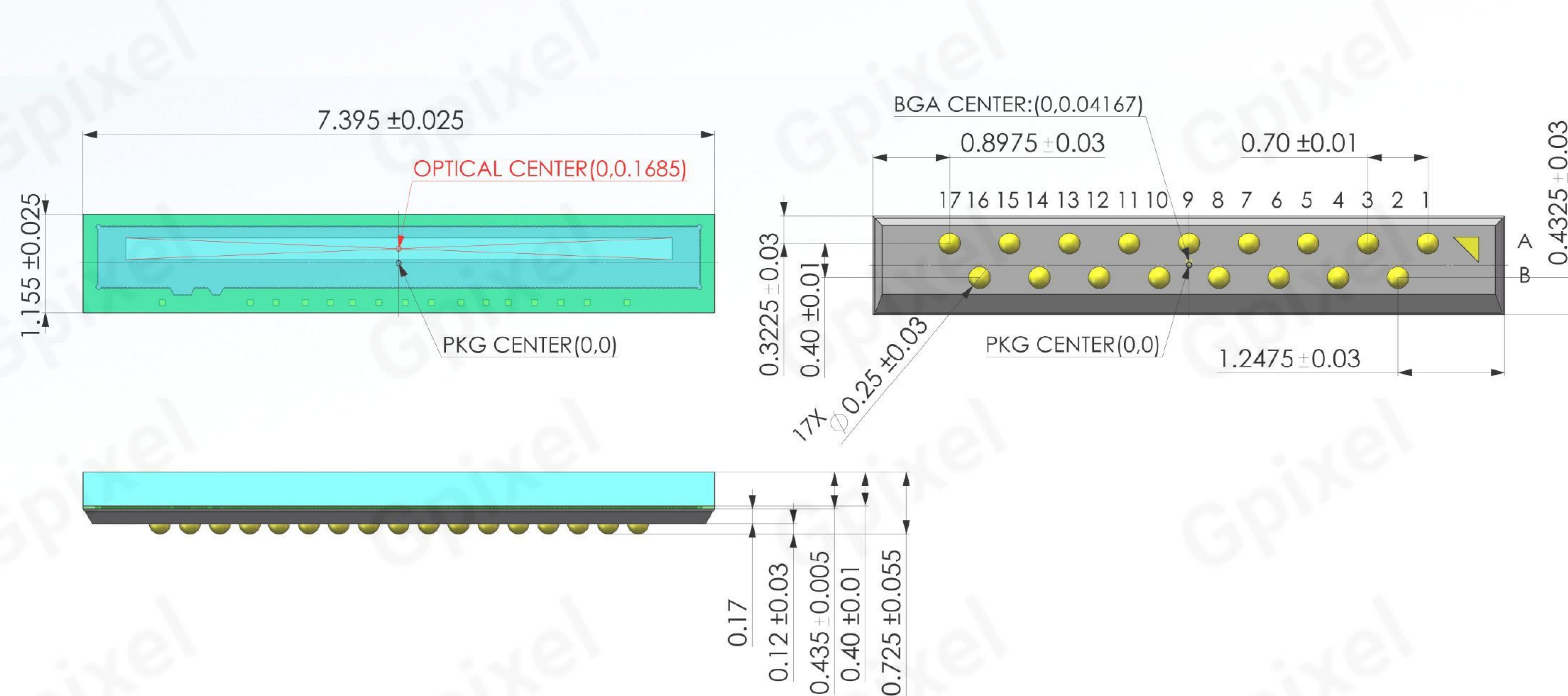
- BSI linear sensor
- Rectangular pixel
- C Mount Compatible
- CSP package
- Large FWC

Application

- Automation & Inspection
- Logistic & Positioning

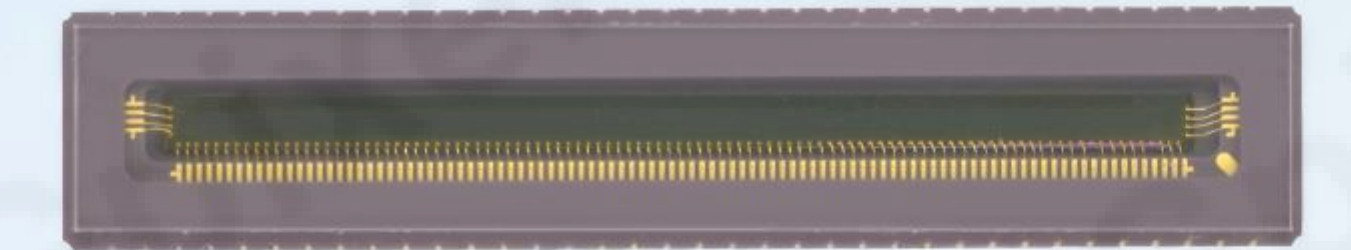
Specifications			
Nr of Active Pixels	512 (H) x 1 (V)	Pixel size	12.5 μm x 250 μm
Optical format	0.4"	Shutter type	Global shutter
Saturation output voltage	2.1 V	Photosensitive area	6.4 mm x 0.25 mm
Peak QE	95%	Temporal noise	0.58 mV rms
Max Line rate	9.43 kHz	Dynamic Range	3620:1
Output format	Analog output	Chroma	Mono
Max. Data rate	5 MHz	Supply voltage	3.3 V
Power consumption	90 mW	Package	17-pin CSP (7.395 mm x 1.155 mm)

Package Drawing



GLR1402BSI-M

2K BSI LINE SCAN CMOS IMAGE SENSOR



GLR1402BSI-M is a single-line linear sensor image sensor with rectangular pixels designed for spectroscopy, OCT, encoder and various other image reading applications.

GLR1402BSI-M has 2048 pixels in 1 row, with a pixel size of 14 μm x 350 μm, yielding an impressive max. 180 ke⁻ full well capacity and boasting a mere 1.4 e⁻ of noise.

Data is read out at 14 bits per pixel with 80 dB of dynamic range, or by combining two 12-bit pixel reads, high and low gain, to achieve a maximum dynamic range of 94 dB. GLR1402BSI-M supports both sLVDS and CMOS data outputs, customer can switch different data channels with 12-bit / 14-bit based on demand.

Key features and Benefits

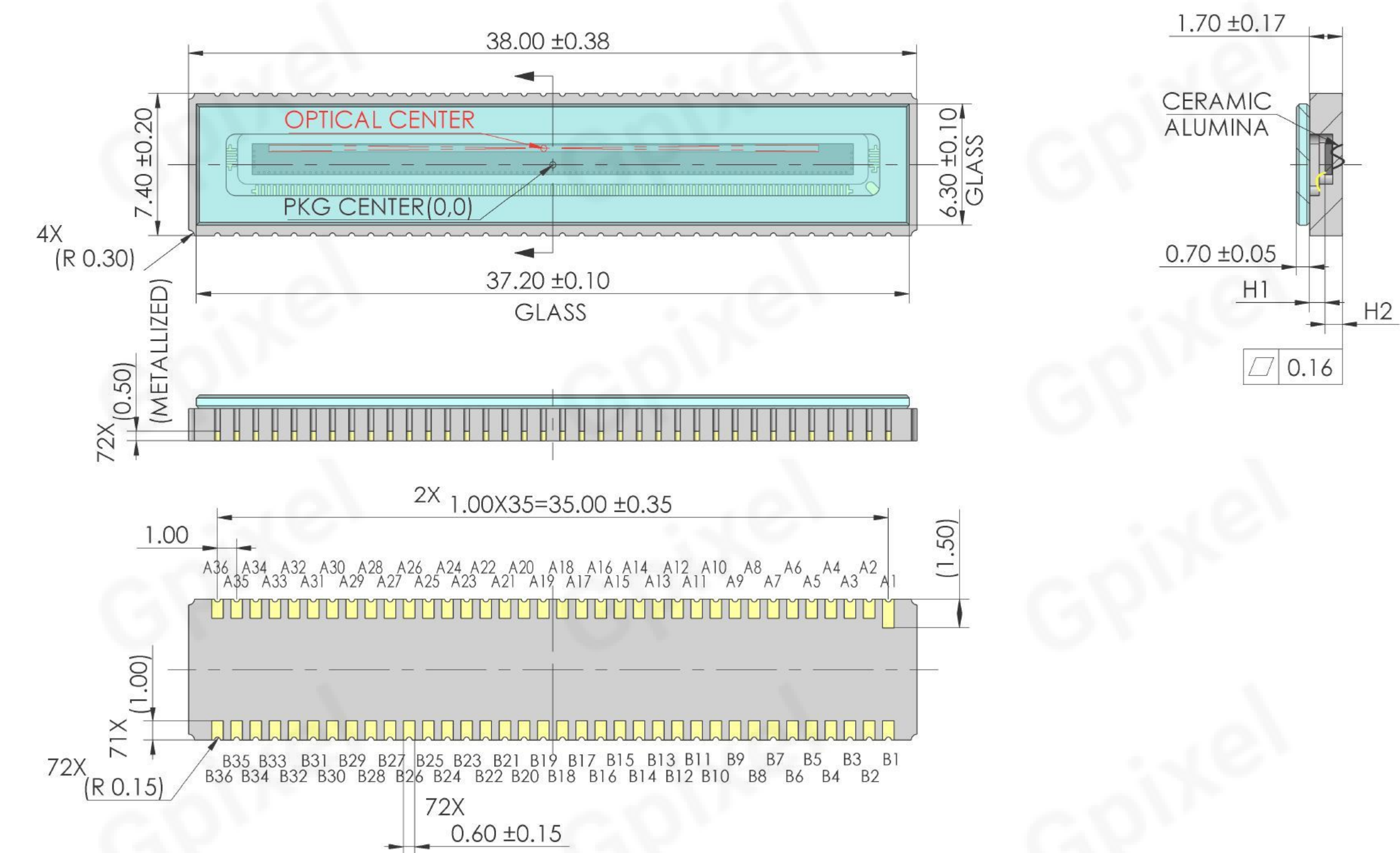
- Back Side Illuminated (BSI) pixels
- Dual gain HDR
- On-chip 12/14-bit ADC
- High Sensitivity
- High Speed: up to 28 kHz
- Wide QE from UV (200 nm) to NIR (1100 nm) with 85% peak at 420 nm

Application

- Spectroscopy

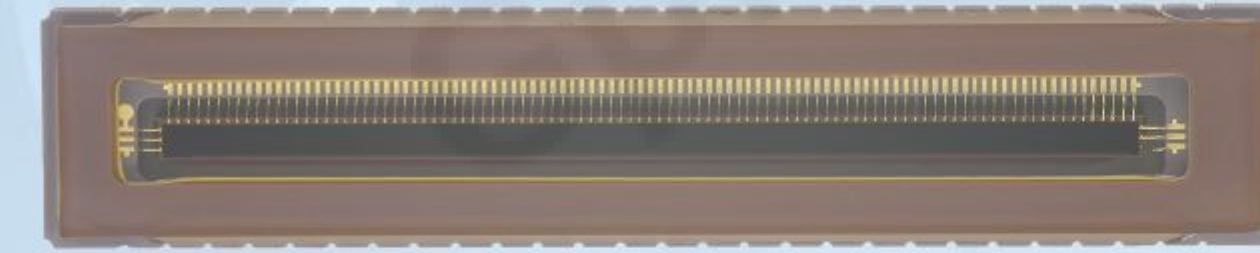
Specifications			
Nr of Active Pixels	2048 (H) x 1 (V)	Pixel size	14 μm x 350 μm
Optical format	28.672 mm	Shutter type	Global shutter
Full well capacity	180 ke ⁻ @ 12 bit HDR LG	Temporal noise	1.4 e ⁻ @ 14-bit HG
Peak QE	85% @ 420nm	Max. SNR	52 dB
Max Line rate	28 kHz	Dynamic Range	94 dB
Output format	4 ch Sub-LVDS, CMOS parallel output	Chroma	Mono
Channel multiplexing	Sub-LVDS 4/2/1	ADC	12-bit / 14-bit
Max. Data rate	2.4 Gbps @ Sub-LVDS, 600M @ CMOS	Supply voltage	3.6 V (analog), 1.8 V-3.3 V (IO), 1.5 V (digital)
Power consumption	350 mW	Package	CLCC 72 pins with quartz glass lid (38.0 mm x 7.4 mm)

Package Drawing



GL1402

2K LINE SCAN CMOS IMAGE SENSOR



GL1402 is a 2k line scan image sensor with 14 μm pixels. The color version of the sensor features red, green, and blue rows with 14 μm gaps between each row to minimize color crosstalk. The monochrome sensor features a three row monochrome option with a readout speed of 27 kHz, or a one row monochrome option with a readout speed of 81 kHz. GL1402 power consumption is less than 420 mW at maximum readout speed. The sensor is assembled into a 54 pin CLCC package with outer dimensions 38 x 7.4 mm.

Key features and Benefits

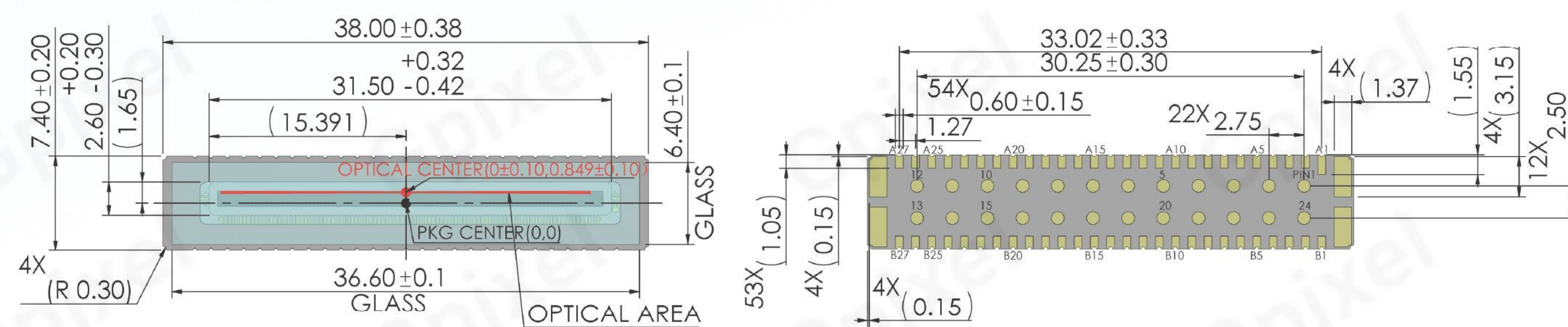
- Cost Efficient
- Low Power Consumption
- High Frame Rate
- High Dynamic Range

Application

- Grain Sorting
- Tomography (OCT)

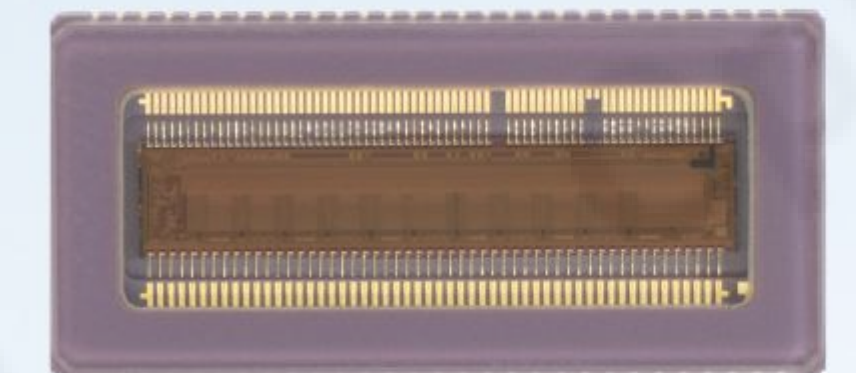
Specifications			
Nr of Active Pixels	2048 (H) x 1 (V), 2048 (H) x 3 (V)	Pixel size	14 μm x 14 μm
Optical format	28.896 mm	Shutter type	Global shutter
Full well capacity	28.7 ke ⁻	Photosensitive area	28.896 mm
Peak QE	69.3% @ 560nm	Temporal noise	9.1 e ⁻
Max. SNR	44.5 dB	Dark Current	702.7 e ⁻ /pixel/s @ 30°C
Max Line rate	81 kHz @ single line	Dynamic Range	69.9 dB
Output format	4 ch Sub-LVDS	Chroma	Mono, RGB color
Channel multiplexing	4/2/1	ADC	12 bit
Max. Data rate	2.08 Gbps	Supply voltage	3.6 V (analog), 1.8 V-3.3 V (IO), 1.5 V (digital)
Power consumption	<0.42 W	Package	54-pins CLCC (38.0 mm x 7.4 mm)

Package Drawing



GL3504

2K/4K LINE SCAN CMOS IMAGE SENSOR



GL3504 is a line scan image sensor suitable for small format camera integration with C mount lens. The sensor contains two lines with 3.5 μm pixels and four lines with 7 μm pixels. GL3504 can run up to 172 kHz with 7 μm pixel line and 84 kHz with 3.5 μm pixel line at 12 bit output with single line readout. GL3504 is assembled with a compact 58-pin CLCC package for fast heat dissipation and high robustness. Both monochrome and color variants are offered.

Key features and Benefits

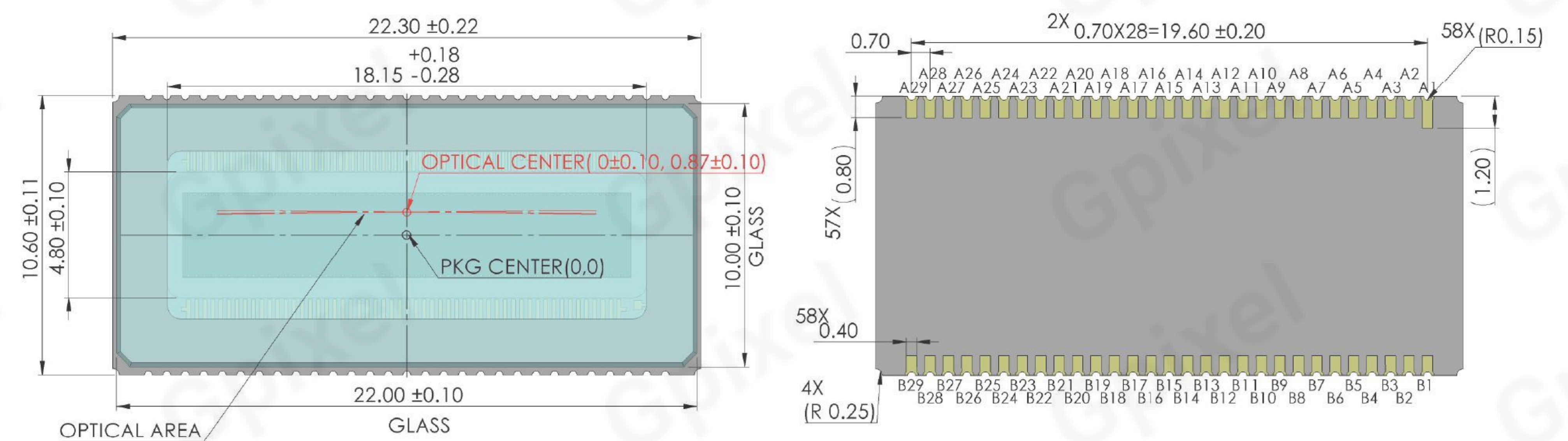
- High Speed
- Low Consumption
- High Dynamic Range
- C Mount Compatible

Application

- Automation & Inspection

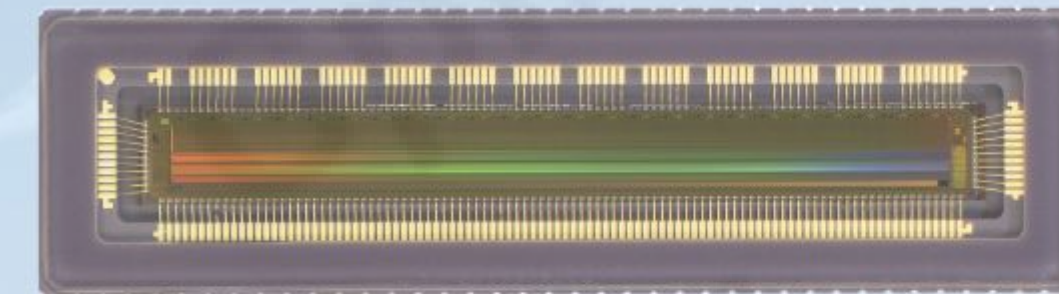
Specifications			
Nr of Active Pixels	4096 (H) x 2 (V) @ 3.5 μm / 2048 (H) x 4 (V) @ 7 μm	Pixel size	3.5 μm x 3.5 μm / 7 μm x 7 μm
Optical format	14.336 mm	Shutter type	Global shutter
Full well capacity	9.3 ke ⁻	Photosensitive area	14.336 mm
Peak QE	7 μm: 71.9% @ 570 nm, 3.5 μm: 62.0% @ 620 nm	Temporal noise	12 bit: 4.9 e ⁻ , 8 bit: 21.2 e ⁻
Max. SNR	39.7 dB	Dark Current	2.1 ke ⁻ /pixel/s @ 63°C
Max Line rate	172.7 kHz @ 7 μm @ 12 bit @ single line	Dynamic Range	65.8 dB @ 3.5 μm @ 12 bit
Output format	6 ch Sub-LVDS	Chroma	Mono, RGB color
Channel multiplexing	6/3/2/1	ADC	8/12 bit
Max. Data rate	5.472 Gbps	Supply voltage	3.3 V (analog), 2.5 V-3.3 V (IO), 2.1 V (digital)
Power consumption	<1.0 W	Package	CLCC 58 pins (22.3 mm x 10.6 mm)

Package Drawing



GL0402

4K LINE SCAN CMOS IMAGE SENSOR



GL0402 is a 4096 x 2 resolution, 7 μm square pixel, global shutter linear image sensor that supports a maximum 200 kHz line rate in single line mode and 100 kHz line rate in dual line mode. GL0402 offers read noise of less than 5.2 e⁻ and 10 ke⁻ FWC for 65.6 dB intra-scene dynamic range. GL0402 uses external clock and all required timing is generated by the on chip sequencer, reducing the amount of external components needed. Output channel multiplexing enables flexibility in FPGA choice, suitable for cost-effective camera solutions for demanding inspection applications. GL0402 is assembled in a compact 76-pin CLCC package for fast heat dissipation and high robustness.

Key features and Benefits

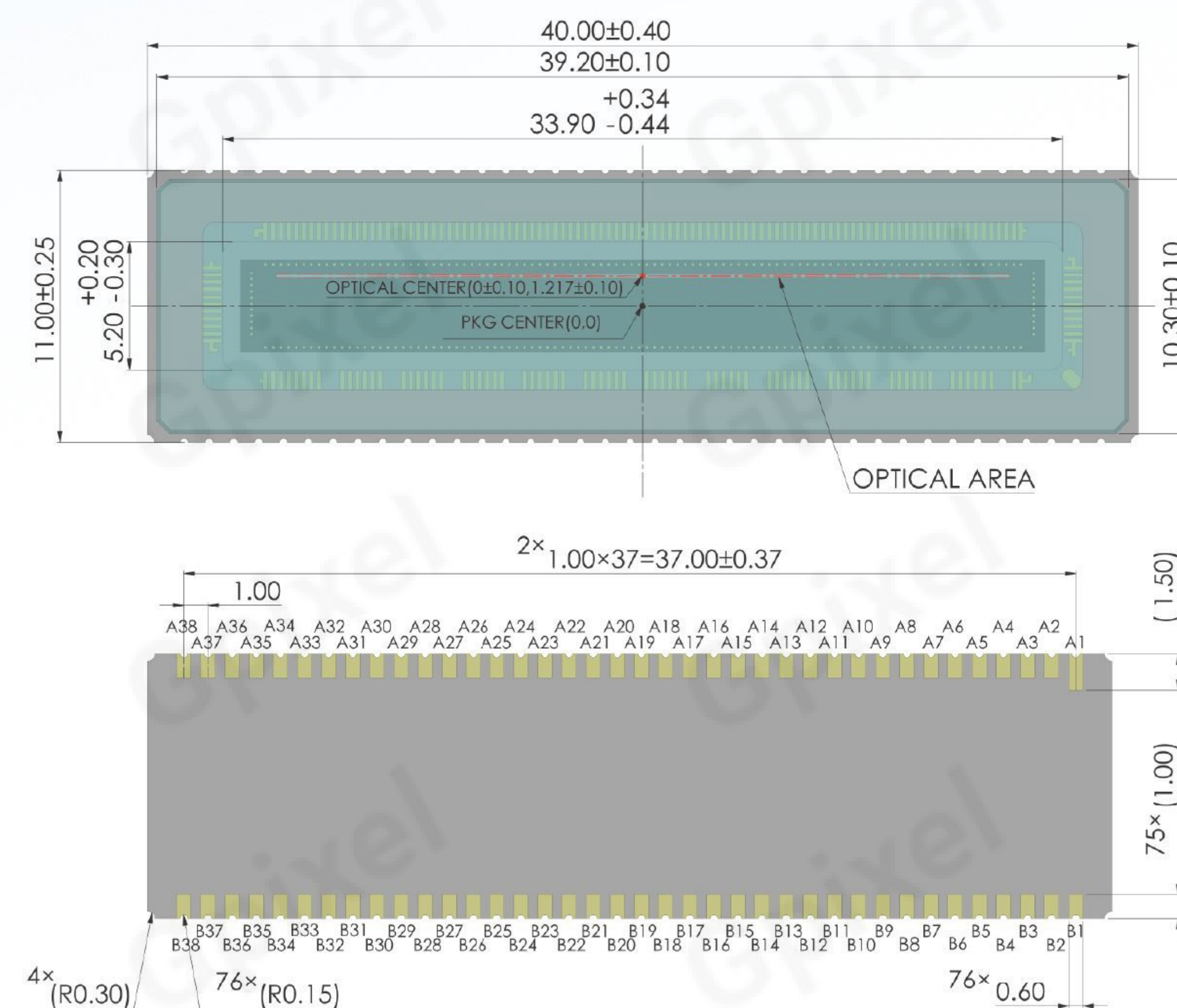
- High Speed
- High Dynamic Range
- Low Noise

Application

- Automation & Inspection

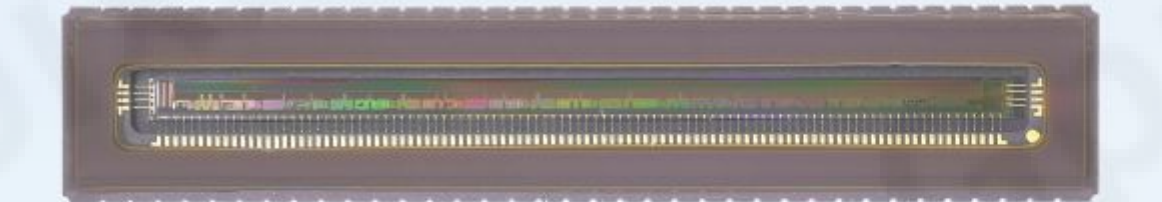
Specifications			
Nr of Active Pixels	4096 (H) x 2 (V)	Pixel size	7 μm x 7 μm
Optical format	28.67 mm	Shutter type	Global shutter
Full well capacity	25 ke ⁻ @ low gain, 10 ke ⁻ @ high gain	Photosensitive area	28.67 mm
Peak QE	75.57% @ 570 nm	Temporal noise	5.2 e ⁻
Max. SNR	43.9 dB	Dark Current	10 ke ⁻ /pixel/s @ 70°C
Max Line rate	200 kHz @ single line, 100 kHz @ dual line	Dynamic Range	65.6 dB @ high gain
Output format	12 ch Sub-LVDS	Chroma	Mono, RGB color
Channel multiplexing	12/6	ADC	12 bit
Max. Data rate	10.944 Gbps	Supply voltage	3.3 V(analog), 2 V(digital), 1.8 V-3.3 V(IO)
Power consumption	<2.25 W	Package	CLCC 76 pins (40.0 mm x 11.0 mm)

Package Drawing



GL7004

4K LINE SCAN CMOS IMAGE SENSOR



GL7004 is a 4096 (H) x 2/4 (V) resolution global shutter linear array CMOS image sensor, featuring 7 μm high-sensitivity pixels. Offered in two basic flavors: a multi color 4 row R+G+B+Mono and 2 row mono variants, the sensor allows each row to have a unique exposure time, with line rates up to 250 kHz in single line mode and 76.9 kHz in quad line mode. The sensor's high line rate is a perfect fit for high-throughput industrial inspection applications including sorting, solar panel inspection, printing inspection and railway monitoring at a cost-effective price point. The GL7004 is available in a compact LCC ceramic package, requiring only 3 external power supplies and consuming only 1.05 W.

Key features and Benefits

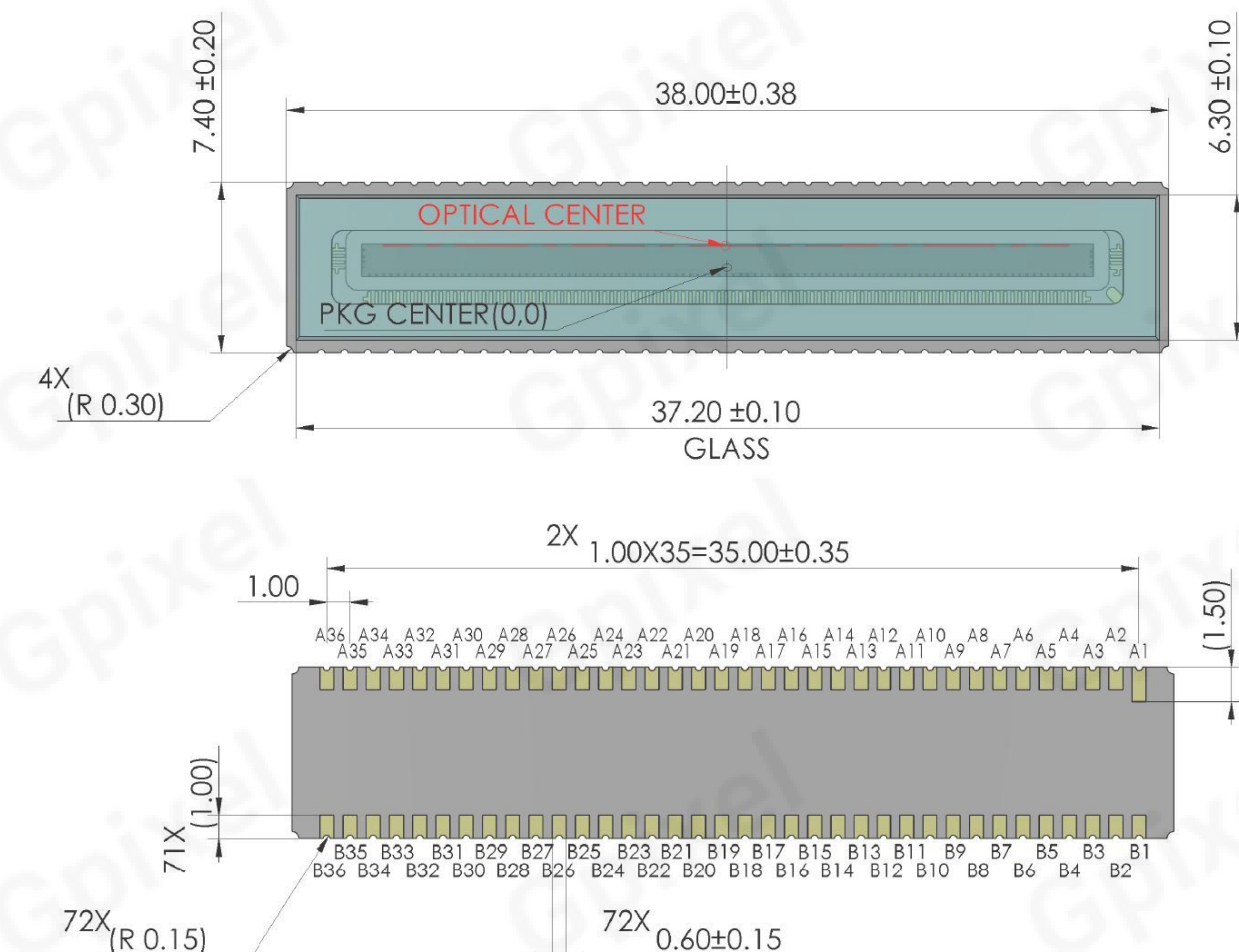
- Individual exposure control for each color line
- Low Power Consumption
- External Trigger
- Cost Efficient
- High Frame Rate

Application

- Automation & Inspection
- Logistic & Positioning

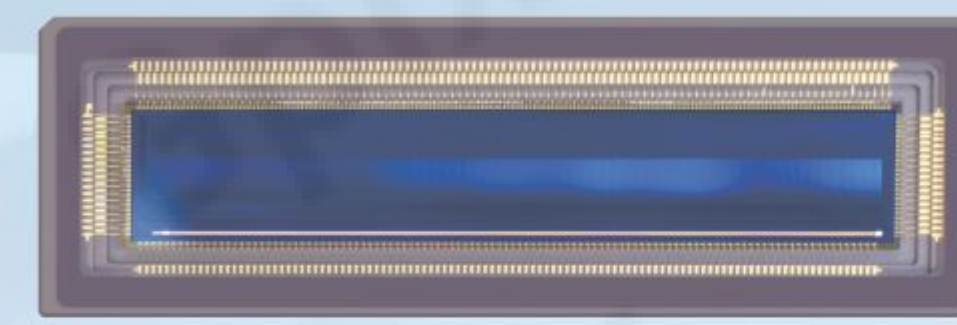
Specifications			
Nr of Active Pixels	4096 (H) x 4 (V)	Pixel size	7 μm x 7 μm
Optical format	28.67 mm	Shutter type	Global shutter
Full well capacity	10.5 ke ⁻	Photosensitive area	28.67 mm x 49 μm
Peak QE	76.8% @ 580 nm	Temporal noise	8.8 e ⁻
Max. SNR	40.2 dB	Dark Current	1.1 ke ⁻ /s @ 44.7°C
Max Line rate	250 kHz @ single-line, 76.9 kHz @ quad-line	Dynamic Range	61.5 dB
Output format	12 ch Sub-LVDS	Chroma	Mono, RGB color
Angular response	>20° (91% response)	ADC	10 bit
Max. Data rate	14.4 Gbps	Supply voltage	3.6 V(analog), 1.5 V(digital), 1.8 V-3.3 V(IO)
Power consumption	1.05 W	Package	72-pins CLCC (38.0 mm x 7.4 mm)

Package Drawing



GL0816

8322x16 LINE SCAN CMOS IMAGE SENSOR



GL0816 is a line scan CMOS image sensor which consists of 16 lines of 8322 pixels with 5 μm pixel size and 5 μm inter-line spacing. It supports dual line, 4-line readout and max 8-line with 2-stage on-chip TDI. The maximum line rate of GL0816 is 200 kHz @ 11bit dual-line mode and 100 kHz @ 10bit 4-line mode. The color version of GL0816 is manufactured with RGBW 4-band CFA with extremely low color crosstalk to enable accurate image reproduction.

Key features and Benefits

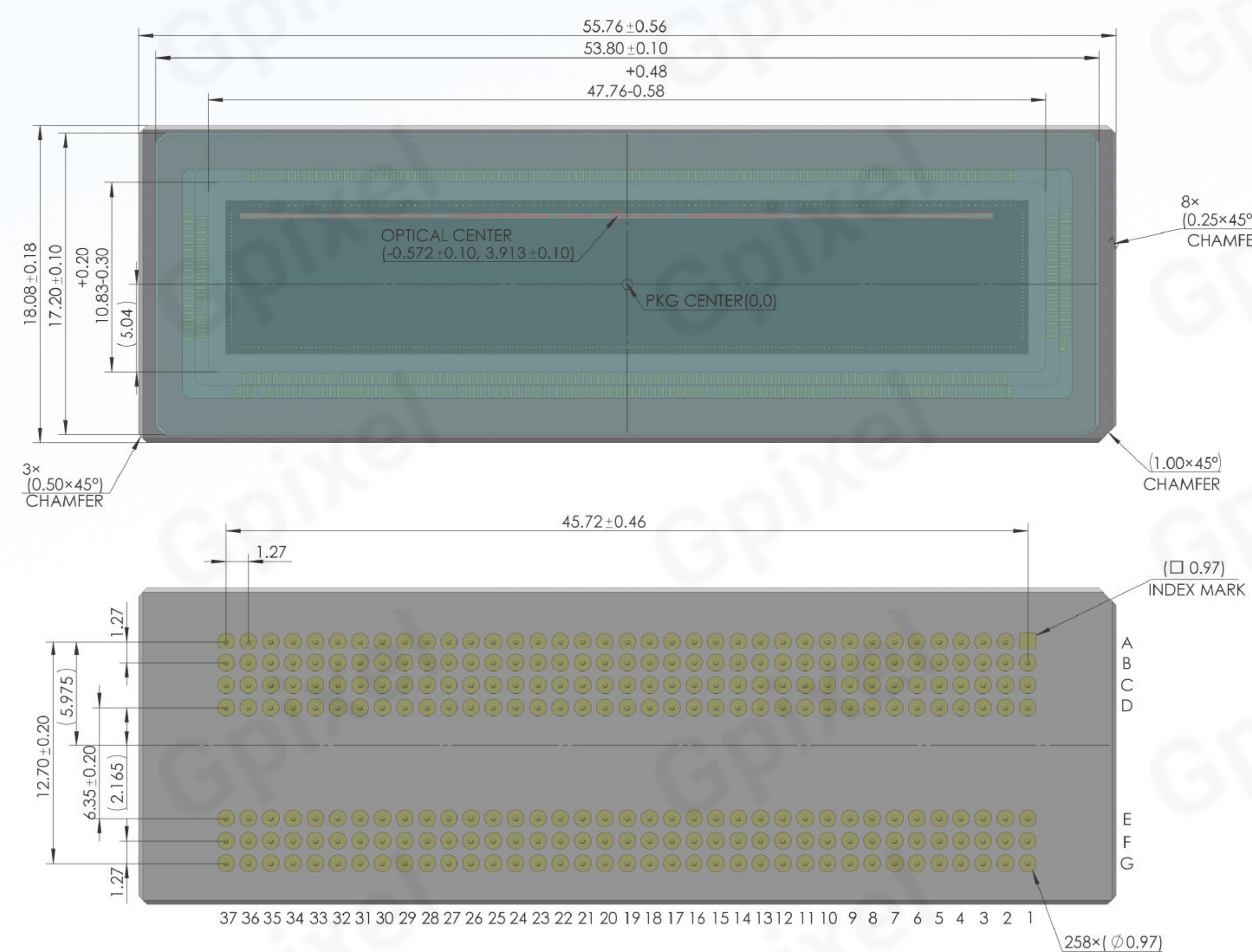
- High Speed
- TDI
- Excellent Color Accuracy
- High Resolution

Application

- Automation & Inspection

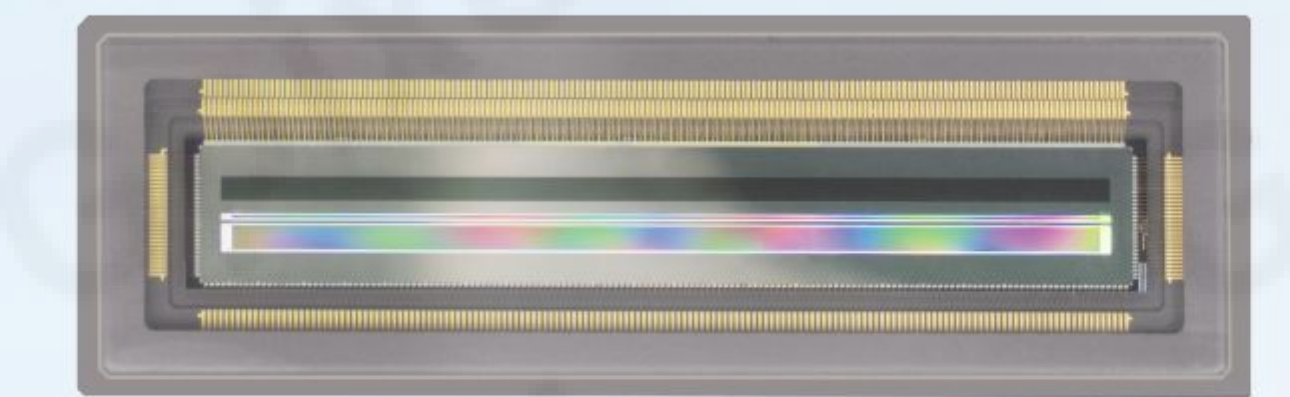
Specifications			
Nr of Active Pixels	8322 (H) x 16 (V)	Pixel size	5 μm x 5 μm
Optical format	41.61 mm	Shutter type	Global shutter
Full well capacity	17 ke ⁻ @ 11 bit, dual line; 15 ke ⁻ @ 10 bit, quad line	Photosensitive area	41.61 mm
Peak QE	>70% @ 600 nm	Temporal noise	13 e ⁻ @ 11 bit, dual line; 17 e ⁻ @ 10 bit quad line
Max. SNR	42 dB	Dark Current	6 ke ⁻ /pixel/s @ 76°C
Max Line rate	200 kHz @ 11 bit, dual line; 100 kHz @ 10 bit, quad line	Dynamic Range	62 dB @ 11 bit, dual line; 58.9 dB @ 10 bit, quad line
Output format	66 ch Sub-LVDS	Chroma	Mono, RGB color
Max. Data rate	800 Mbps	Supply voltage	3.3 V(analog), 2 V(digital/LVDS), 2.2 V(ADC)
Power consumption	<4 W	Package	258 Pins μPGA (55.8 mm x 18.1 mm)

Package Drawing



GLT5009BSI

9K BSI TDI CMOS IMAGE SENSOR



GLT5009BSI is a Backside illuminated (BSI), charge-domain Time delay and integration (TDI) CMOS image sensor with 5 μm pixels, 9k resolution and line rate up to 608 kHz. The sensor has two photosensitive bands, 256 stages and 32 stages respectively, enabling a high dynamic range (HDR) imaging mode. The sensor integrates several features to ease camera integration including an internal sequencer, channel multiplexing, and selectable scan direction. GLT5009BSI is assembled in a 269-pin μPGA package for reliability and good heat dissipation.

Key features and Benefits

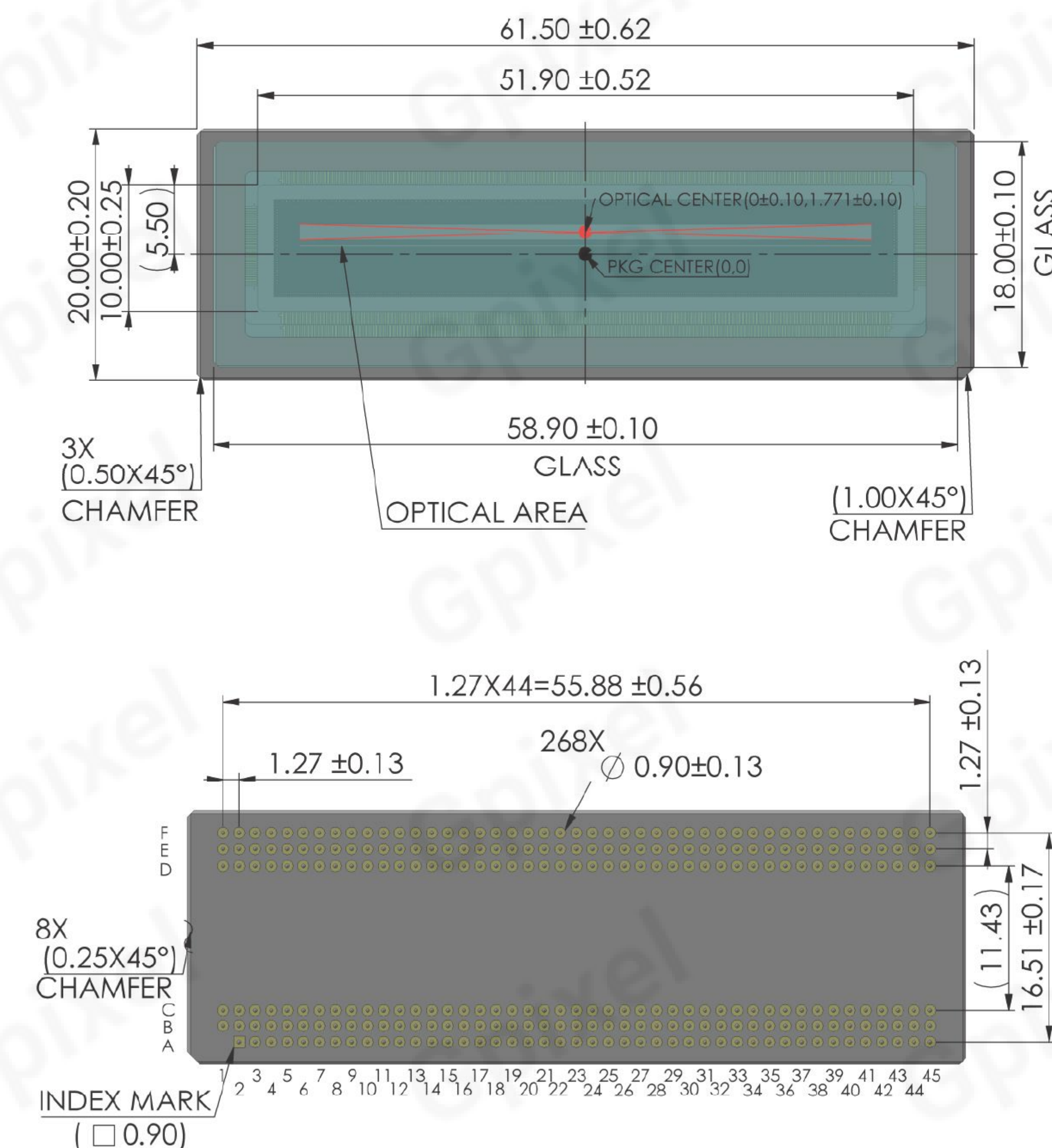
- True charge-domain TDI
- High Speed
- Back Side Illuminated (BSI)
- HDR read out
- High Sensitivity
- QE @ 266nm ≥ 50%

Application

- Automation & Inspection
- Life Sciences
- Microscopy
- Semiconductor Inspection

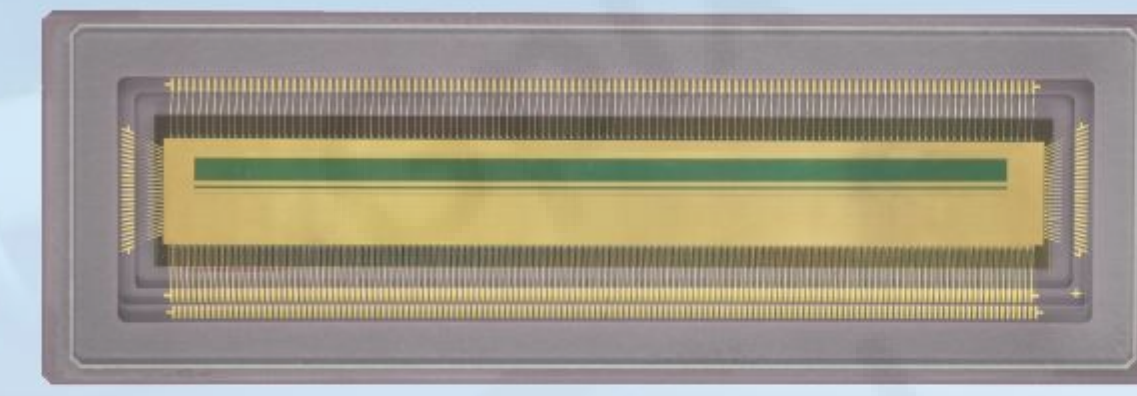
Specifications			
Nr of Active Pixels	9072 (H) x (256 + 32) (V)	Pixel size	5 μm x 5 μm
Optical format	45.36 mm	Shutter type	Global shutter
Full well capacity	15.8 ke ⁻ @ 10 bit / 15.9 ke ⁻ @ 12 bit	Photosensitive area	P1: 45.36 mm x 1.28 mm, P2: 45.36 mm x 0.16 mm
Peak QE	STD : 82.4% @ 550 nm / DUV : 61% @ 248 nm	Temporal noise	10.5 e ⁻ @ 10 bit, 6.2 e ⁻ @ 12 bit
Max. SNR	42 dB	Dark Current	~8 ke ⁻ /pix/sec @ 30°C
Max Line rate	608 kHz @ 10 bit / 300 kHz @ 12 bit	Dynamic Range	63.5 dB @ 10 bit, 68.1 dB @ 12 bit
Output format	84 ch Sub-LVDS	Chroma	Mono
Max. Data rate	74.304 Gbps	Supply voltage	5 V(analog), 1.8 V(ADC), 1.8 V(digital)
Power consumption	< 5.8 W @ 12bit, < 8.2 W @ 10bit	Package	μPGA 269 pins (61.5 mm x 20.0 mm)

Package Drawing



GLT5008BSI

8K BSI TDI LINE SCAN IMAGE SENSOR



GLT5008BSI is a Backside illuminated (BSI), Time delay integration (TDI), charge domain CMOS image sensor with 5 μm pixels and 8208 effective resolutions. The sensor has two photosensitive bands, 256 stages and 32 stages respectively enabling a high dynamic range (HDR) imaging mode, which is designed to meet the needs of high speed and low light applications by maximizing sensitivity with state-of-art BSI scientific CMOS technology.

GLT5008BSI Sensor integrates an on-chip sequencer, supports channel multiplexing and selectable 2 scan directions (Forward and Reverse). It is assembled in a 231-pin μPGA ceramic package for reliability and good heat dissipation.

Key features and Benefits

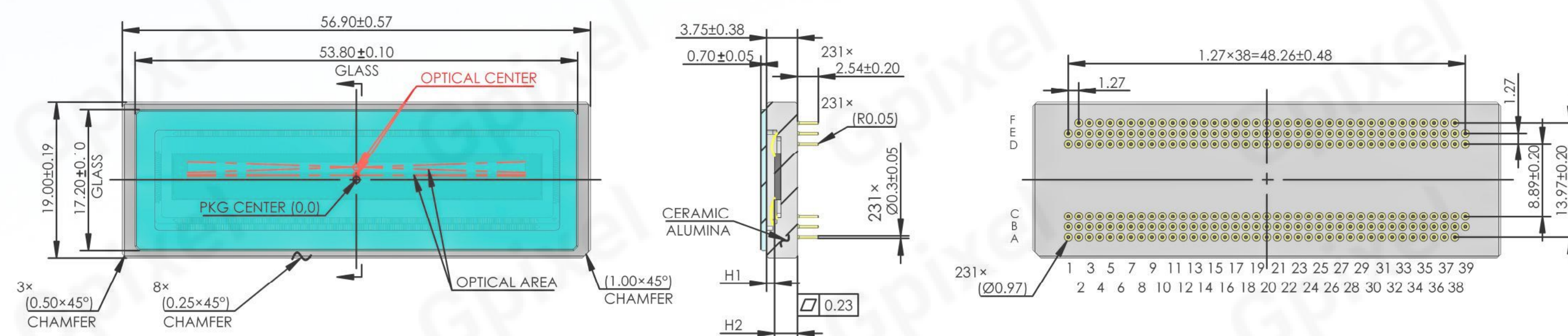
- True charge domain Time Delay Integration
- High Sensitivity with QE of 63.9% @ 266 nm and 93.4% @ 440 nm
- High Speed: up to 1 MHz
- Back Side Illuminated (BSI) pixels
- HDR read out
- On-chip binning

Application

- Automation & Inspection
- Life Sciences
- Microscopy
- Microluminescence Imaging

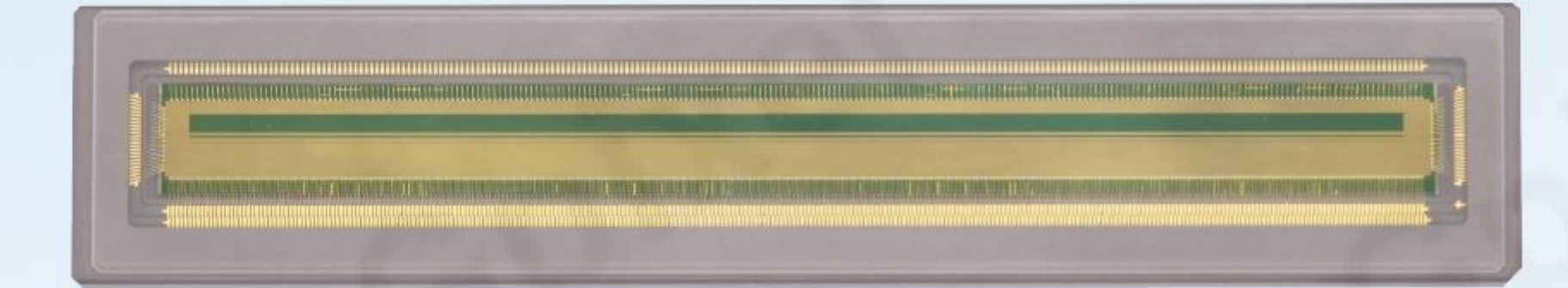
Specifications			
Nr of Active Pixels	P1: 8208 pixels x 256 stages P2: 8208 pixels x 32 stages	Photosensitive area	P1: 41.04 mm x 1.28 mm P2: 41.04 mm x 0.16 mm
Optical format	41.04 mm	Pixel size	5 μm x 5 μm
Full well capacity	17.0 ke ⁻ @ 10-bit	Shutter type	Time Delay Integration
Peak QE	93.4% @ 440 nm	Temporal noise	14.3 ke ⁻ @ 10-bit
Max. SNR	42.3 dB @ 10-bit	Dark Current	4.6 ke ⁻ /pixel/s @ 11.9°C
Max Line rate	1 MHz	Dynamic Range	61.5 dB @ 10-bit
Output format	72 ch Sub-LVDS @ 10-bit	Chroma	Mono
Channel multiplexing	72/54/48/36/24/18/12/6 @ 10-bit	ADC	10/12 bit
Max. Data rate	86.4 Gbps @ 10-bit	Supply voltage	3.3 V(analog), 1.65 V(ADC), 1.6 V(digital)
Power consumption	< 4.2 W @ 10-bit	Package	μPGA 231 pins (56.90 mm x 19.00 mm)

Package Drawing



GLT5016BSI

16k BSI TDI LINE SCAN IMAGE SENSOR



GLT5016BSI is a Backside illuminated (BSI), Time delay integration (TDI), charge domain CMOS image sensor with 5μm pixels and 16416 effective resolutions. The sensor has two photosensitive bands, 256 stages and 32 stages respectively enabling a high dynamic range (HDR) imaging mode, which is designed to meet the needs of high speed and low light applications by maximizing sensitivity with state-of-art BSI scientific CMOS technology.

GLT5016BSI comes in 2 spectrum variants: an UV-optimized with high QE below 300 nm and a visible and NIR range optimized version.

Key features and Benefits

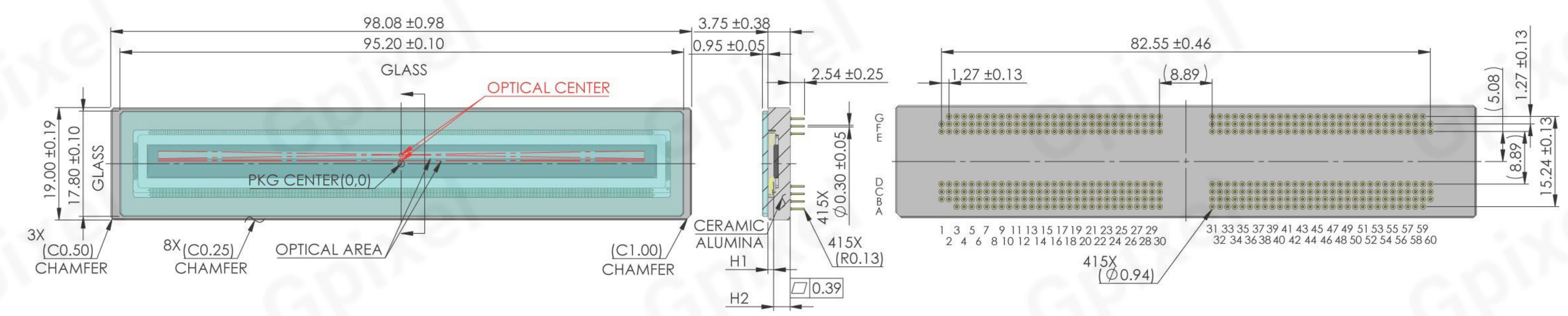
- True charge domain Time Delay Integration
- High Sensitivity with QE of 70.7% @ 266 nm (UV Version) and up to 92.4% @ 440 nm (VIS version)
- High Speed: up to 500 kHz
- Back Side Illuminated (BSI) pixels
- HDR read out
- On-chip binning

Application

- Automation & Inspection

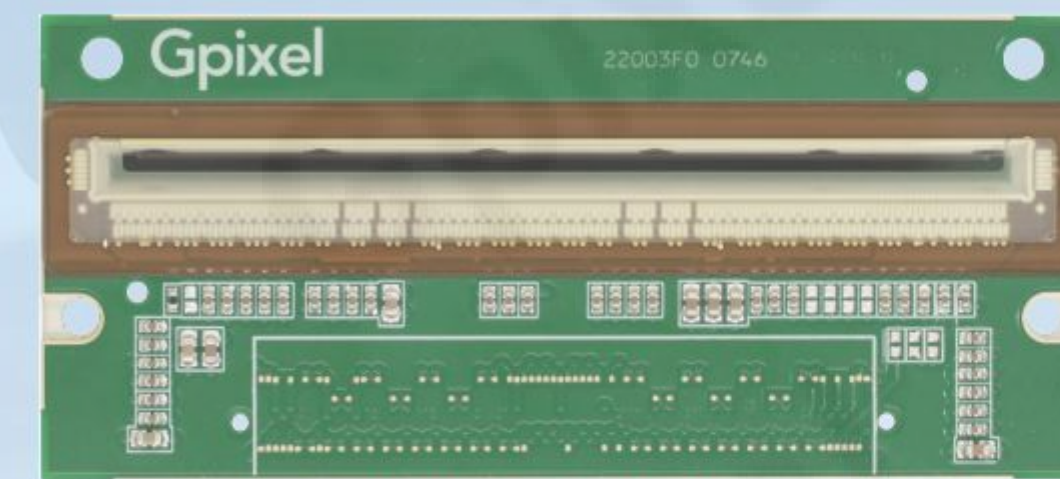
Specifications			
Nr of Active Pixels	P1: 16416 pixels x 256 stages P2: 16416 pixels x 32 stages	Photosensitive area	P1: 82.08 mm x 1.28 mm P2: 82.08 mm x 0.16 mm
Optical format	82.02 mm	Pixel size	5 μm x 5 μm
Full well capacity	15.0 ke ⁻	Shutter type	Time Delay Integration
Peak QE	UV version - 70.7% @ 266 nm - 87.8% @ 420 nm VIS version - 92.4% @ 436 nm - 87.0% @ 590 nm	Temporal noise	7.7 e ⁻
Max. SNR	41.7 dB	Dark Current	1.0 ke ⁻ /pixel/s @ 16.5°C
Max Line rate	500 kHz	Dynamic Range	65.8 dB
Output format	108 ch Sub-LVDS	Chroma	Mono
Channel multiplexing	108/96/72/48/36/24/12	ADC	12 bit
Max. Data rate	103.68 Gbps	Supply voltage	3.3 V(analog), 1.65 V(ADC), 1.6 V(digital)
Power consumption	< 6.2 W	Package	μPGA 415 pins (98.08 mm x 19.00 mm)

Package Drawing



GL7008

8K LINE SCAN CMOS IMAGE SENSOR



GL7008 is a global shutter line scan image sensor with 7 μm square pixel and 8192 horizontal resolution. The sensor's 12-bit ADC transmits data over 25 pairs of sub-LVDS at line rate up to 200 kHz. GL7008 is offered in both color and monochrome versions. The monochrome sensor supports single and dual line modes with optimal sensitivity. At full speed, the power consumption of GL7008 is around 4.4 W. The sensor adopts a COB package with WCu heat sink for optimal heat dissipation during high-speed scanning and is pin compatible with GL3516.

Key features and Benefits

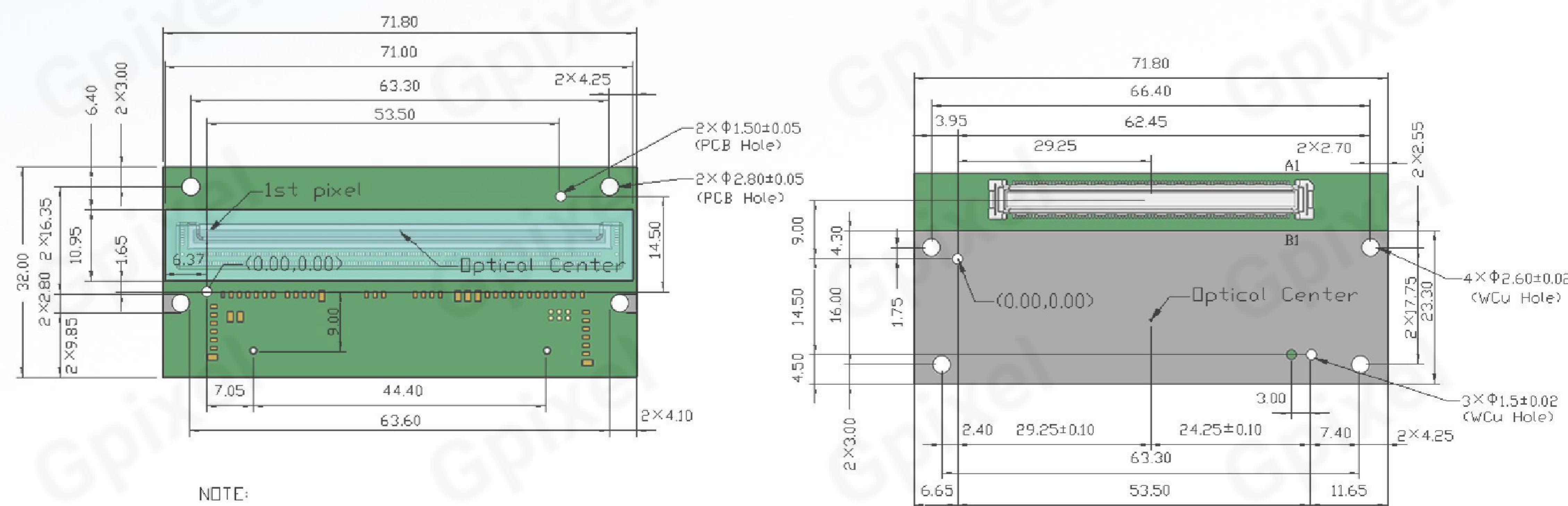
- Individual exposure control for each color line
- Easy Integration
- External Trigger
- Pin Compatible with GL3516

Application

- Automation & Inspection
- Logistic & Positioning

Specifications			
Nr of Active Pixels	8192 (H) x 4 (V)	Pixel size	7 μm x 7 μm
Optical format	57.344 mm	Shutter type	Global shutter
Full well capacity	10 ke ⁻	Photosensitive area	57.344 mm
Peak QE	73.2% @ 530 nm	Temporal noise	6.8 e ⁻
Max. SNR	40 dB	Dark Current	0.4 ke ⁻ /pixel/s @ 44°C
Max Line rate	200 kHz @ single line, 100 kHz @ dual line	Dynamic Range	63.3 dB
Output format	25 ch sub-LVDS	Chroma	Mono, RGB color
Channel multiplexing	25/13/7/4	ADC	12 bit
Max. Data rate	24 Gbps	Supply voltage	3.3 V(analog), 1.8 V(digital), 1.8 V-3.3 V(IO)
Power consumption	4.4 W	Package	168 Pins COB (71.8 mm x 32.0 mm)

Package Drawing

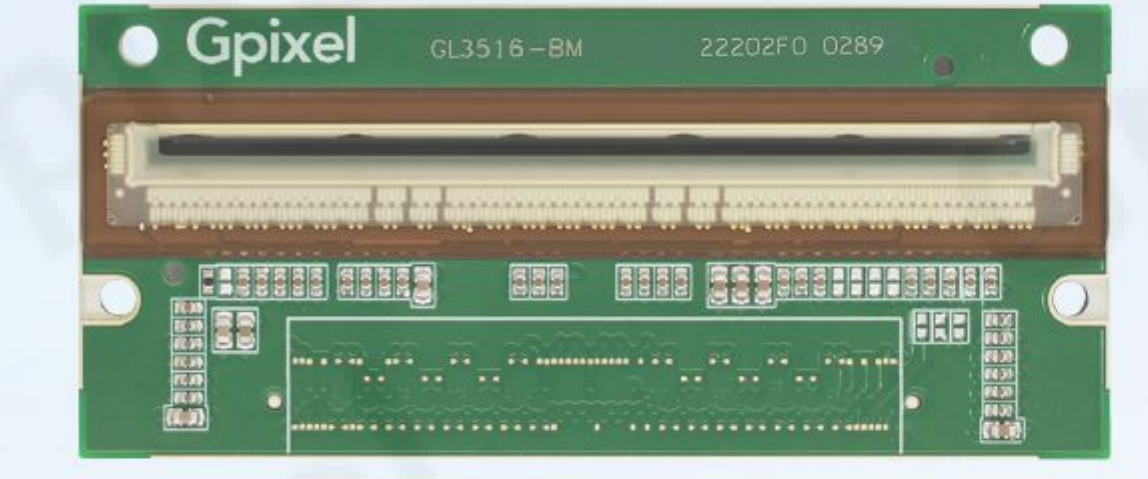


NOTE:

1. GL7008 COLOR 4 lines, Optical Center1(29.25±0.10,9.333±0)
GL7008 MONO 2 lines, Optical Center2(29.25±0.10,9.305±0);
2. All tolerances +/-0.1mm unless otherwise noticed

GL3516

16K LINE SCAN CMOS IMAGE SENSOR



GL3516 is a 16384 x 2 resolution, 3.5 μm square pixel, line scan CMOS image sensor that supports a maximum 120 kHz line rate in single line mode and 60 kHz line rate in dual line mode. GL3516 is pin and footprint compatible with Gpixel's existing GL7008 8K line scan sensor. GL3516 is offered in both color and monochrome versions. The monochrome sensor supports single and dual line modes. The color sensor supports dual line mode. GL3516 is assembled in a COB package with WCu heat sink for optimal heat dissipation and with connector for easy integration. GL3516 is an ideal solution for the inspection of lithium batteries, flat panel displays, PCBs, labels, and railways.

Key features and Benefits

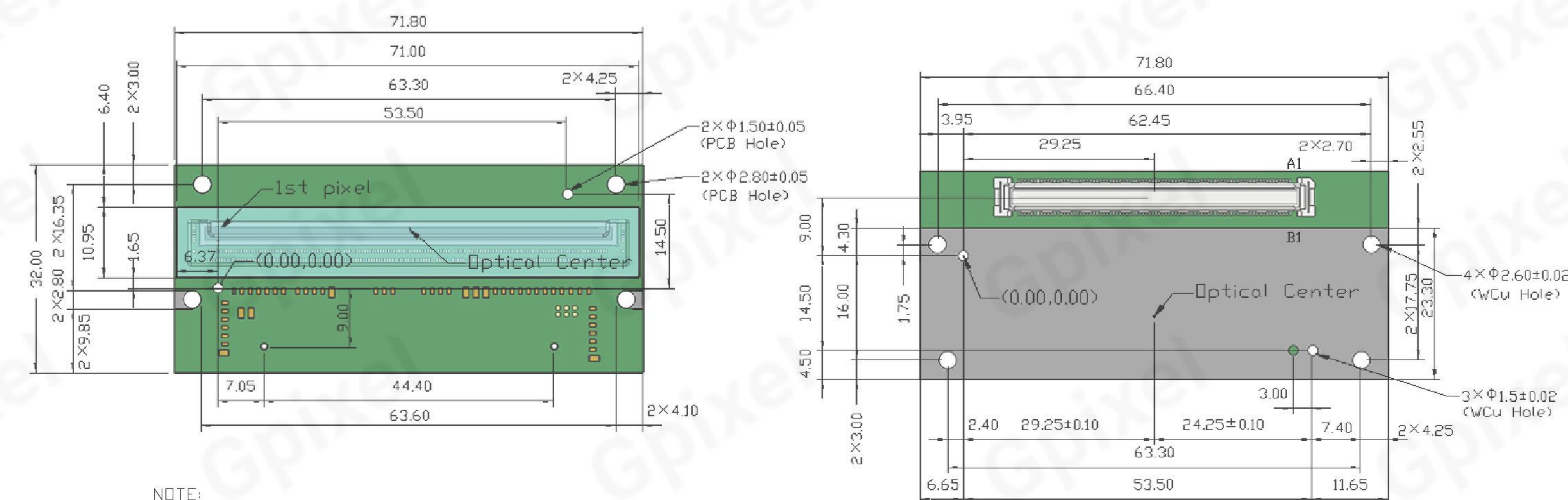
- High Resolution
- Easy Integration
- Pin Compatible with GL7008

Application

- Automation & Inspection

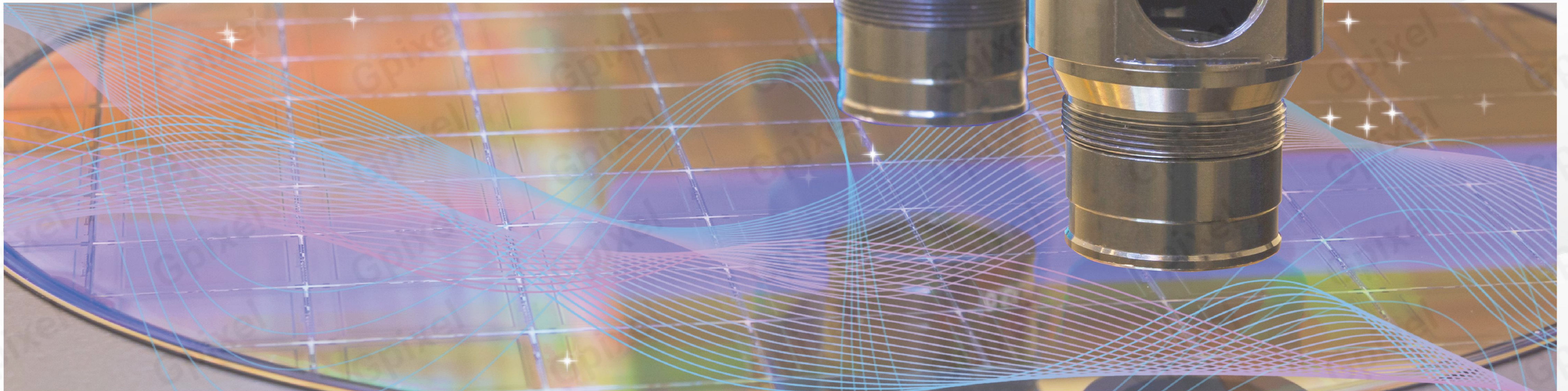
Specifications			
Nr of Active Pixels	16384 (H) x 2 (V)	Pixel size	3.5 μm x 3.5 μm
Optical format	57.344 mm	Shutter type	Global shutter
Full well capacity	5.6 ke ⁻	Photosensitive area	57.344 mm
Peak QE	57.1% @ 530 nm	Temporal noise	8.2 e ⁻
Max. SNR	37.4 dB	Dark Current	0.8 ke ⁻ /pixel/s @ 42°C
Max Line rate	120 kHz @ single line, 60 kHz @ dual line	Dynamic Range	56.6 dB
Output format	25 ch sub-LVDS	Chroma	Mono, RGB color
Channel multiplexing	25/13/7/4	ADC	10 bit
Max. Data rate	24 Gbps	Supply voltage	3.3 V(analog), 1.8 V-3.3 V(IO), 1.8 V(digital)
Power consumption	3.2 W	Package	168 Pins COB (71.8 mm x 32.0 mm)

Package Drawing



NOTE:

1. GL3516 COLOR 2 lines, Optical Center1(29.25±0.10,9.246±0.10)
GL3516 MONO 2 lines, Optical Center2(29.25±0.10,9.204±0.10)
2. All tolerances +/-0.1mm unless otherwise noticed



Custom Design

Full Custom

- Customized IC, package, and cover glass
- Chip architecture and detailed design, product testing and reliability experiments

Semi Custom

- Customize an existing design
- Color filters, micro lenses
- Package type
- Glass cover plate coating
- Chip final test standard